

CUS30M

EVALUATION DATA

型式データ

INDEX

1. 測定方法	Evaluation Method	PAGE
1.1 測定回路	Circuit used for determination	
測定回路 1	Circuit 1 used for determination	T-1
静特性	Steady state data	
過電流保護特性	Over current protection (OCP) characteristics	
過電圧保護特性	Over voltage protection (OVP) characteristics	
出力立ち上がり特性	Output rise characteristics	
出力立ち下がり特性	Output fall characteristics	
出力保持時間特性	Hold up time characteristics	
測定回路 2	Circuit 2 used for determination	T-1
過渡応答 (負荷急変) 特性	Dynamic load response characteristics	
測定回路 3	Circuit 3 used for determination	T-1
入力サージ電流 (突入電流) 波形	Inrush current waveform	
測定回路 4	Circuit 4 used for determination	T-2
リーク電流特性	Leakage current characteristics	
測定回路 5	Circuit 5 used for determination	T-2
出力リップル、ノイズ波形	Output ripple and noise waveform	
測定構成	Configuration used for determination	T-3
EMI特性	Electro-Magnetic Interference characteristics	
(a) 雑音端子電圧 (帰還ノイズ)	Conducted Emission	
(b) 雑音電界強度 (放射ノイズ)	Radiated Emission	
1.2 使用測定機器	List of equipment used	T-4
2. 特性データ	Characteristics	
2.1 静特性	Steady state data	
(1) 入力・負荷・温度変動／出力起動・遮断電圧	Regulation - line and load, Temperature drift	
	/ Start up voltage and Drop out voltage	T-5~6
(2) 効率対出力電流	Efficiency vs. Output current	T-7~8
(3) 入力電流対出力電流	Input current vs. Output current	T-9~10
(4) 入力電力対出力電流	Input power vs. Output current	T-11~12
2.2 過電流保護特性	Over current protection (OCP) characteristics	T-13~14
2.3 過電圧保護特性	Over voltage protection (OVP) characteristics	T-15~17
2.4 出力立ち上がり特性	Output rise characteristics	T-18~19
2.5 出力立ち下がり特性	Output fall characteristics	T-20~21
2.6 出力保持時間特性	Hold up time characteristics	T-22~23
2.7 過渡応答 (負荷急変) 特性	Dynamic load response characteristics	T-24~27
2.8 入力電圧瞬停特性	Response to brown out characteristics	T-28~31
2.9 入力サージ電流 (突入電流) 波形	Inrush current waveform	T-32~34
2.10 リーク電流特性	Leakage current characteristics	T-35~43
2.11 出力リップル、ノイズ波形	Output ripple and noise waveform	T-44~47
2.12 EMI 特性	Electro-Magnetic Interference characteristics	T-48~71

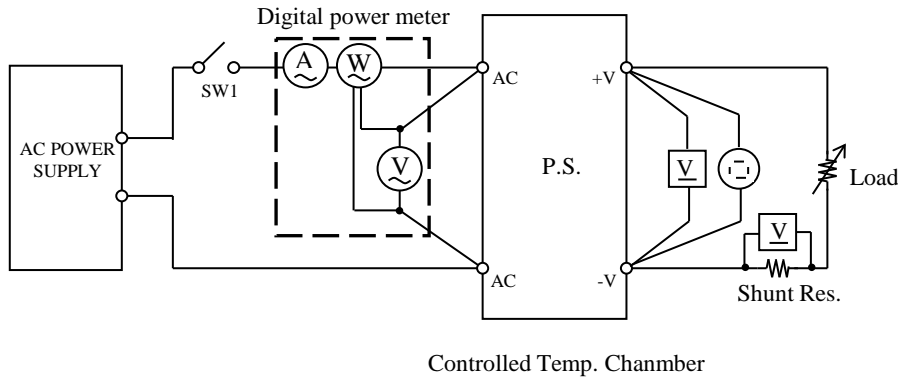
使用記号 Terminology used

	定義	Definition
Vin 入力電圧	Input voltage
Vout 出力電圧	Output voltage
Iin 入力電流	Input current
Iout 出力電流	Output current
Ta 周囲温度	Ambient temperature
f 周波数	Frequency

1.1 測定回路 Circuit used for determination

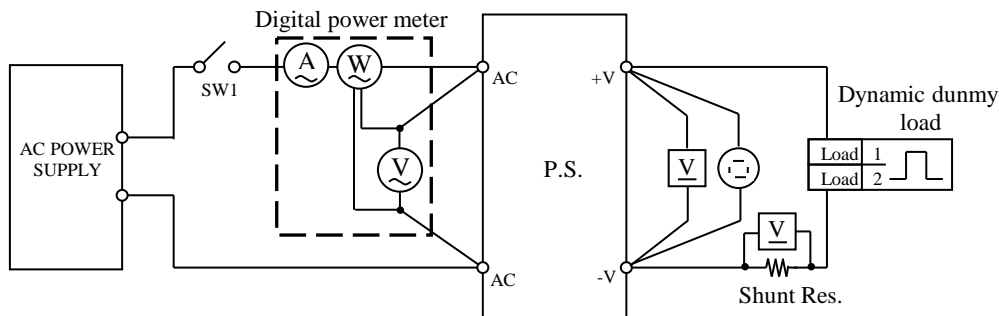
測定回路1 Circuit 1 used for determination

- 静特性 Steady state data
- 過電流保護特性 Over current protection (OCP) characteristics
- 過電圧保護特性 Over voltage protection (OVP) characteristics
- 出力立ち上がり特性 Output rise characteristics
- 出力立ち下がり特性 Output fall characteristics
- 出力保持時間特性 Hold up time characteristics

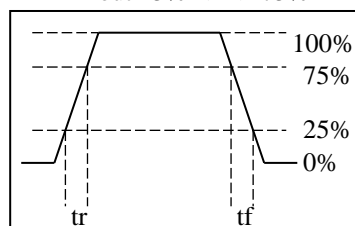


測定回路2 Circuit 2 used for determination

- 過渡応答(負荷急変) 特性 Dynamic load response characteristics

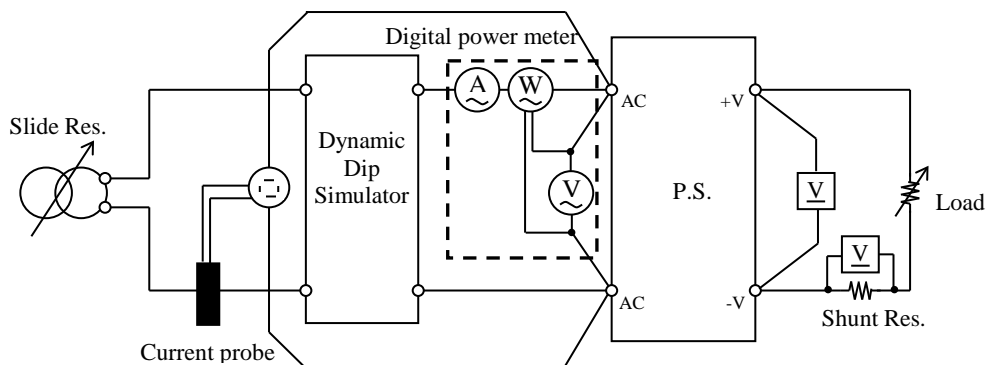


Output current waveform
I_{out} 25% <=> 75%



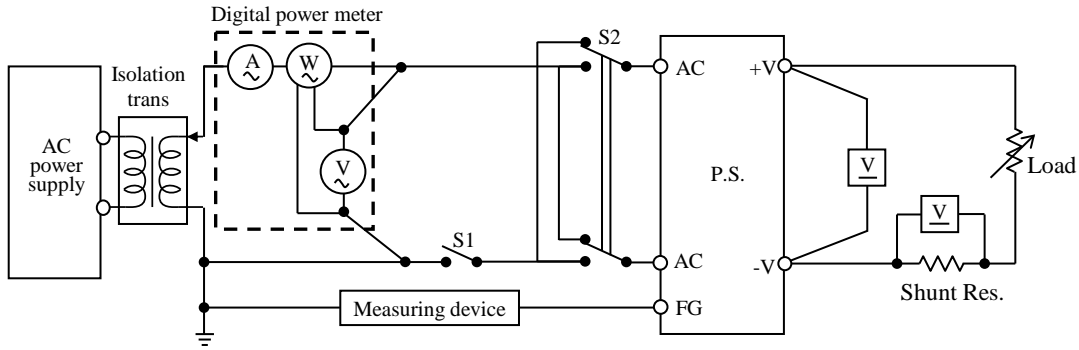
測定回路3 Circuit 3 used for determination

- 入力サージ電流(突入電流) 波形 Inrush current waveform



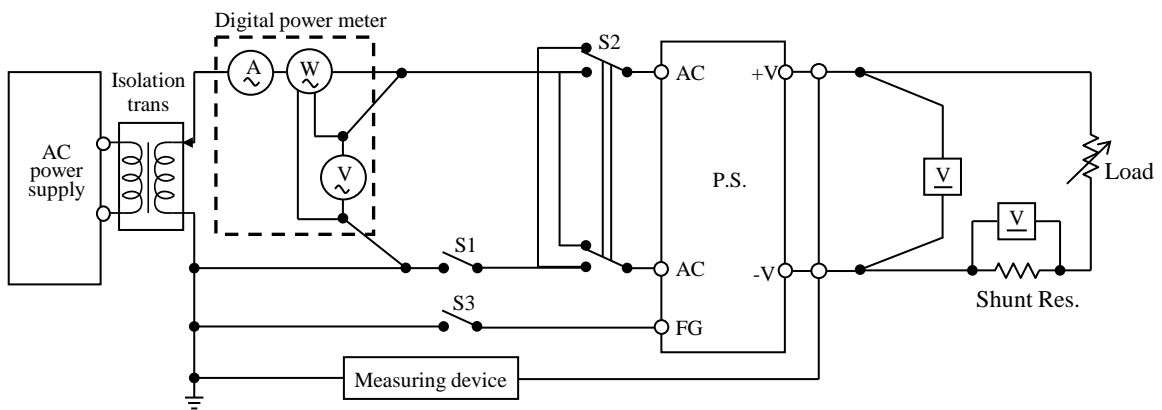
・リーク電流特性 Leakage current characteristics

(a) Earth leakage current of CLASS I equipment



Measure in all possible combination of position of S2 with : S1 closed (NORMAL CONDITION), and S1 open (Single fault condition).

(b) Patient leakage current



CLASS I equipment:

S1, S3 closed, measure under all possible position of S2.

Single fault condition: S1 open with S3 close or S1 close with S3 open.

CLASS II equipment:

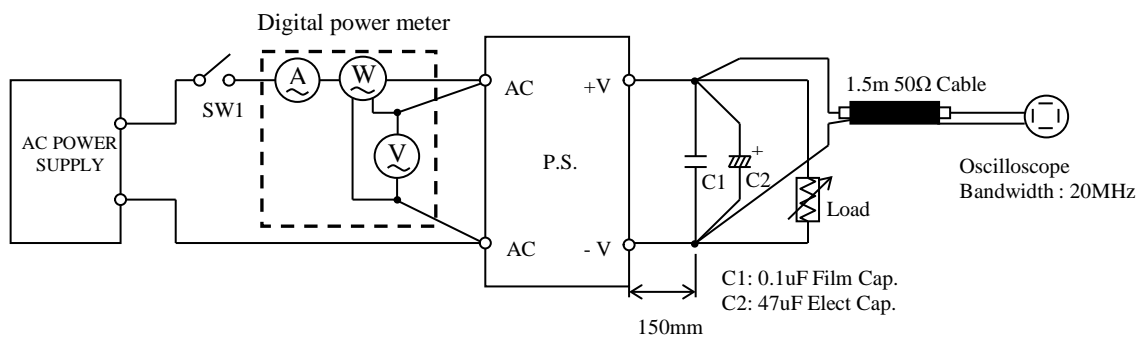
S3 open, Protection Earth not connected, measure under all combination of position of S1 and S2.

Single fault condition: S1 open.

測定回路5 Circuit 5 used for determination

・出力リップル、ノイズ波形

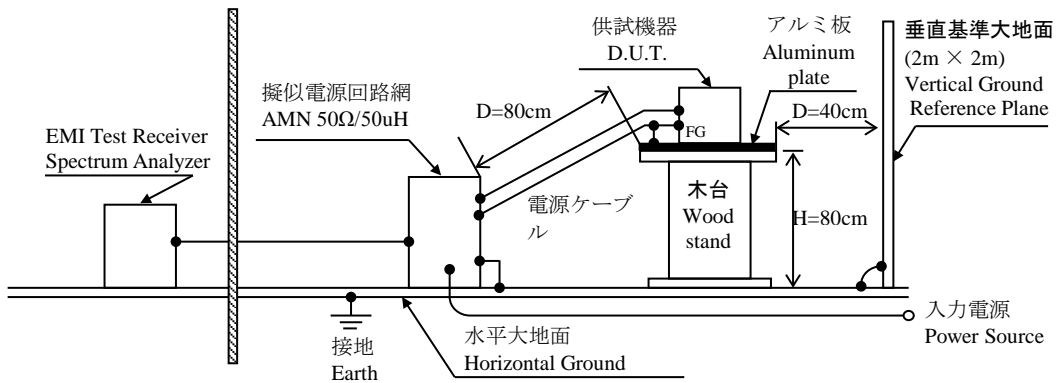
Output ripple and noise waveform



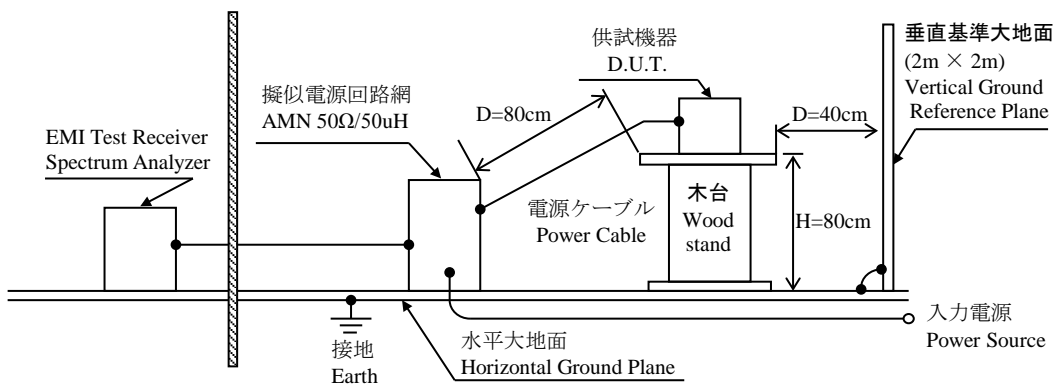
・ EMI 特性 Electro-Magnetic Interference characteristics

(a) 雑音端子電圧 (帰還ノイズ) Conducted Emission

CLASS I setup:

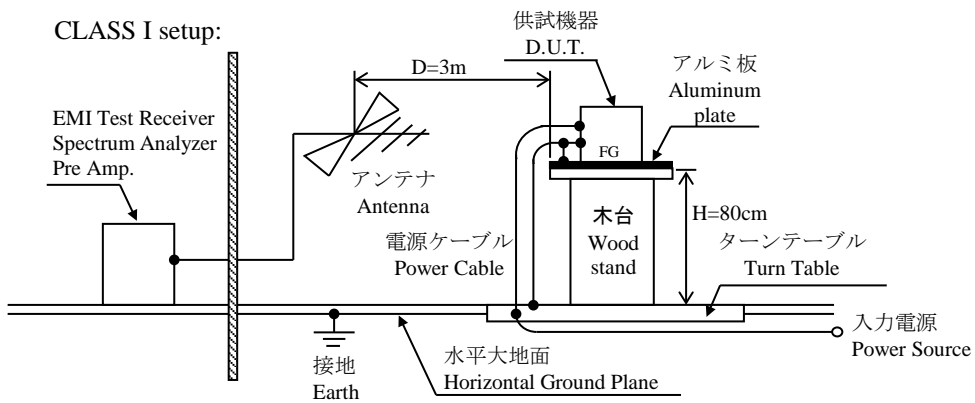


CLASS II setup:

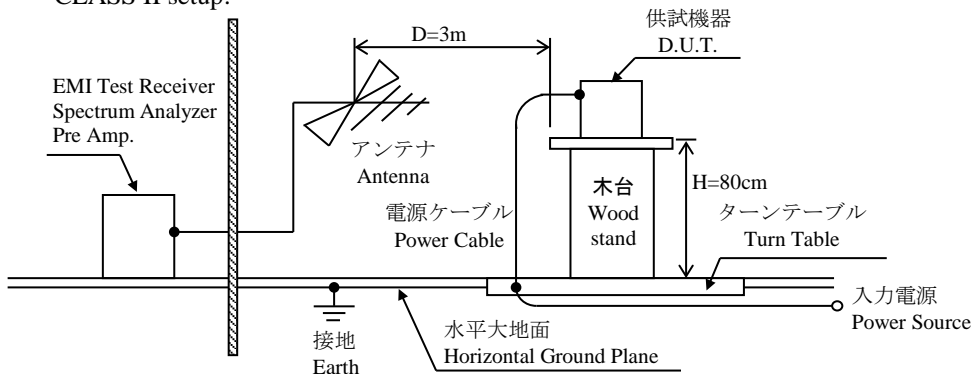


(b) 雑音電界強度 (放射ノイズ) Radiated Emission

CLASS I setup:



CLASS II setup:



1.2 使用測定機器 List of equipment used

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	DIGITAL STORAGE OSCILLOSCOPE	YOKOGAWA ELECT.	DL2054/DL9040
2	DIGITAL MULTIMETER	AGILENT	34970A
3	DIGITAL POWER METER	YOKOGAWA ELECT.	WT210
4	CURRENT PROBE	TEKTRONIX	63202
5	DC AMPERE METER	TEKTRONIX	P5100
6	DYNAMIC DUMMY LOAD	CHROMA	63030/63610/63640
7	AC SOURCE	KIKUSUI	PCR2000L
8	AC SOURCE	TAKAMISAWA	PSA-210
9	EARTH LEAKAGE CURRENT METER	SIMPSON	228
10	PATIENT LEAKAGE CURRENT METER	SIQ	SIQ16042
11	CONTROLLED TEMP. CHAMBER	TABAI-ESPEC	63203
12	EMI TEST RECEIVER	ROHDE & SCHWARZ	ESCI-03
13	LISN	ROHDE & SCHWARZ	ENV216
14	BICONICAL ANTENNA	EMCO	63208

2. 特性データ Characteristics

CUS30M

2.1 静特性 Steady state data

(1) 入力・負荷・温度変動／出力起動・遮断電圧

Regulation - line and load, Temperature drift / Start up voltage and Drop out voltage

12V
(CUS30M-12)

1. Regulation - line and load

Condition Ta : 25 °C

Iout \ Vin	85VAC	115VAC	230VAC	265VAC	line regulation	
0%	12.074V	12.074V	12.075V	12.075V	1mV	0.008%
50%	12.050V	12.050V	12.050V	12.051V	1mV	0.008%
100%	12.025V	12.026V	12.026V	12.026V	1mV	0.008%
load regulation	49mV	48mV	49mV	49mV		
	0.408%	0.400%	0.408%	0.408%		

2. Temperature drift

Conditions Vin : 115 VAC

Iout : 100 %

Ta	-20°C	+25°C	+50°C	temperature stability	
Vout	11.989V	12.026V	12.023V	37mV	0.004%

3. Start up voltage and Drop out voltage

Conditions Ta : 25 °C

Iout : 100 %

Start up voltage (Vin)	60.0Vac
Drop out voltage (Vin)	61.0Vac

24V
(CUS30M-24)

1. Regulation - line and load

Condition Ta : 25 °C

Iout \ Vin	85VAC	115VAC	230VAC	265VAC	line regulation	
0%	24.053V	24.054V	24.056V	24.058V	5mV	0.021%
50%	24.033V	24.033V	24.028V	24.026V	7mV	0.029%
100%	24.009V	24.003V	24.001V	24.001V	8mV	0.033%
load regulation	44mV	51mV	55mV	57mV		
	0.183%	0.212%	0.229%	0.237%		

2. Temperature drift

Conditions Vin : 115 VAC

Iout : 100 %

Ta	-20°C	+25°C	+50°C	temperature stability	
Vout	23.981V	24.003V	23.972V	31mV	0.004%

3. Start up voltage and Drop out voltage

Conditions Ta : 25 °C

Iout : 100 %

Start up voltage (Vin)	61.0Vac
Drop out voltage (Vin)	63.0Vac

2. 特性データ Characteristics

CUS30M

2.1 静特性 Steady state data

(1) 入力・負荷・温度変動／出力起動・遮断電圧

Regulation - line and load, Temperature drift / Start up voltage and Drop out voltage

48V
(CUS30M-48)

1. Regulation - line and load

Condition Ta : 25 °C

Iout \ Vin	85VAC	115VAC	230VAC	265VAC	line regulation	
0%	47.771V	47.772V	47.775V	47.779V	8mV	0.017%
50%	47.757V	47.759V	47.759V	47.758V	2mV	0.004%
100%	47.742V	47.744V	47.744V	47.742V	2mV	0.004%
load regulation	29mV	28mV	31mV	37mV		
	0.060%	0.058%	0.065%	0.077%		

2. Temperature drift

Conditions Vin : 115 VAC

Iout : 100 %

Ta	-20°C	+25°C	+45°C	temperature stability	
Vout	47.529V	47.744V	47.810V	281mV	0.009%

3. Start up voltage and Drop out voltage

Conditions Ta : 25 °C

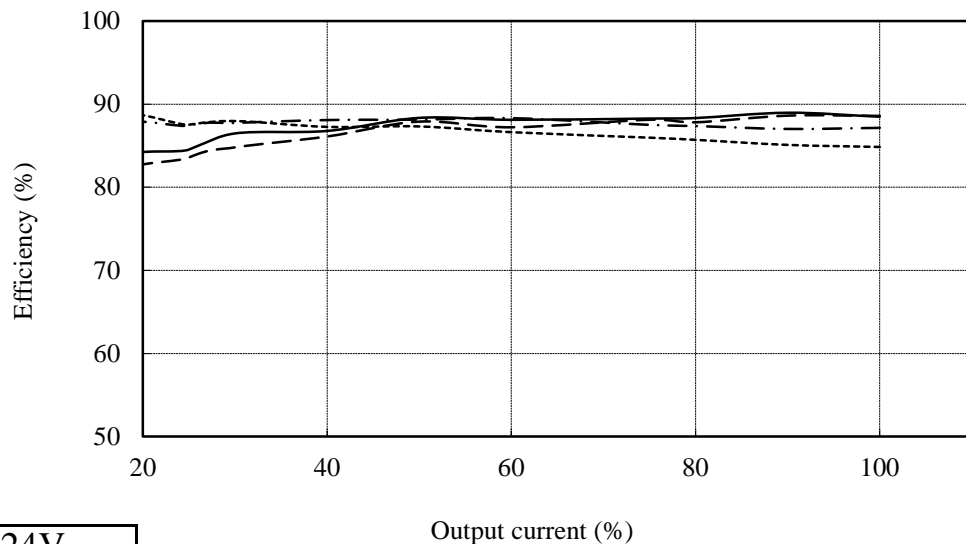
Iout : 100 %

Start up voltage (Vin)	61.5Vac
Drop out voltage (Vin)	65.0Vac

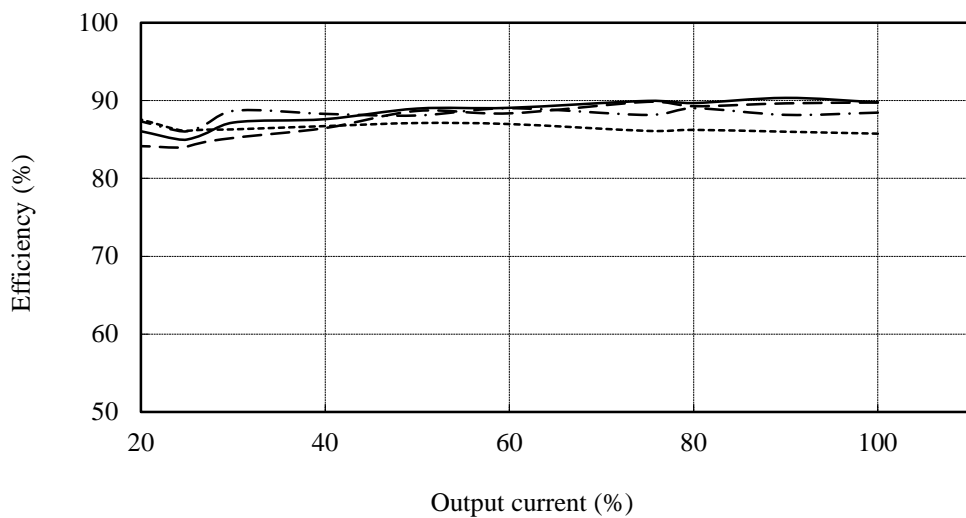
(2) 効率対出力電流
Efficiency vs. Output current

Conditions Vin : 85 VAC -----
 : 115 VAC -.-.-.
 : 230 VAC ———
 : 265 VAC - - - -
 Ta : 25 °C

12V
(CUS30M-12)



24V
(CUS30M-24)

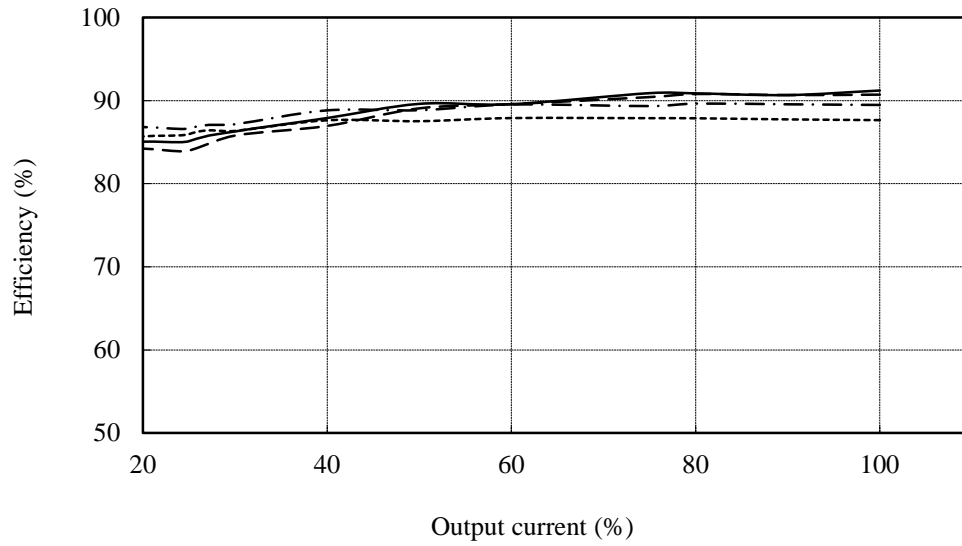


(2) 効率対出力電流
Efficiency vs. Output current

Conditions Vin : 85 VAC -----
 : 115 VAC -.-.-.-
 : 230 VAC ————
 : 265 VAC - - - -
 Ta : 25 °C

48V

(CUS30M-48)



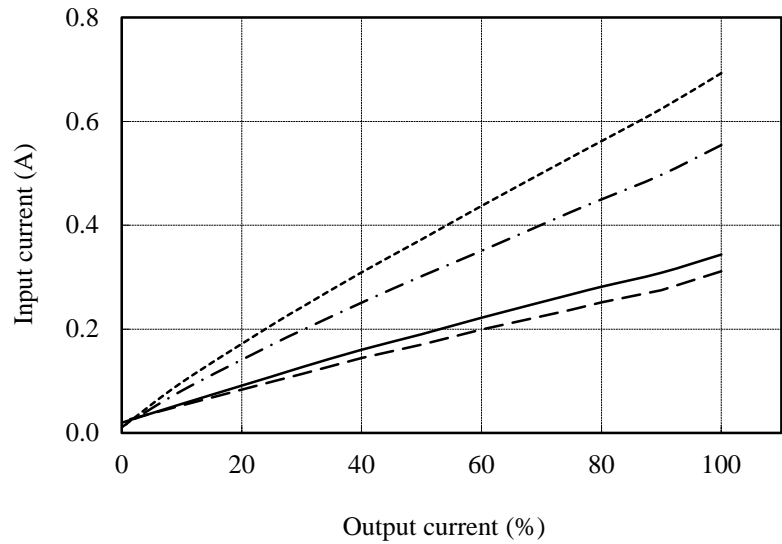
(3) 入力電流対出力電流
Input current vs. Output current

Conditions Vin : 85 VAC -----
 : 115 VAC -.-.-.-
 : 230 VAC ————
 : 265 VAC - - - - -
 Ta : 25 °C

12V
(CUS30M-12)

Io: 100%

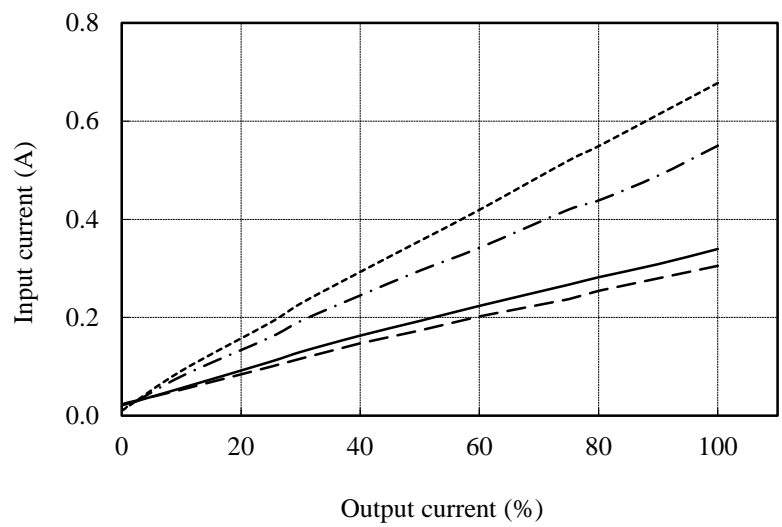
Vin	Input current
85Vac	0.693A
115Vac	0.554A
230Vac	0.344A
265Vac	0.311A



24V
(CUS30M-24)

Io: 100%

Vin	Input current
85Vac	0.678A
115Vac	0.550A
230Vac	0.340A
265Vac	0.305A



(3) 入力電流対出力電流
Input current vs. Output current

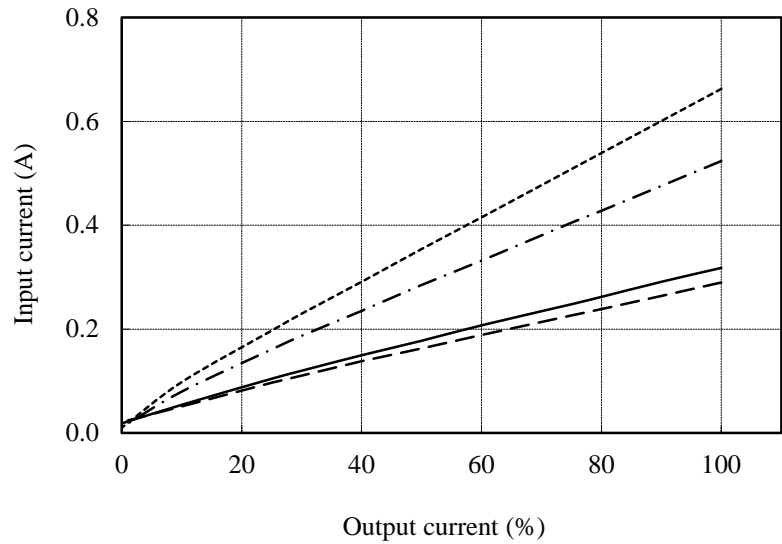
Conditions Vin : 85 VAC -----
 : 115 VAC -.-.-.-
 : 230 VAC ————
 : 265 VAC - - - - -
 Ta : 25 °C

48V

 (CUS30M-48)

Io: 100%

Vin	Input current
85Vac	0.663A
115Vac	0.524A
230Vac	0.318A
265Vac	0.290A



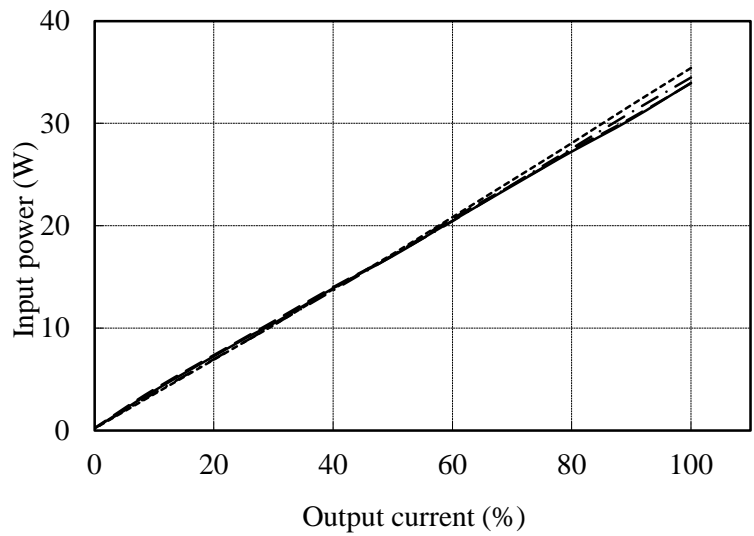
(4) 入力電力対出力電流
Input power vs. Output current

Conditions Vin : 85 VAC -----
 : 115 VAC -.-.-.
 : 230 VAC ———
 : 265 VAC - - - -
 Ta : 25 °C

12V
(CUS30M-12)

Io: 100%

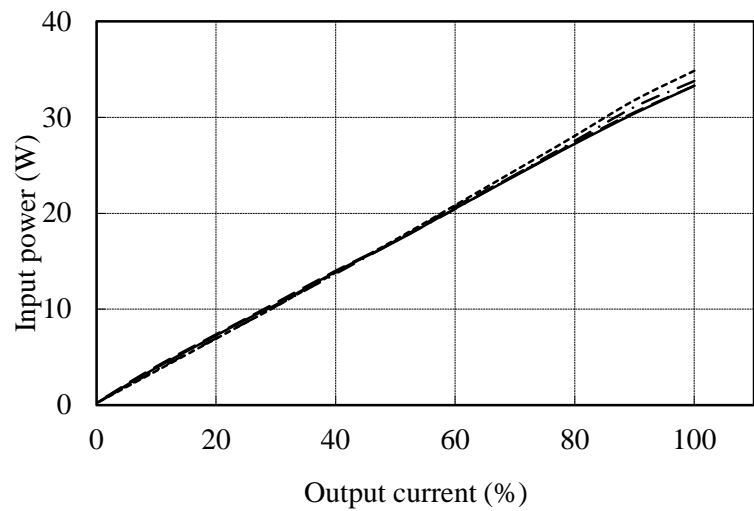
Vin	Input power
85Vac	35.41W
115Vac	34.48W
230Vac	33.96W
265Vac	33.92W



24V
(CUS30M-24)

Io: 100%

Vin	Input power
85Vac	34.86W
115Vac	33.79W
230Vac	33.29W
265Vac	33.30W



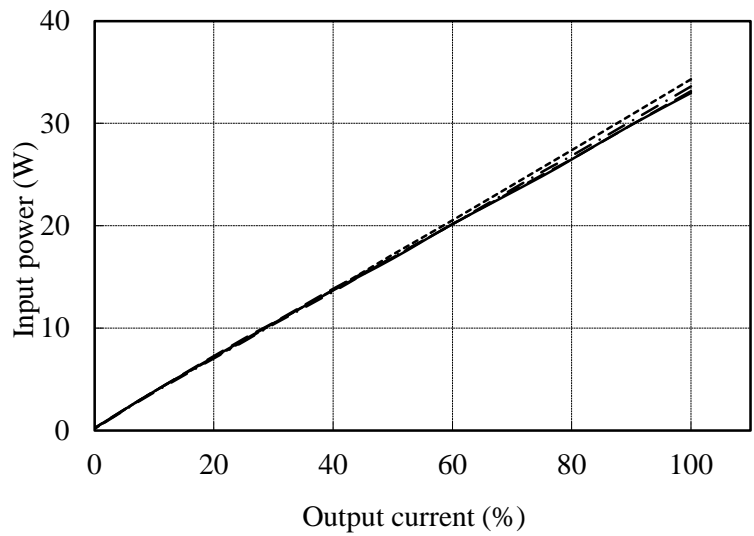
(4) 入力電力対出力電流
Input power vs. Output current

Conditions Vin : 85 VAC -----
 : 115 VAC - - - -
 : 230 VAC ———
 : 265 VAC - - - -
 Ta : 25 °C

48V
(CUS30M-48)

Io: 100%

Vin	Input power
85Vac	34.31W
115Vac	33.61W
230Vac	32.97W
265Vac	33.15W

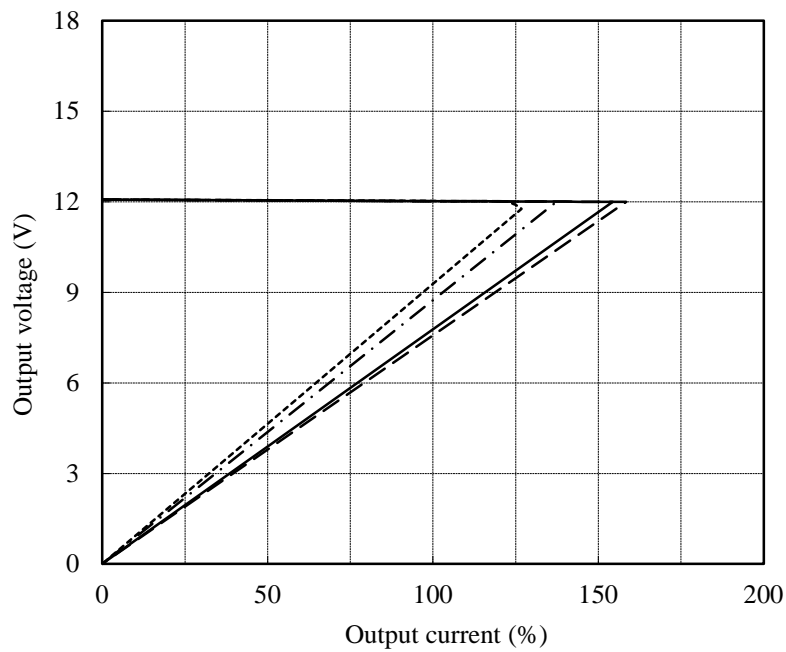


2.2 過電流保護特性

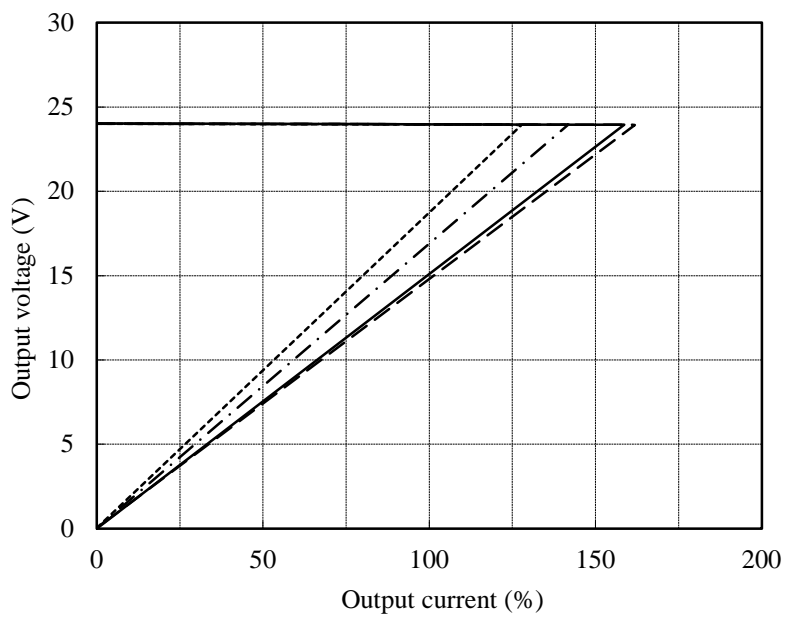
Over current protection (OCP) characteristics

Conditions Vin : 85 VAC -----
 115 VAC -.-.-.-
 230 VAC ————
 265 VAC - - - -
 Ta : 25 °C

12V
 (CUS30M-12)



24V
 (CUS30M-24)

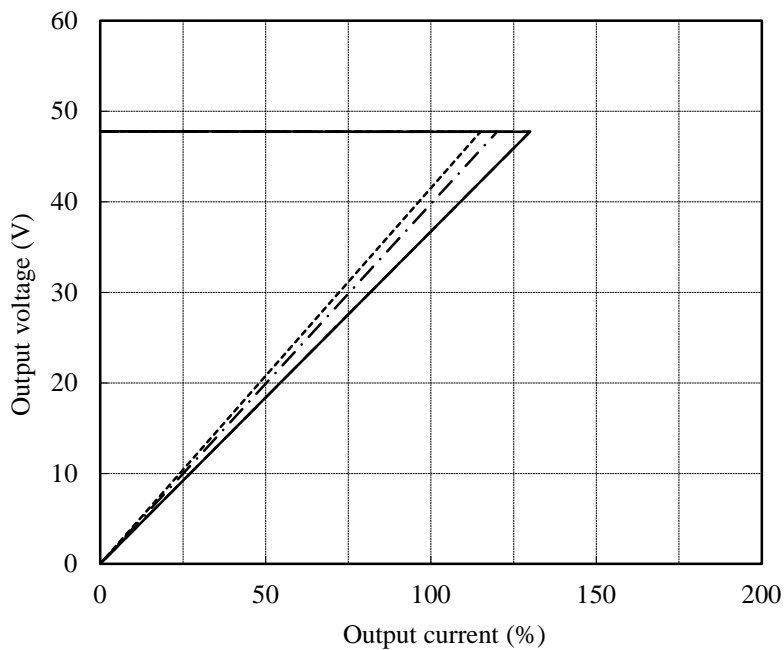


2.2 過電流保護特性

Over current protection (OCP) characteristics

Conditions Vin : 85 VAC -----
 115 VAC -.-.-.-
 230 VAC ————
 265 VAC - - - -
 Ta : 25 °C

48V
 (CUS30M-48)

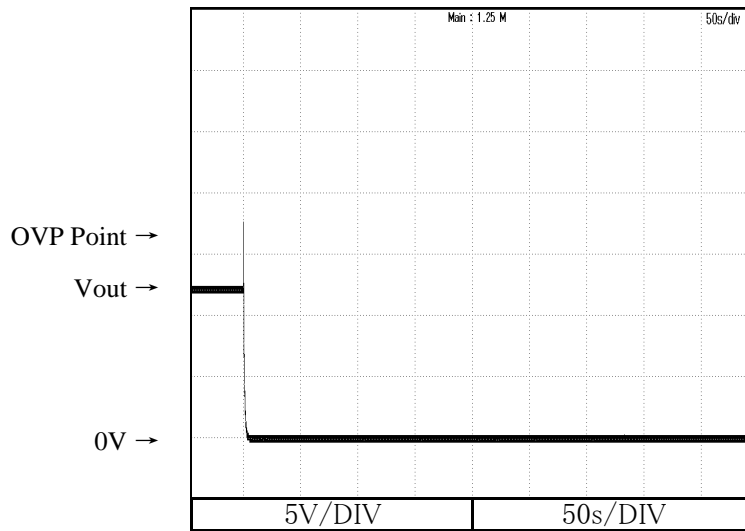


2.3 過電圧保護特性

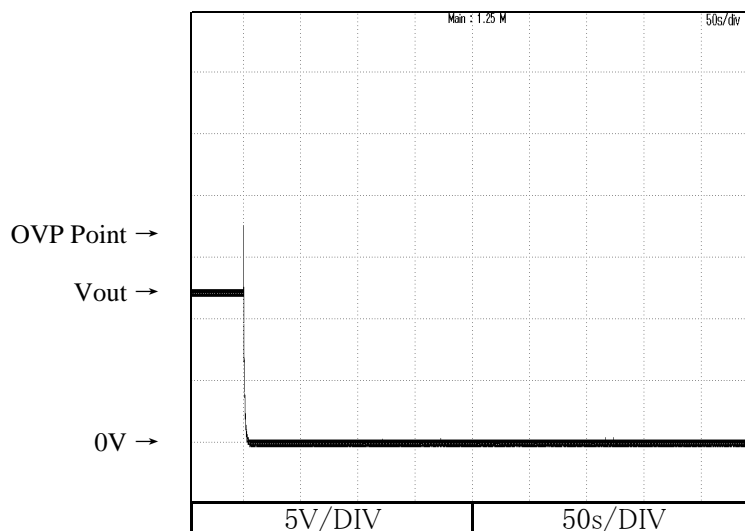
Over voltage protection (OVP) characteristics

12V
(CUS30M-12)

Conditions Vin : 115 VAC
Iout : 0 %
Ta : 25 °C



Conditions Vin : 230 VAC
Iout : 0 %
Ta : 25 °C

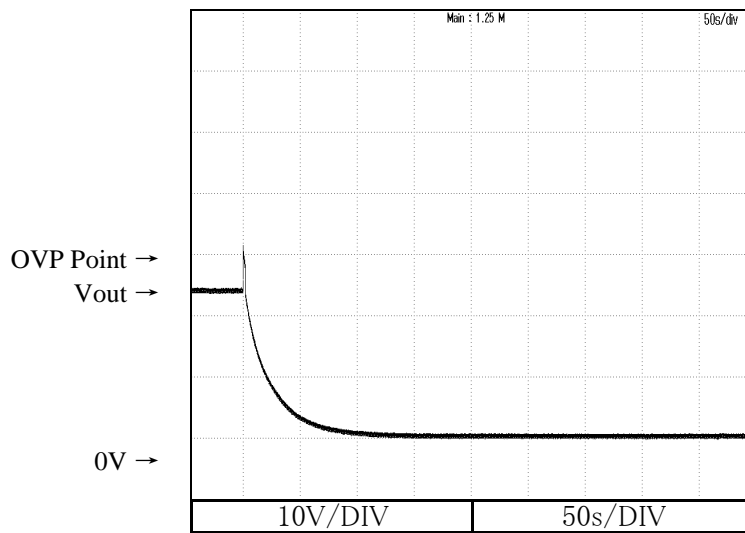


2.3 過電圧保護特性

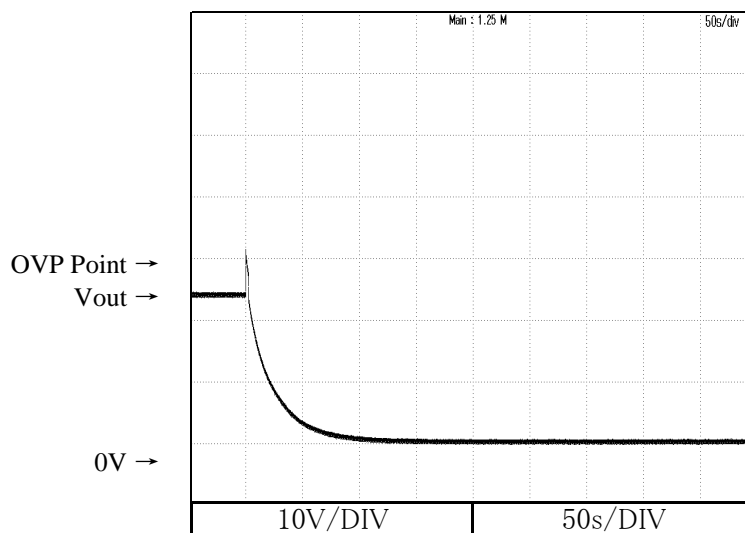
Over voltage protection (OVP) characteristics

24V
(CUS30M-24)

Conditions Vin : 115 VAC
Iout : 0 %
Ta : 25 °C



Conditions Vin : 230 VAC
Iout : 0 %
Ta : 25 °C

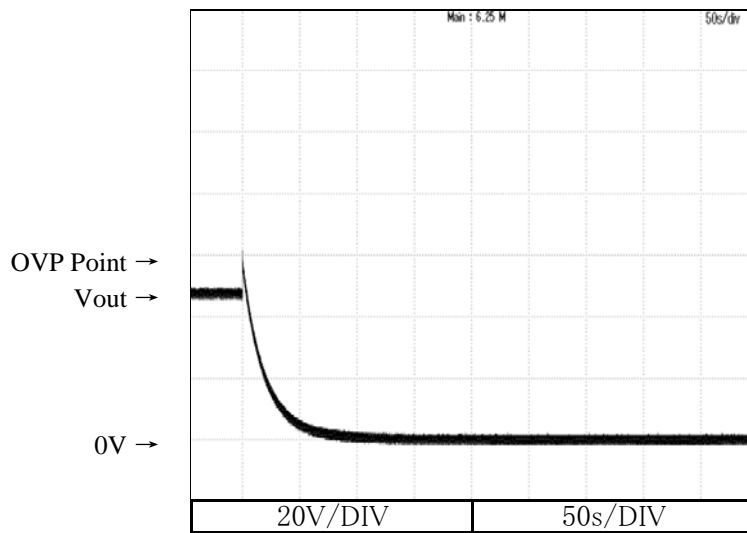


2.3 過電圧保護特性

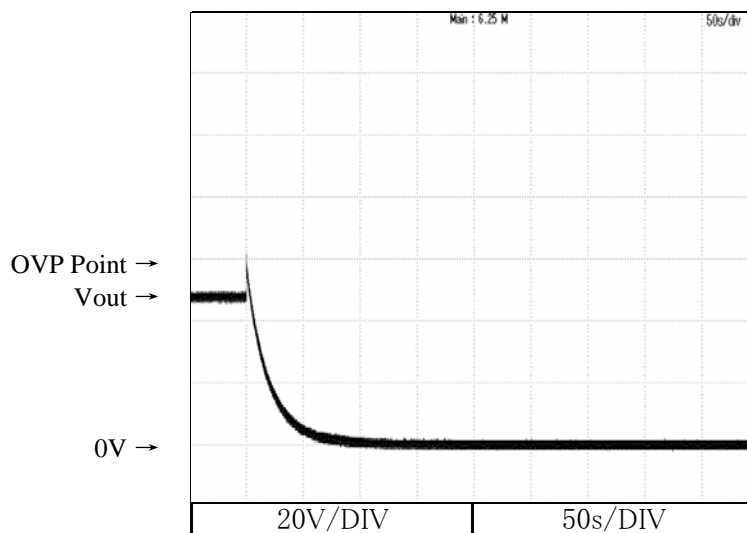
Over voltage protection (OVP) characteristics

48V
(CUS30M-48)

Conditions Vin : 115 VAC
Iout : 0 %
Ta : 25 °C



Conditions Vin : 230 VAC
Iout : 0 %
Ta : 25 °C

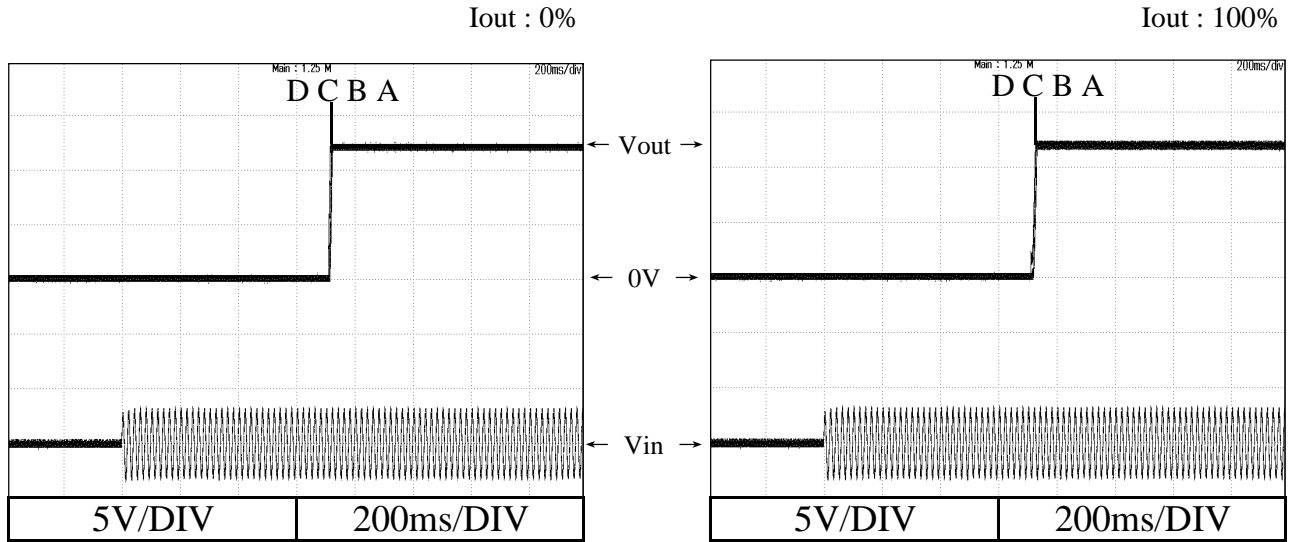


2.4 出力立ち上がり特性
Output rise characteristics

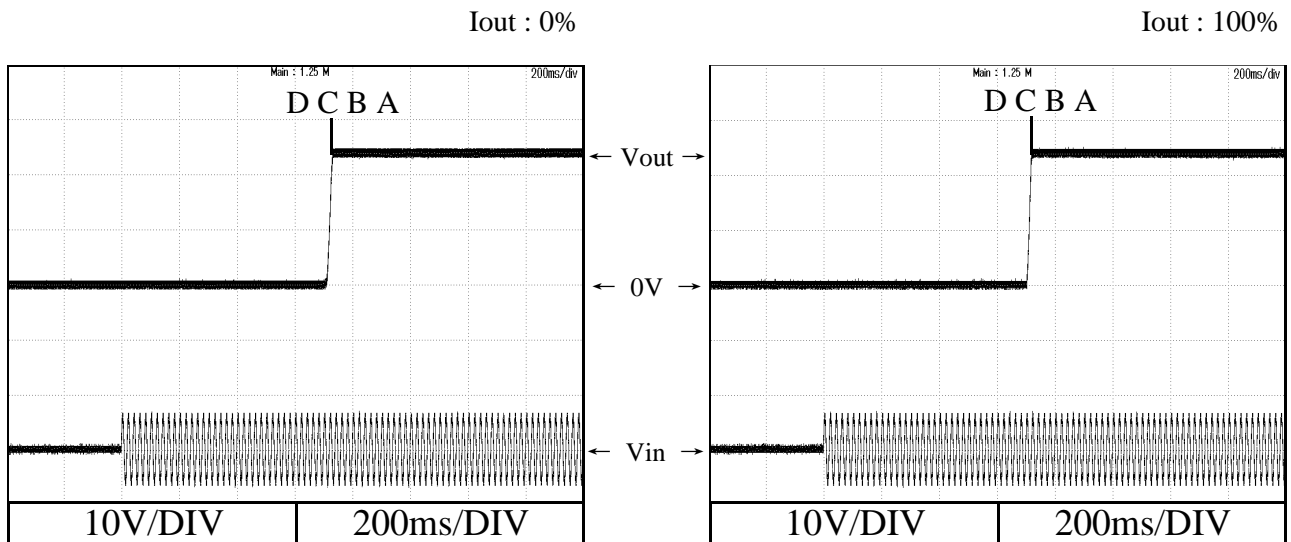
CUS30M

Conditions Vin : 85 VAC (A)
115 VAC (B)
230 VAC (C)
265 VAC (D)
Ta : 25 °C

12V
(CUS30M-12)



24V
(CUS30M-24)

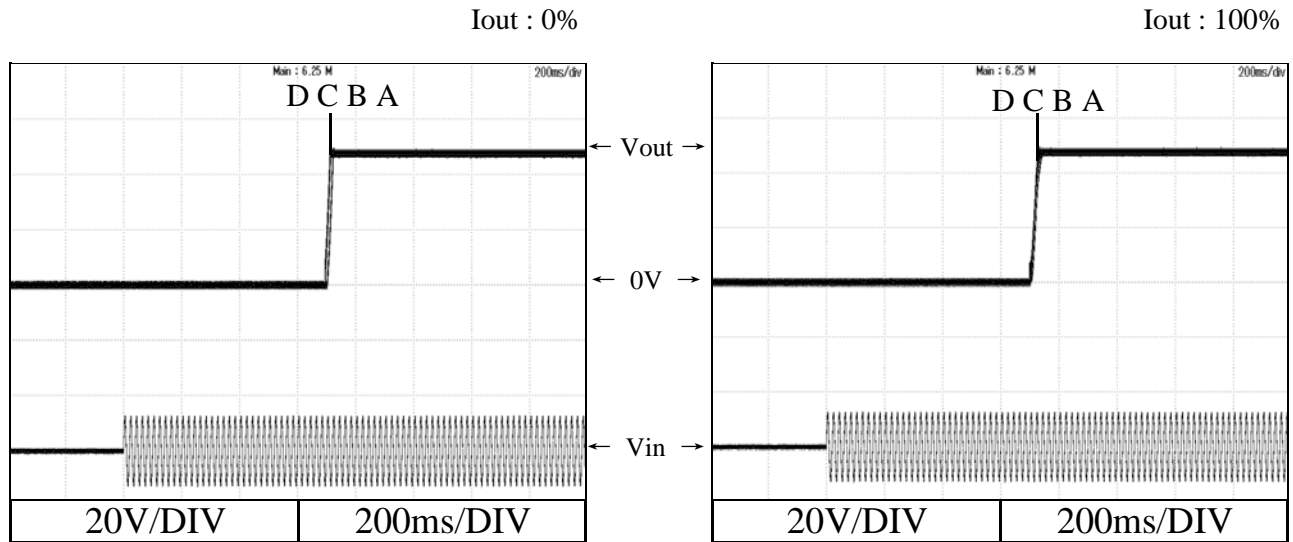


2.4 出力立ち上がり特性
Output rise characteristics

CUS30M

Conditions Vin : 85 VAC (A)
115 VAC (B)
230 VAC (C)
265 VAC (D)
Ta : 25 °C

48V
(CUS30M-48)



2.5 出力立ち下がり特性
Output fall characteristics

CUS30M

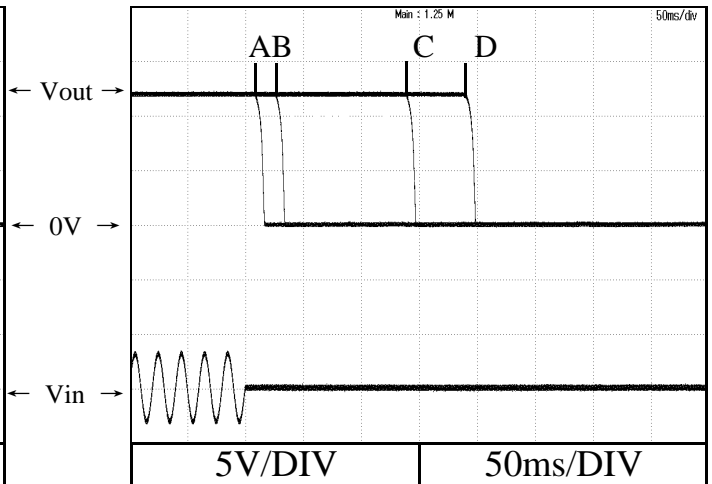
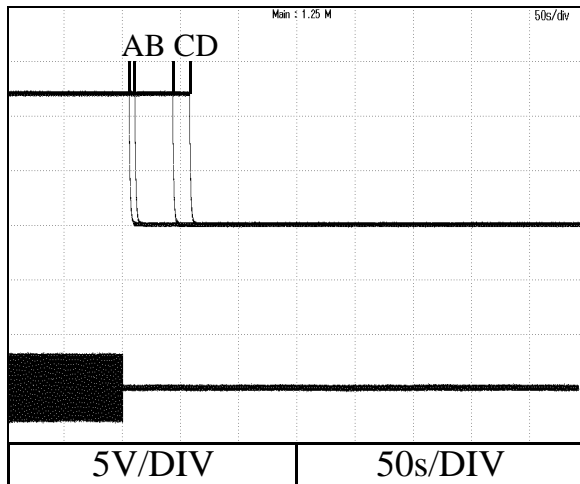
Conditions Vin : 85 VAC (A)
115 VAC (B)
230 VAC (C)
265 VAC (D)
Ta : 25 °C

12V

(CUS30M-12)

Iout : 0%

Iout : 100%

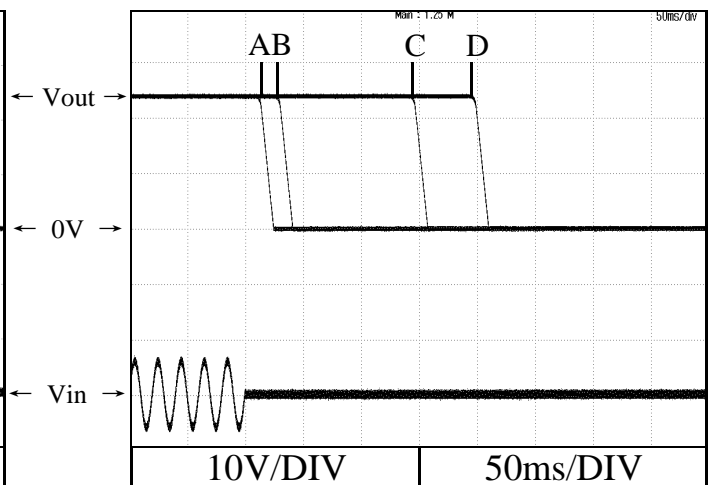
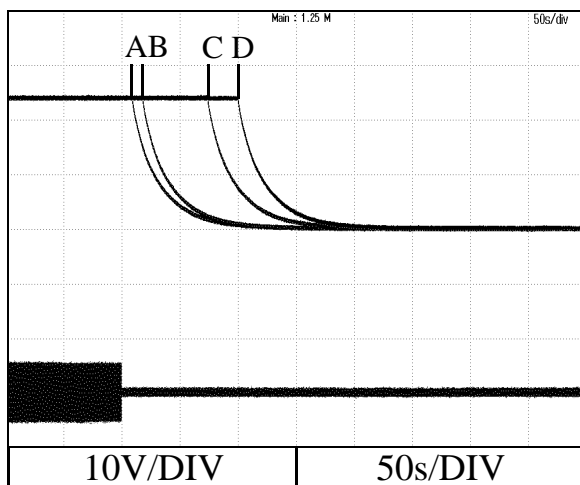


24V

(CUS30M-24)

Iout : 0%

Iout : 100%



2.5 出力立ち下がり特性
Output fall characteristics

CUS30M

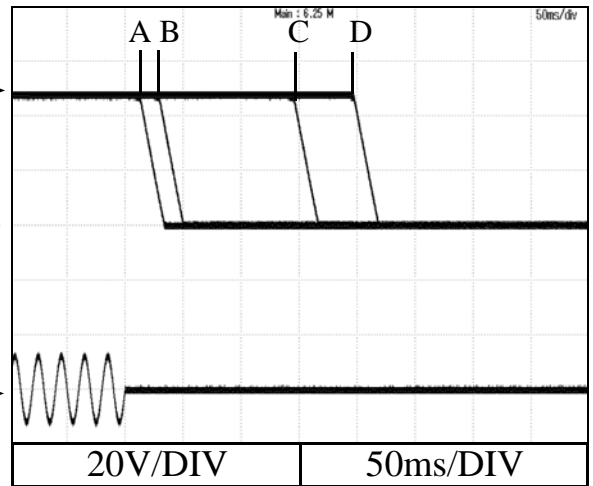
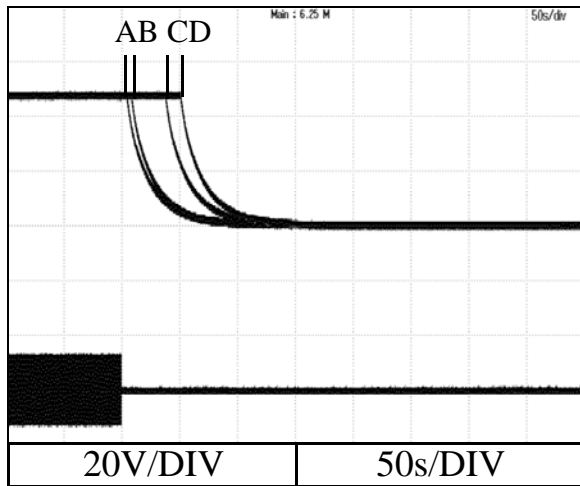
Conditions Vin : 85 VAC (A)
115 VAC (B)
230 VAC (C)
265 VAC (D)
Ta : 25 °C

48V

(CUS30M-48)

Iout : 0%

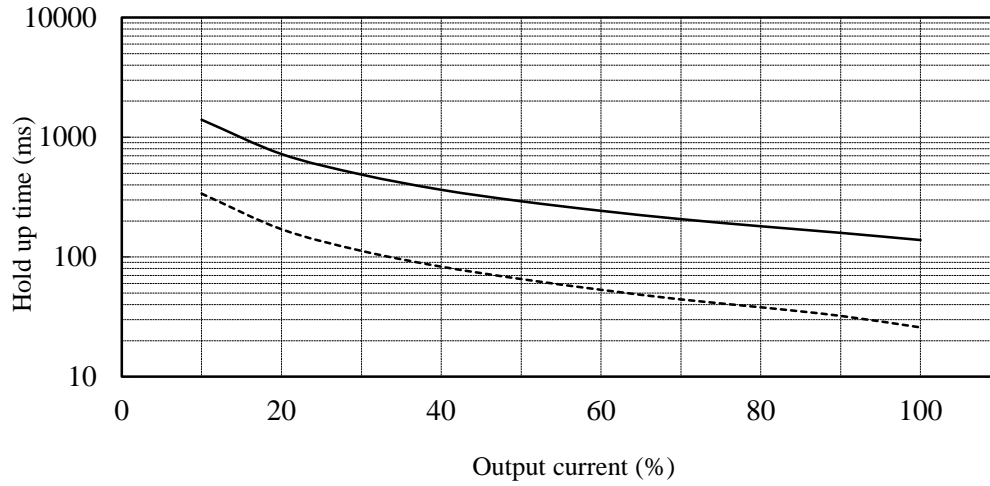
Iout : 100%



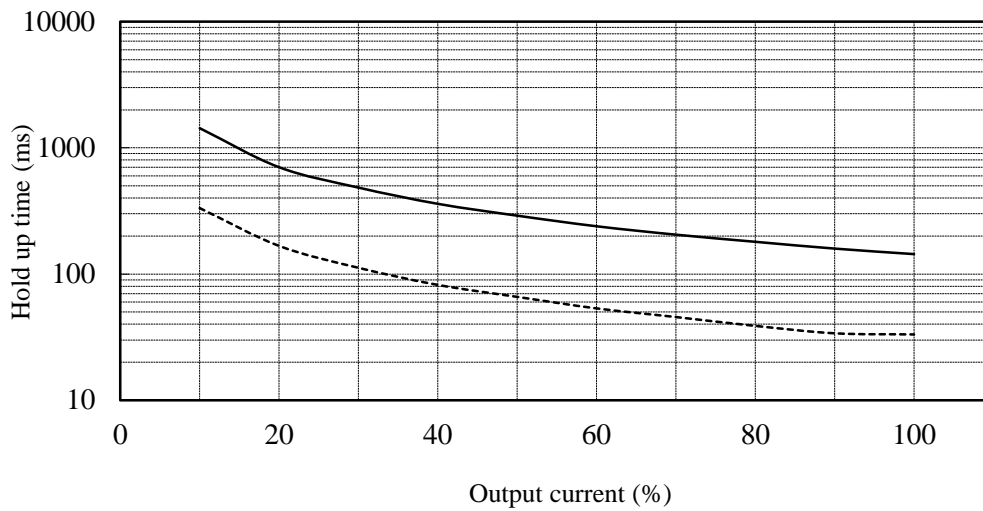
2.6 出力保持時間特性
Hold up time characteristics

Conditions Vin : 115 VAC -----
230 VAC ————
Ta : 25 °C

12V
(CUS30M-12)



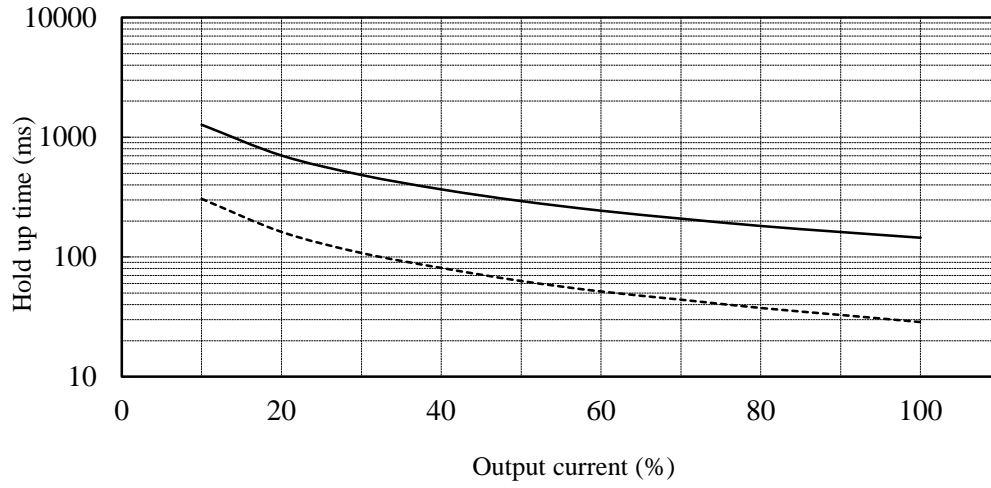
24V
(CUS30M-24)



2.6 出力保持時間特性
Hold up time characteristics

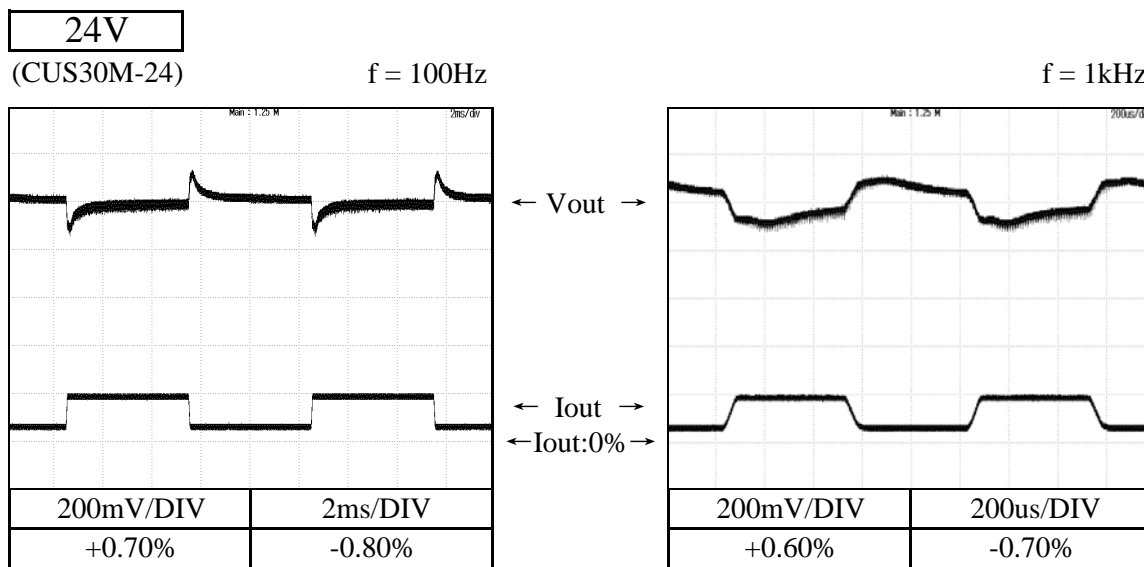
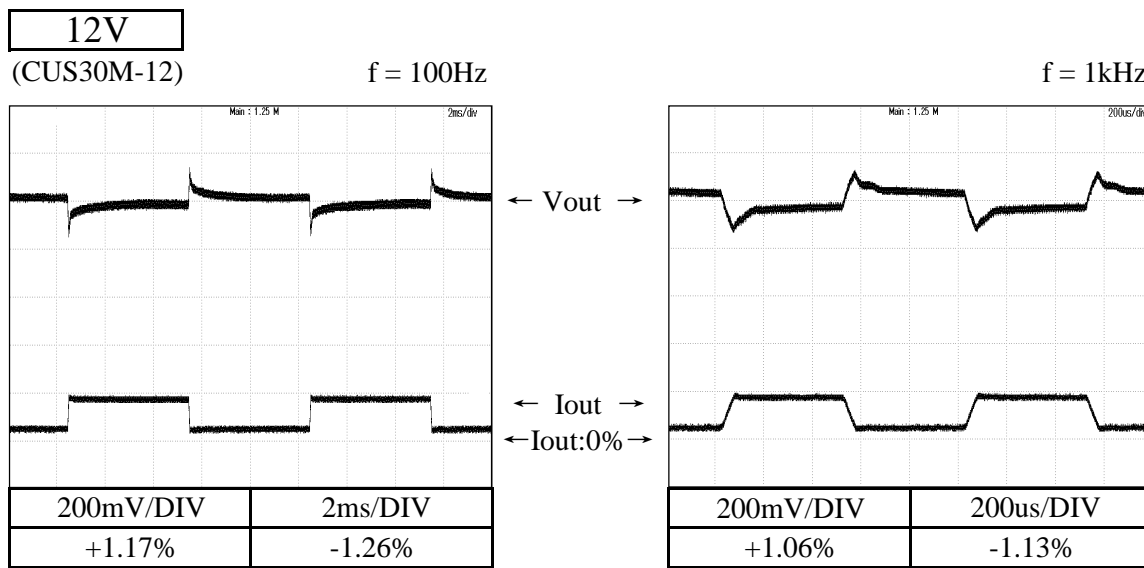
Conditions Vin : 115 VAC -----
 230 VAC —
 Ta : 25 °C

48V
(CUS30M-48)



2.7 過渡応答（負荷急変）特性 Dynamic load response characteristics

Conditions Vin : 115 VAC
 Iout : 25 % ↔ 75 %
 (tr = tf = 50us)
 Ta : 25 °C

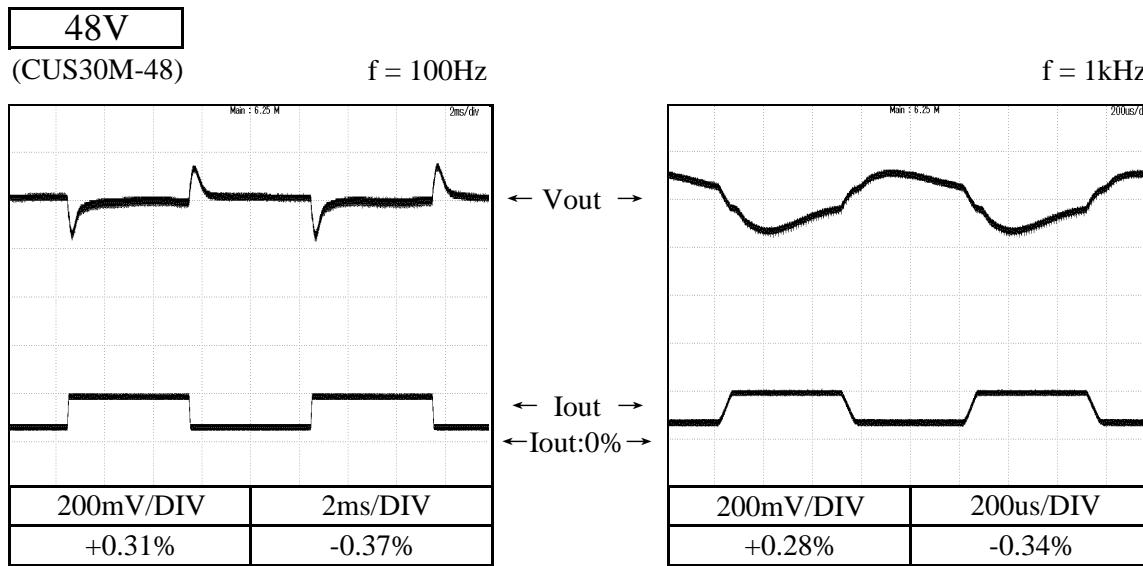


CUS30M

2.7 過渡応答（負荷急変）特性

Dynamic load response characteristics

Conditions Vin : 115 VAC
 Iout : 25 % ↔ 75 %
 (tr = tf = 50us)
 Ta : 25 °C

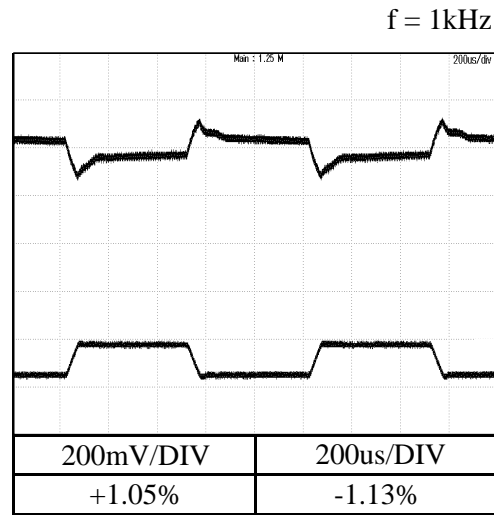
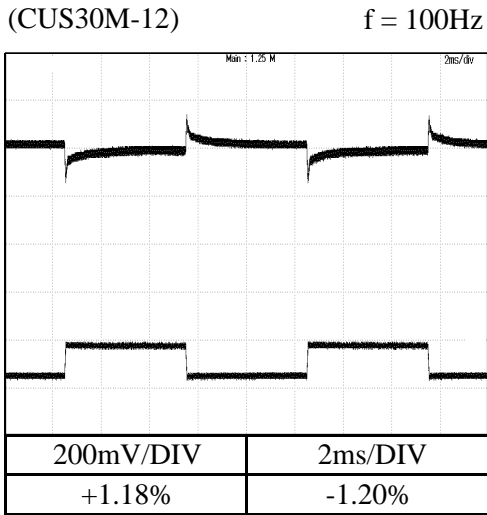


2.7 過渡応答（負荷急変）特性

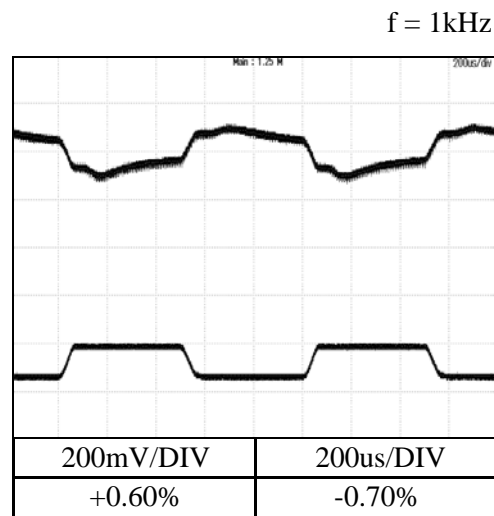
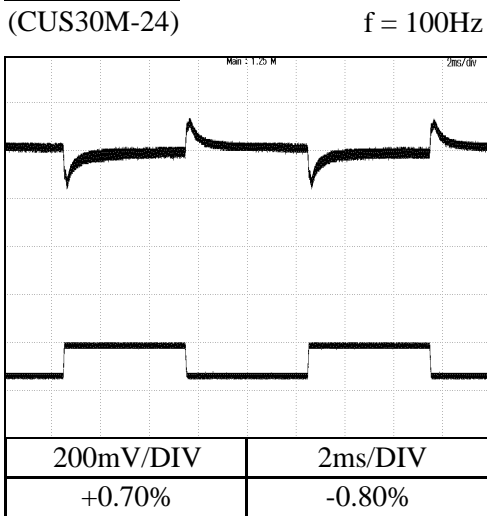
Dynamic load response characteristics

Conditions Vin : 230 VAC
 Iout : 25 % ↔ 75 %
 (tr = tf = 50us)
 Ta : 25 °C

12V
 (CUS30M-12)



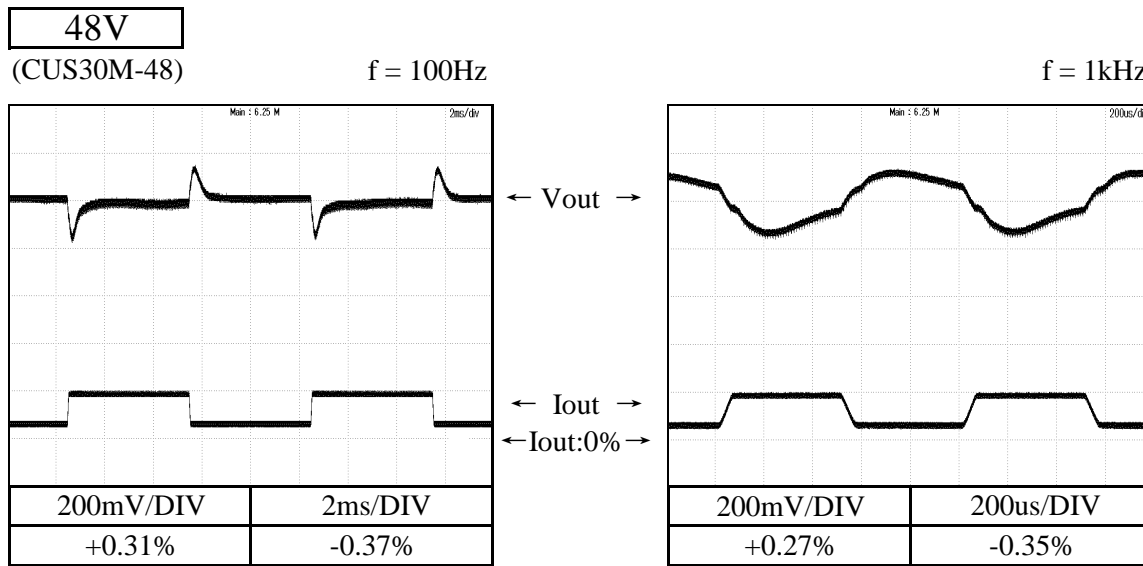
24V
 (CUS30M-24)



CUS30M

2.7 過渡応答（負荷急変）特性 Dynamic load response characteristics

Conditions Vin : 230 VAC
Iout : 25 % ↔ 75 %
(tr = tf = 50us)
Ta : 25 °C



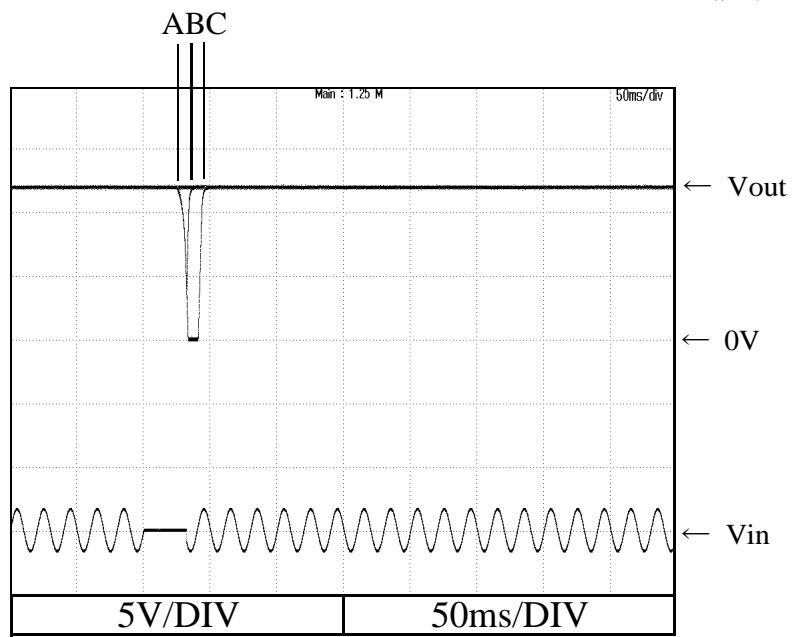
2.8 入力電圧瞬停特性

Response to brown out characteristics

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

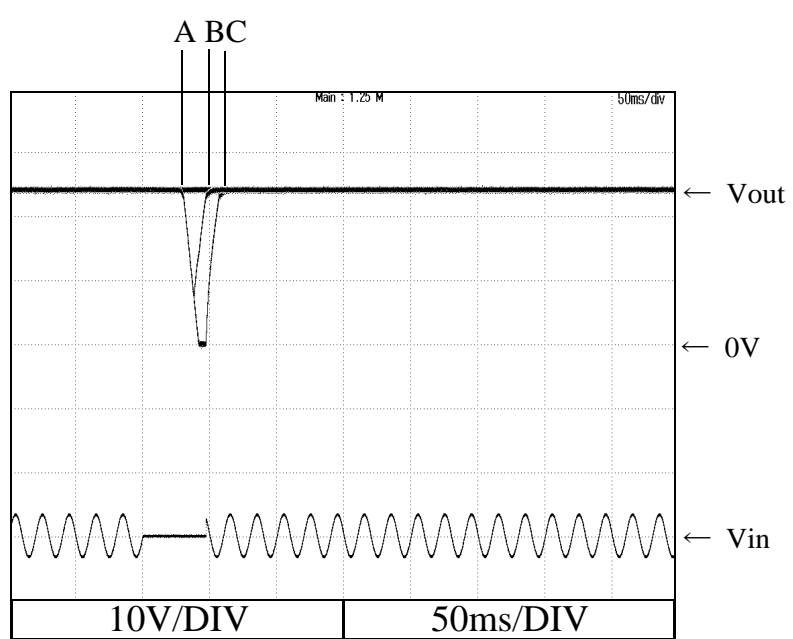
12V
(CUS30M-12)

A = 25ms
B = 32ms
C = 40ms



24V
(CUS30M-24)

A=27ms
B=32ms
C=47ms



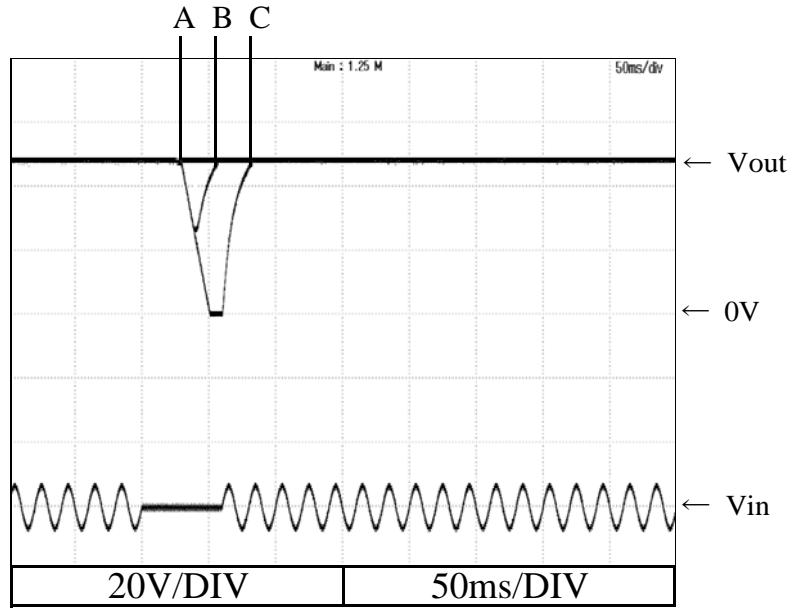
2.8 入力電圧瞬停特性

Response to brown out characteristics

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

48V
(CUS30M-48)

A = 18ms
B = 24ms
C = 30ms



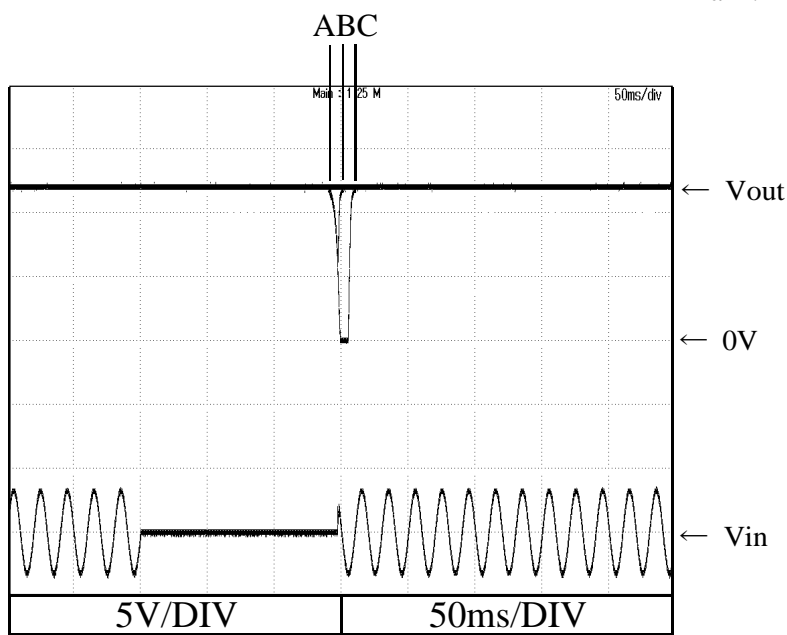
2.8 入力電圧瞬停特性

Response to brown out characteristics

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

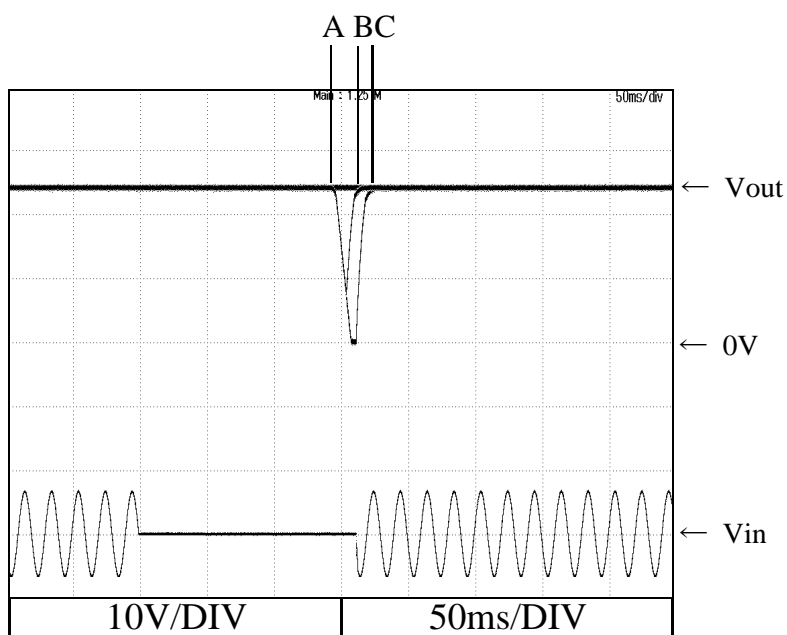
12V
(CUS30M-12)

A = 138ms
B = 147ms
C = 155ms



24V
(CUS30M-24)

A = 140ms
B = 148ms
C = 162ms



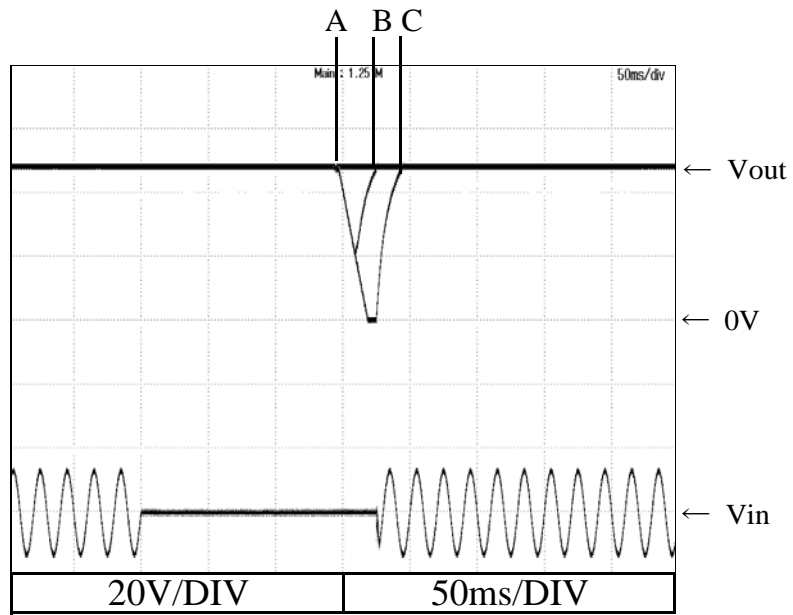
2.8 入力電圧瞬停特性

Response to brown out characteristics

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

48V
(CUS30M-48)

A = 109ms
B = 114ms
C = 121ms

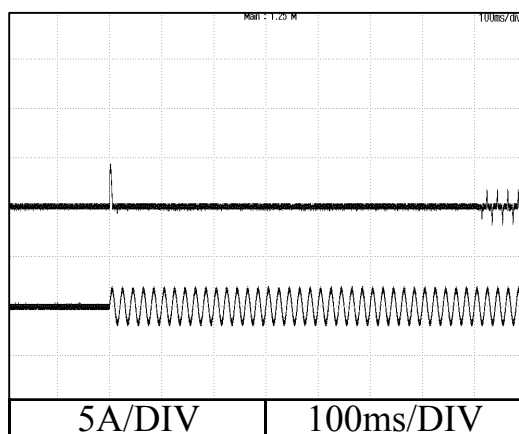


2.9 入力サージ電流（突入電流）波形
Inrush current waveform

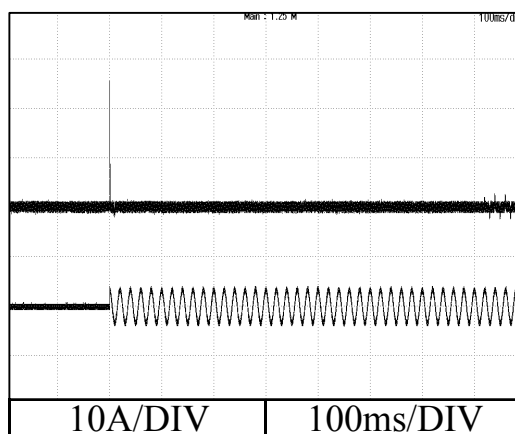
12V
(CUS30M-12)

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C
Cold start

Switch on phase angle of input AC voltage
 $\Phi=0^\circ$

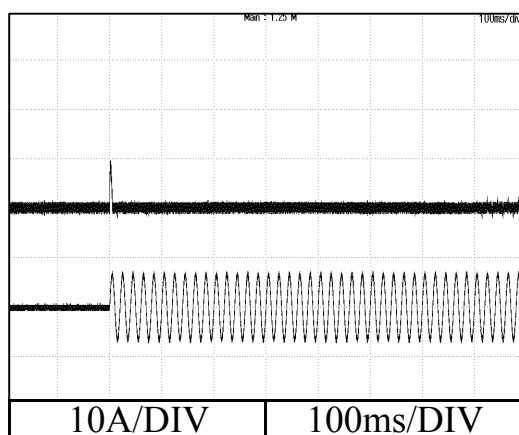


Switch on phase angle of input AC voltage
 $\Phi=90^\circ$

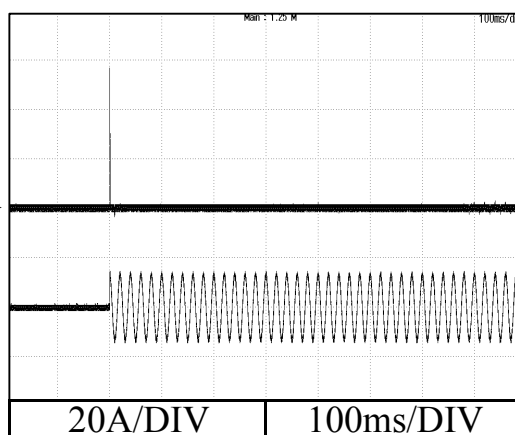


Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C
Cold start

Switch on phase angle of input AC voltage
 $\Phi=0^\circ$



Switch on phase angle of input AC voltage
 $\Phi=90^\circ$

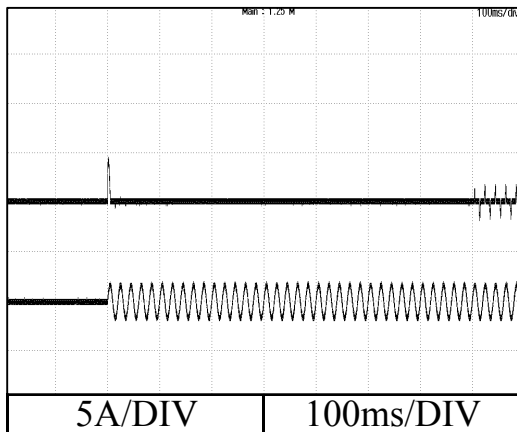


2.9 入力サージ電流（突入電流）波形
Inrush current waveform

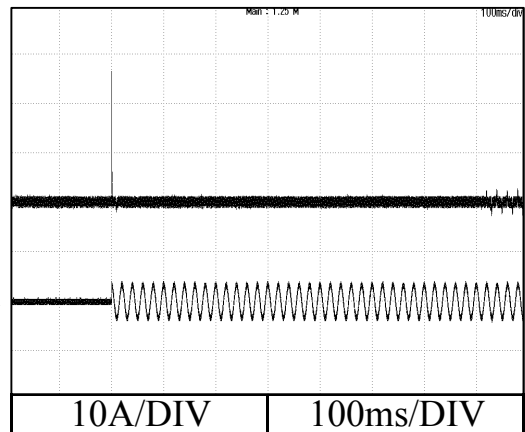
24V
(CUS30M-24)

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C
Cold start

Switch on phase angle of input AC voltage
 $\Phi=0^\circ$

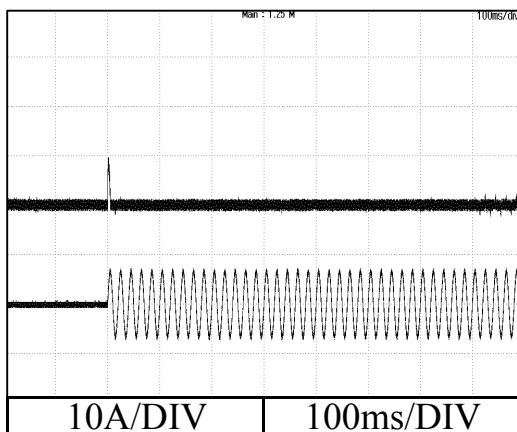


Switch on phase angle of input AC voltage
 $\Phi=90^\circ$

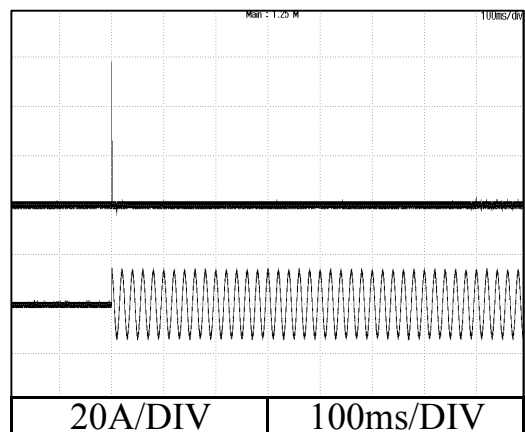


Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C
Cold start

Switch on phase angle of input AC voltage
 $\Phi=0^\circ$



Switch on phase angle of input AC voltage
 $\Phi=90^\circ$

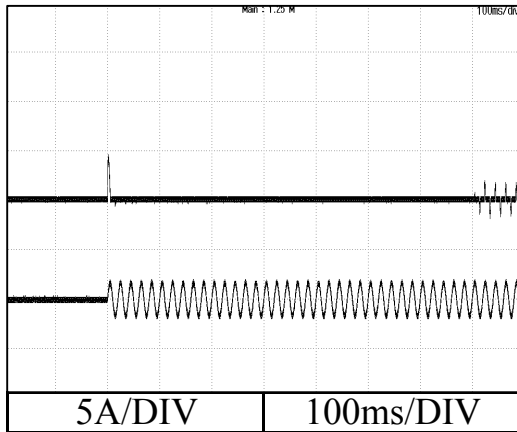


2.9 入力サージ電流（突入電流）波形
Inrush current waveform

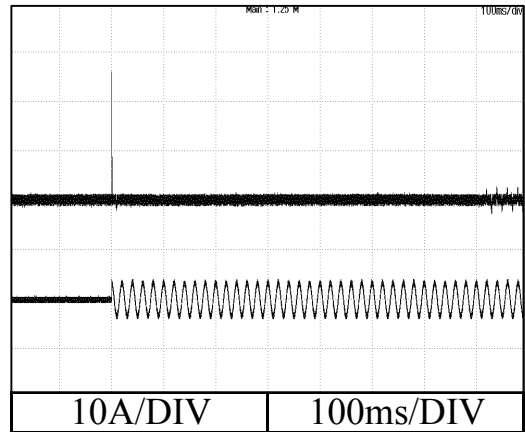
48V
(CUS30M-48)

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C
Cold start

Switch on phase angle of input AC voltage
 $\Phi=0^\circ$

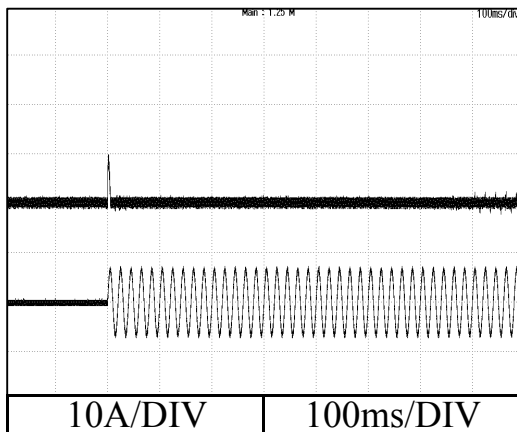


Switch on phase angle of input AC voltage
 $\Phi=90^\circ$

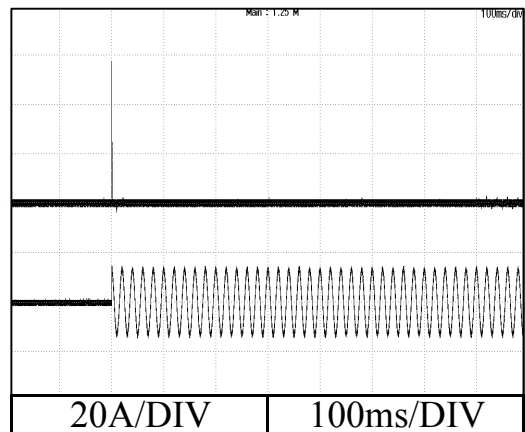


Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C
Cold start

Switch on phase angle of input AC voltage
 $\Phi=0^\circ$



Switch on phase angle of input AC voltage
 $\Phi=90^\circ$



2.10 リーク電流特性
Leakage current characteristics

CUS30M

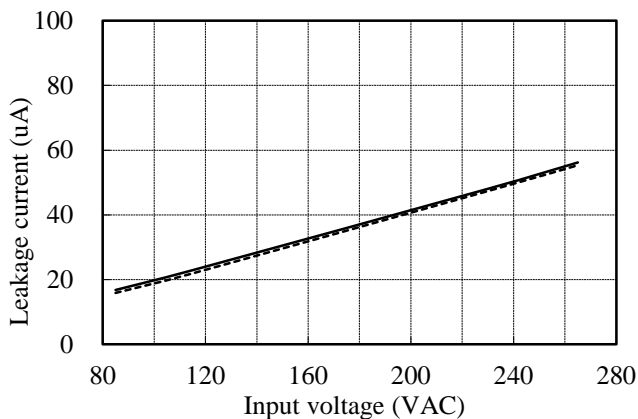
Conditions Iout : 0 % -----
100 % ————
Ta : 25 °C
Equipment used : SIQ16042

12V
(CUS30M-12)

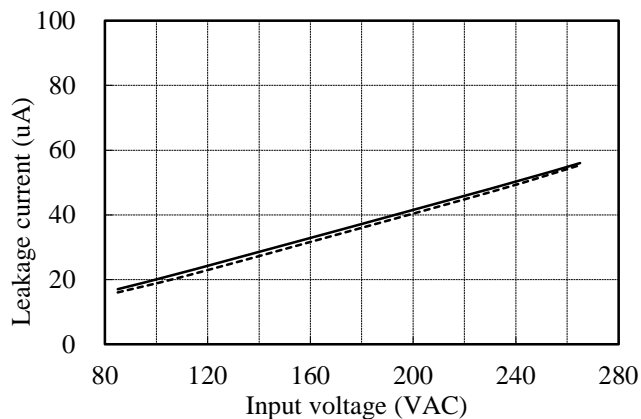
Patient leakage current of CLASS I equipment

f : 50 Hz

Normal condition

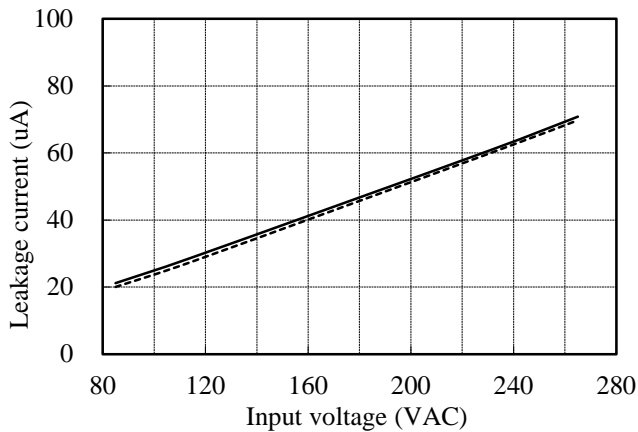


Single fault condition(Open FG)

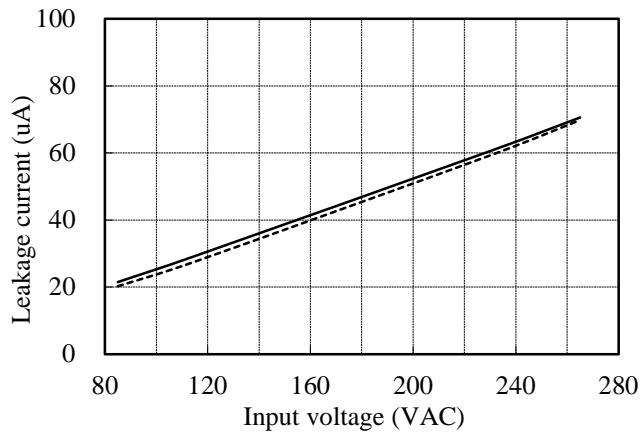


f : 60 Hz

Normal condition



Single fault condition(Open FG)



2.10 リーク電流特性
Leakage current characteristics

CUS30M

Conditions Iout : 0 % -----
 100 % ————
 Ta : 25 °C
Equipment used : SIQ16042

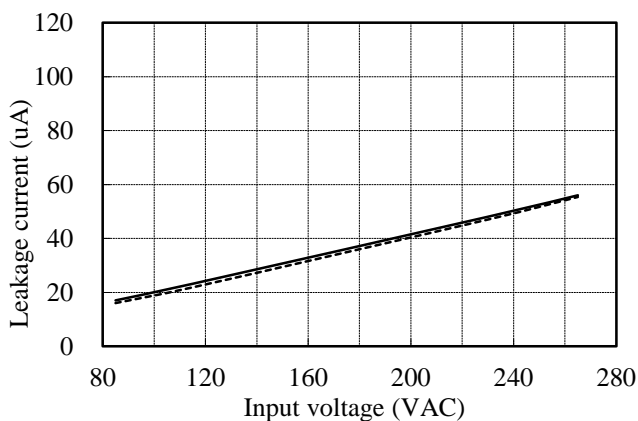
12V

(CUS30M-12)

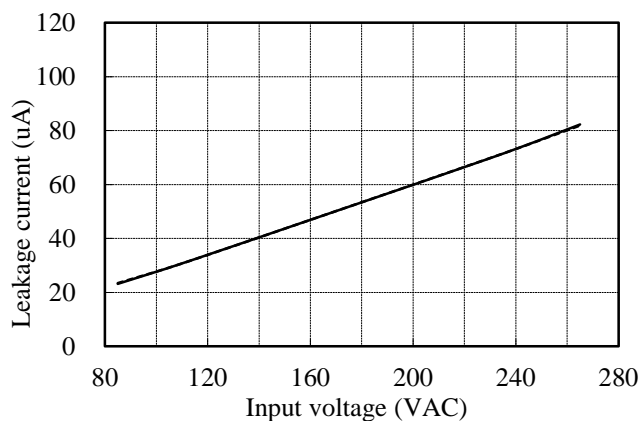
Patient leakage current of CLASS II equipment

f : 50 Hz

Normal condition

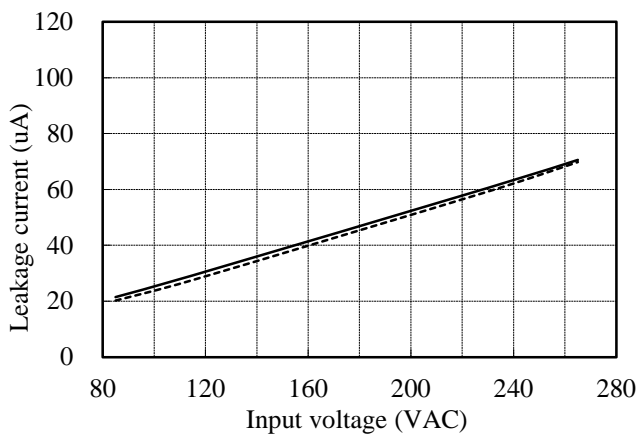


Single fault condition(Open L or N)

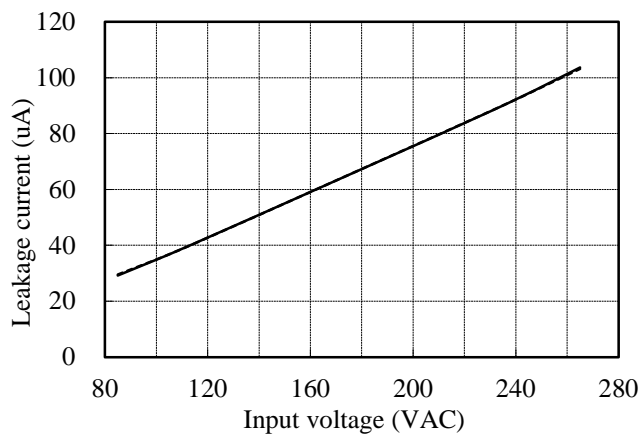


f : 60 Hz

Normal condition



Single fault condition(Open L or N)



2.10 リーク電流特性
Leakage current characteristics

CUS30M

Conditions Iout : 0 % -----
 100 % ————
 Ta : 25 °C
Equipment used : SIMPSON228

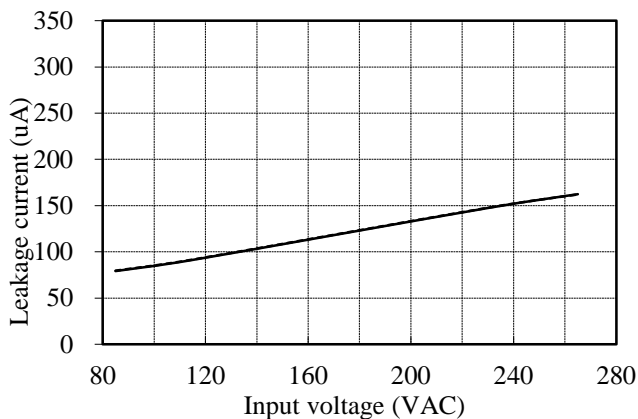
12V

(CUS30M-12)

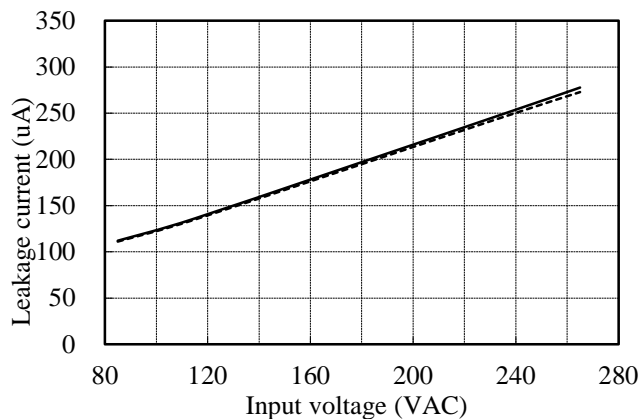
Earth leakage current of CLASS I equipment

f : 50 Hz

Normal condition

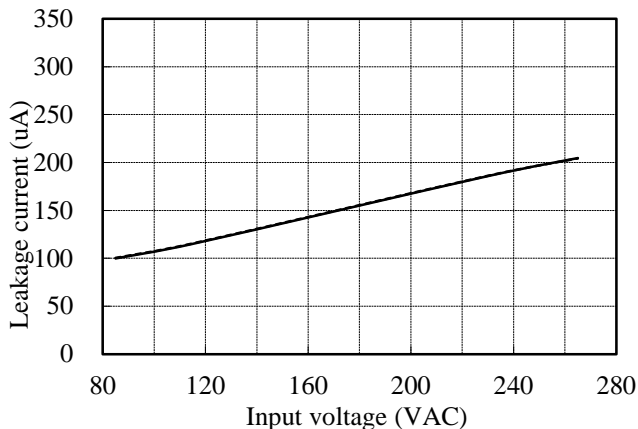


Single fault condition(Open L or N)

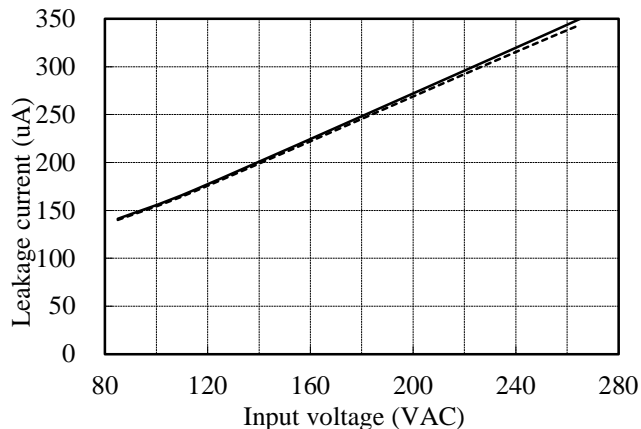


f : 60 Hz

Normal condition



Single fault condition(Open L or N)



2.10 リーク電流特性
Leakage current characteristics

CUS30M

Conditions Iout : 0 % -----
100 % ————
Ta : 25 °C
Equipment used : SIQ16042

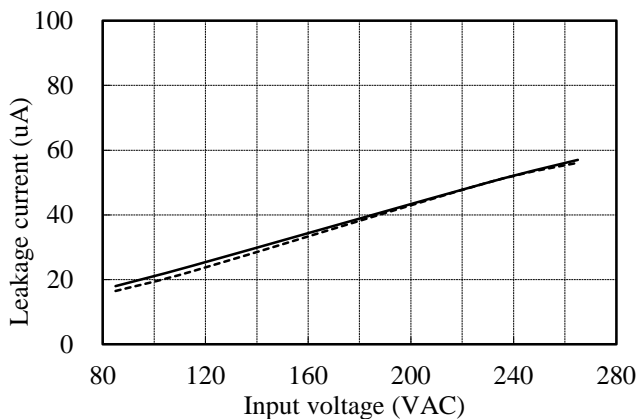
24V

(CUS30M-24)

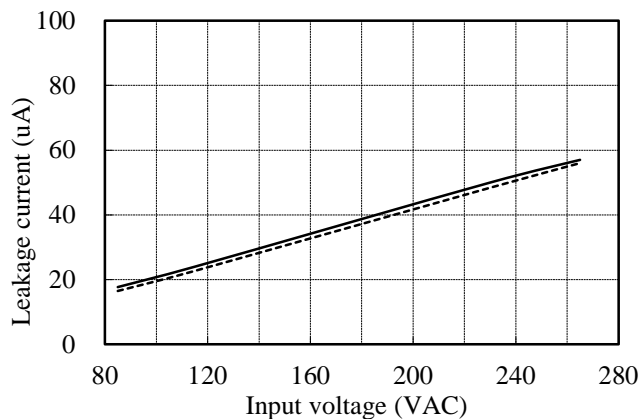
Patient leakage current of CLASS I equipment

f : 50 Hz

Normal condition

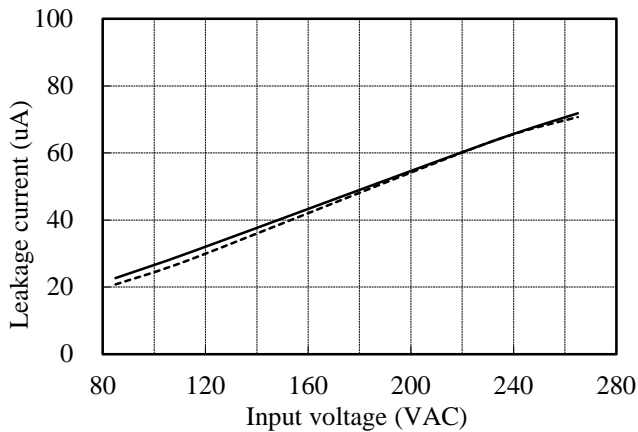


Single fault condition(Open FG)

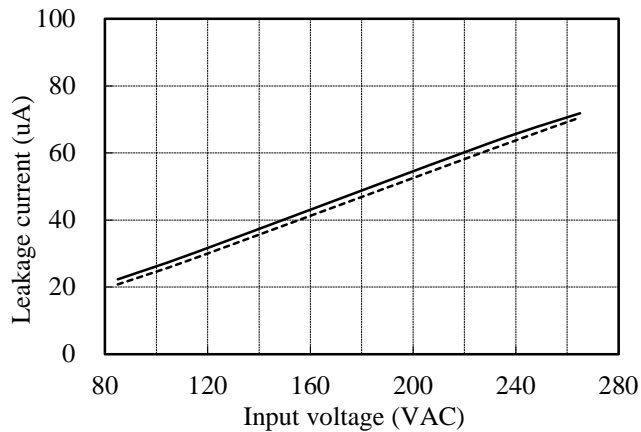


f : 60 Hz

Normal condition



Single fault condition(Open FG)



2.10 リーク電流特性
Leakage current characteristics

CUS30M

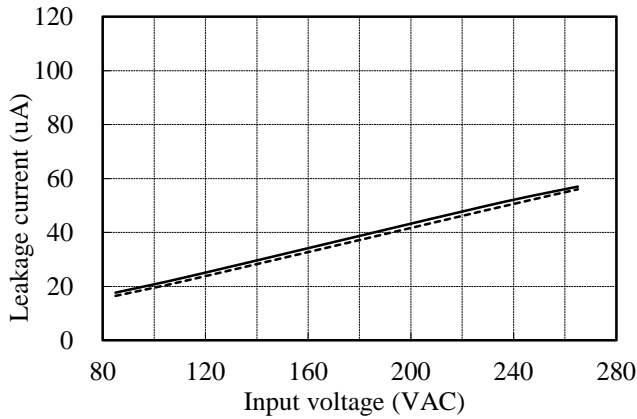
Conditions Iout : 0 % -----
 100 % ————
 Ta : 25 °C
Equipment used : SIQ16042

24V
(CUS30M-24)

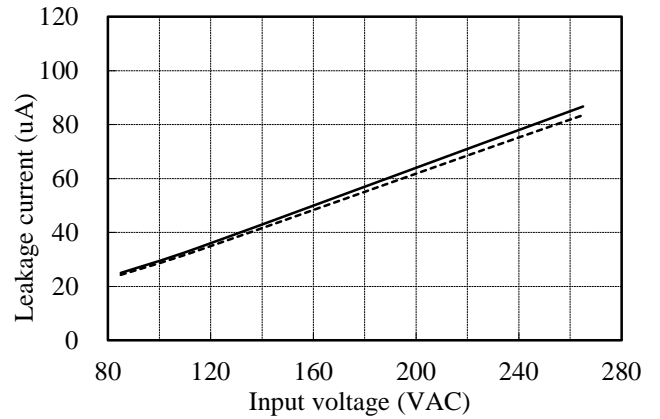
Patient leakage current of CLASS II equipment

f : 50 Hz

Normal condition

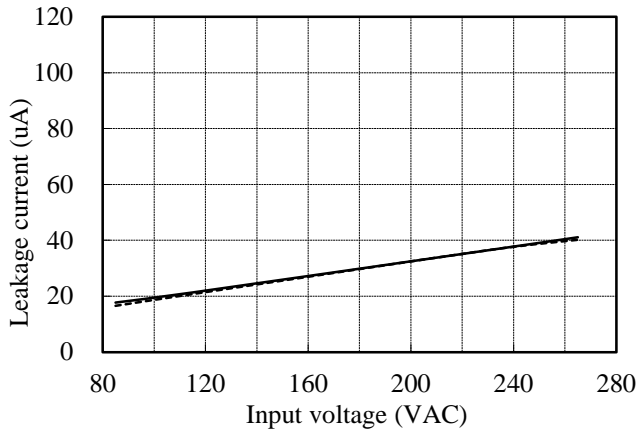


Single fault condition(Open L or N)

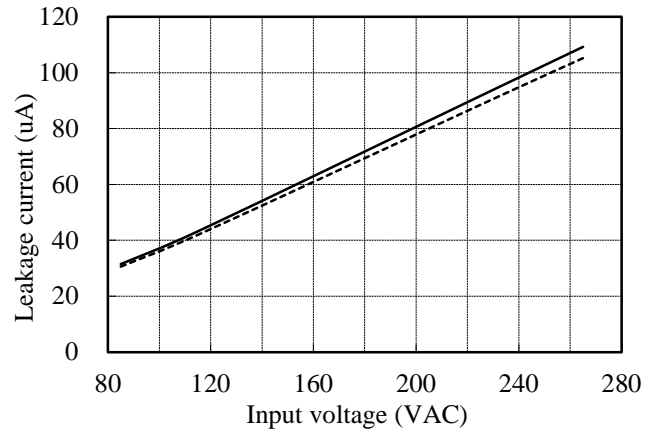


f : 60 Hz

Normal condition



Single fault condition(Open L or N)



2.10 リーク電流特性
Leakage current characteristics

CUS30M

Conditions Iout : 0 % -----
 100 % ————
 Ta : 25 °C
Equipment used : SIMPSON228

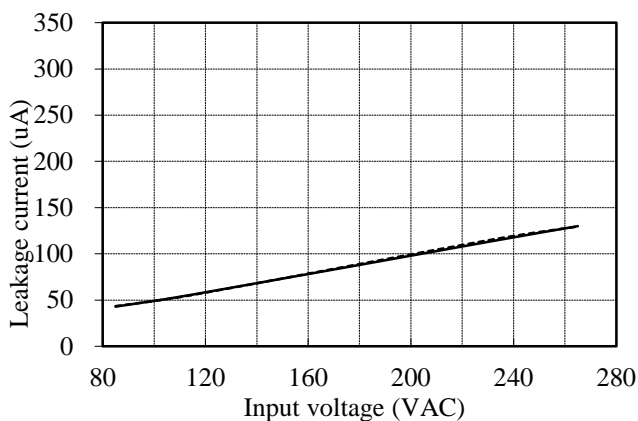
24V

(CUS30M-24)

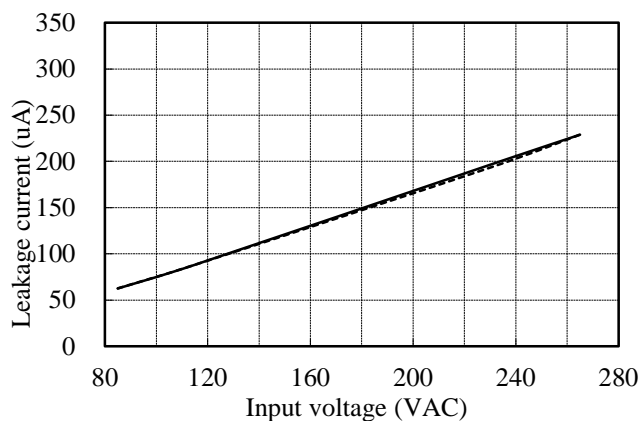
Earth leakage current of CLASS I equipment

f : 50 Hz

Normal condition

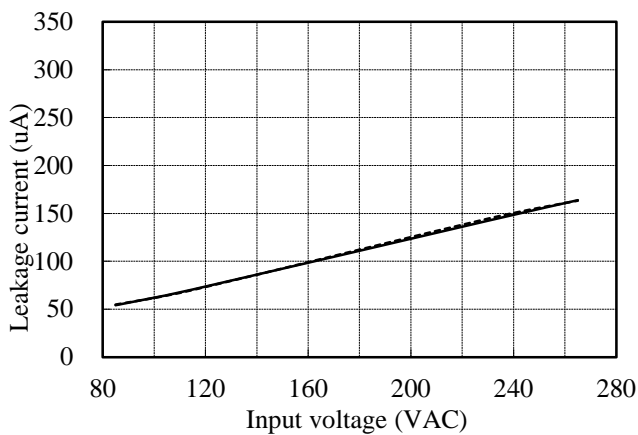


Single fault condition(Open L or N)

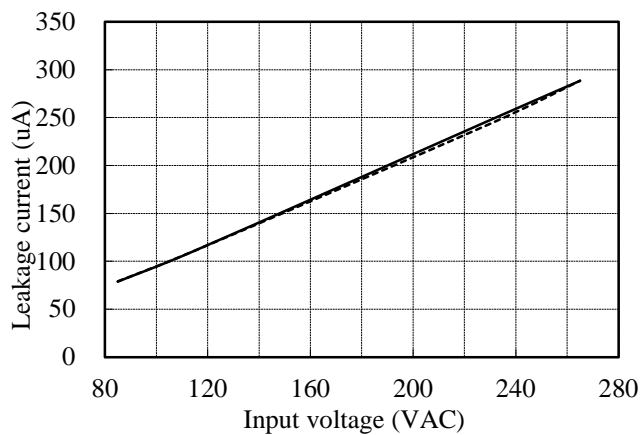


f : 60 Hz

Normal condition



Single fault condition(Open L or N)



2.10 リーク電流特性
Leakage current characteristics

CUS30M

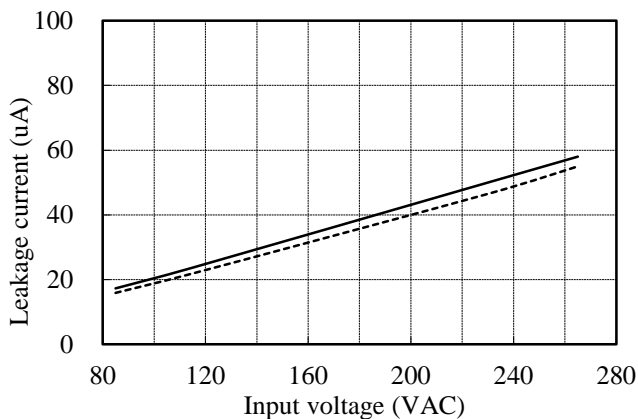
Conditions Iout : 0 % -----
100 % ———
Ta : 25 °C
Equipment used : SIQ16042

48V
(CUS30M-48)

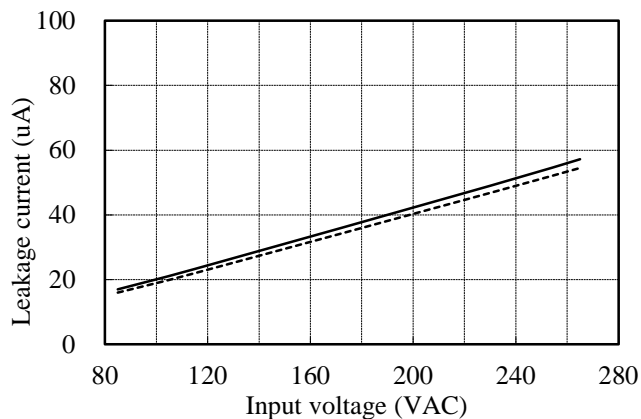
Patient leakage current of CLASS I equipment

f : 50 Hz

Normal condition

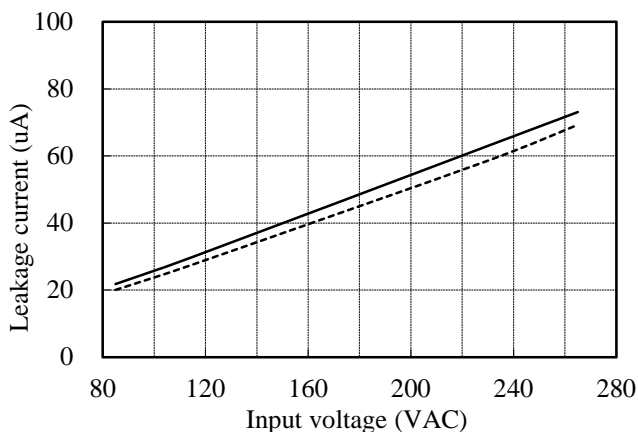


Single fault condition(Open FG)

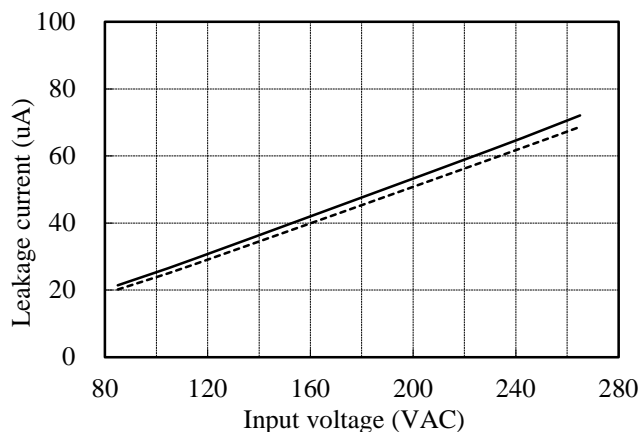


f : 60 Hz

Normal condition



Single fault condition(Open FG)



2.10 リーク電流特性
Leakage current characteristics

CUS30M

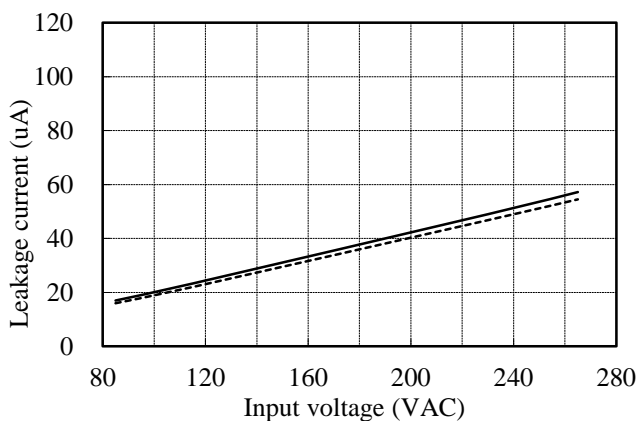
Conditions Iout : 0 % -----
100 % ————
Ta : 25 °C
Equipment used : SIQ16042

48V
(CUS30M-48)

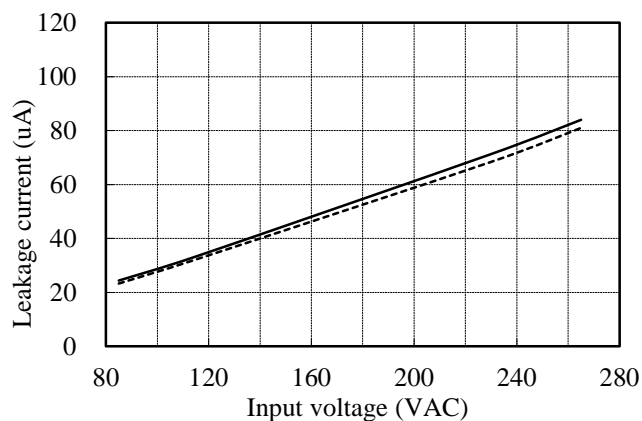
Patient leakage current of CLASS II equipment

f : 50 Hz

Normal condition

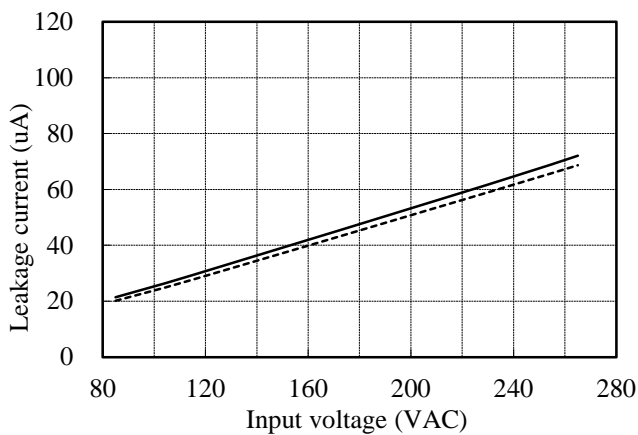


Single fault condition(Open L or N)

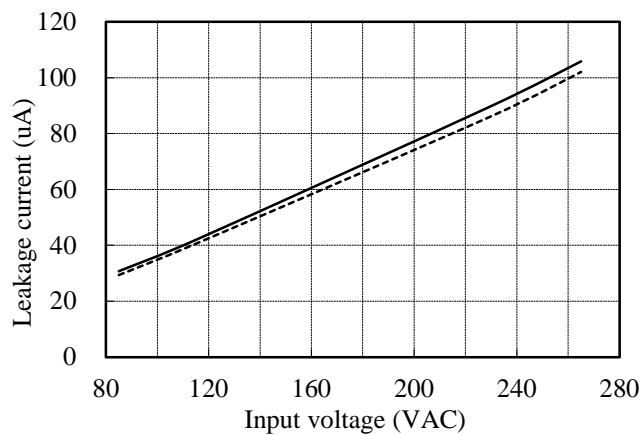


f : 60 Hz

Normal condition



Single fault condition(Open L or N)



2.10 リーク電流特性
Leakage current characteristics

CUS30M

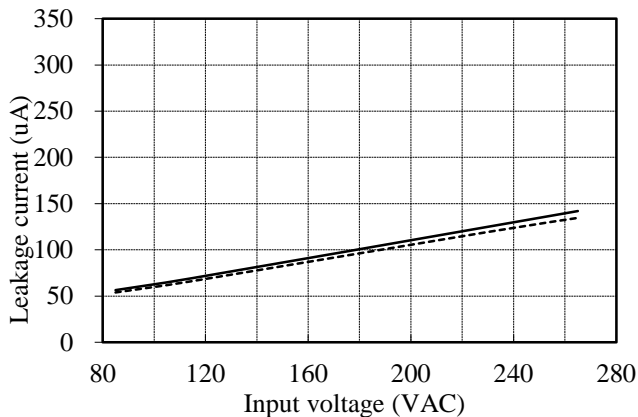
Conditions Iout : 0 % -----
 100 % ————
 Ta : 25 °C
Equipment used : SIMPSON228

48V
(CUS30M-48)

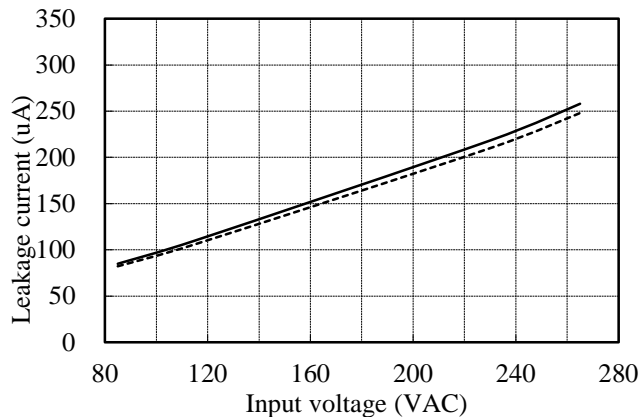
Earth leakage current of CLASS I equipment

f : 50 Hz

Normal condition

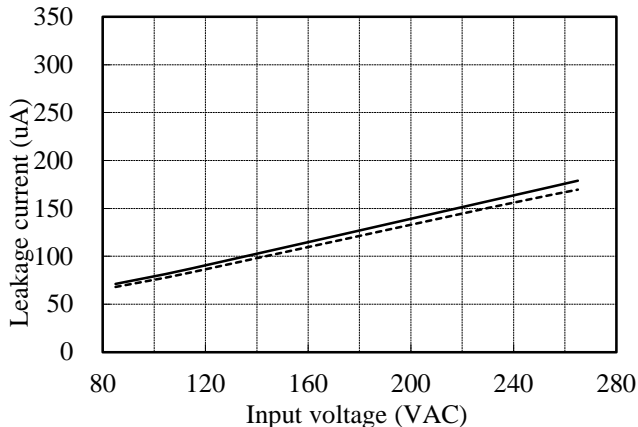


Single fault condition(Open L or N)

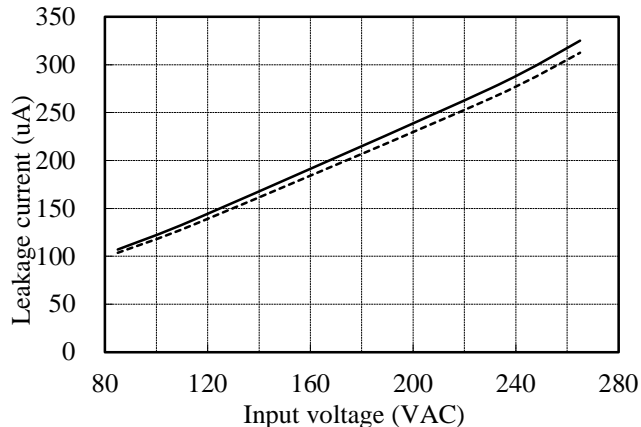


f : 60 Hz

Normal condition



Single fault condition(Open L or N)



2.11 出力リップル、ノイズ波形
Output ripple and noise waveform

CUS30M

Conditions

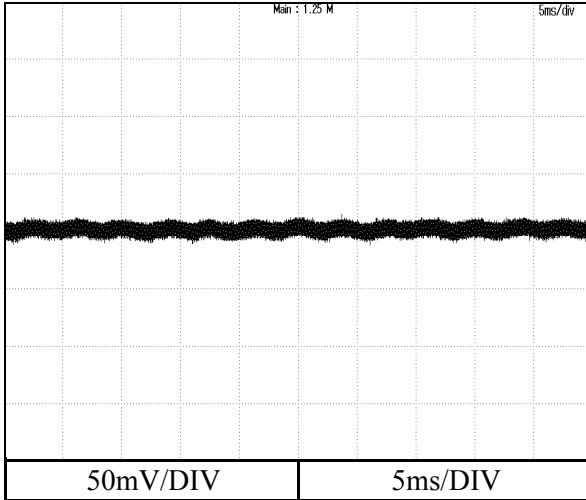
Vin : 115 VAC

Ta : 25 °C

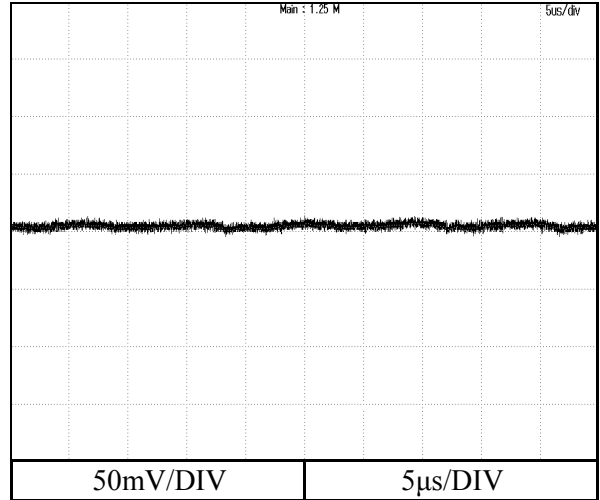
12V

(CUS30M-12)

Iout : 100%



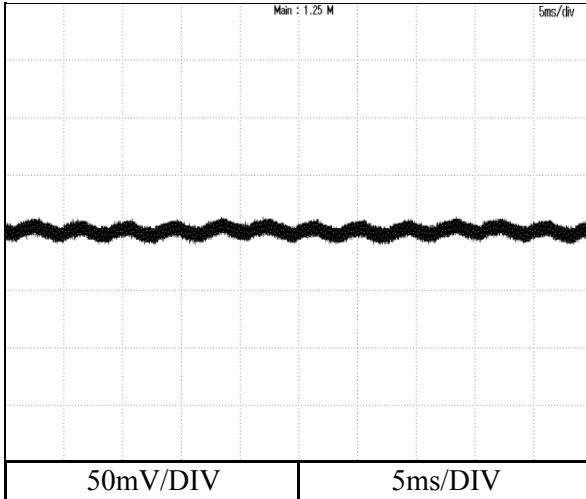
Iout : 100%



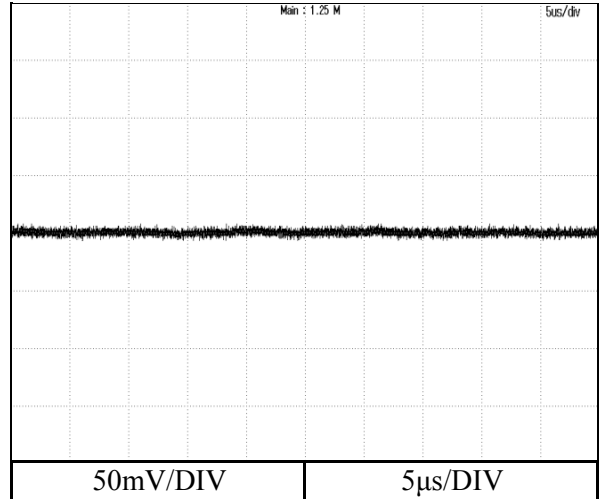
24V

(CUS30M-24)

Iout : 100%



Iout : 100%



2.11 出力リップル、ノイズ波形
Output ripple and noise waveform

CUS30M

Conditions

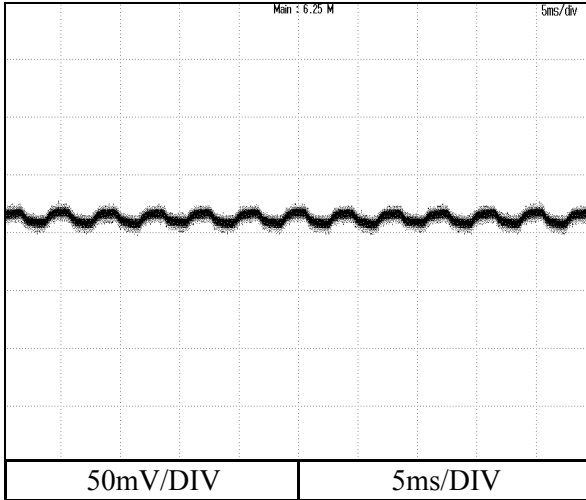
Vin : 115 VAC

Ta : 25 °C

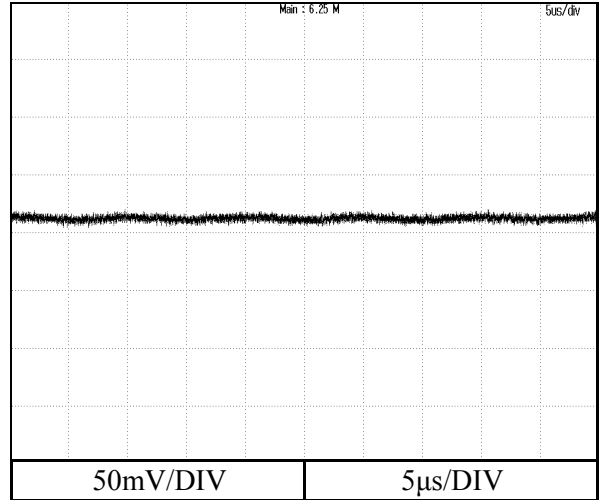
48V

(CUS30M-48)

Iout : 100%



Iout : 100%



2.11 出力リップル、ノイズ波形
Output ripple and noise waveform

CUS30M

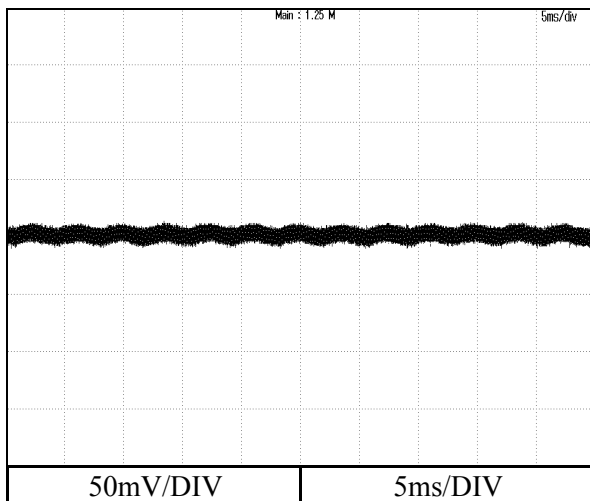
Conditions

Vin : 230 VAC
Ta : 25 °C

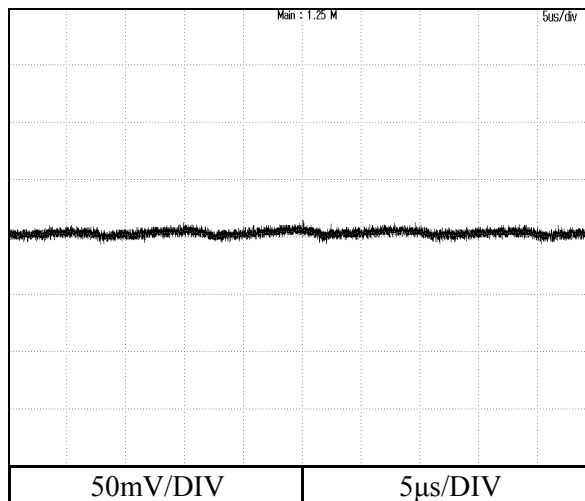
12V

(CUS30M-12)

Iout : 100%



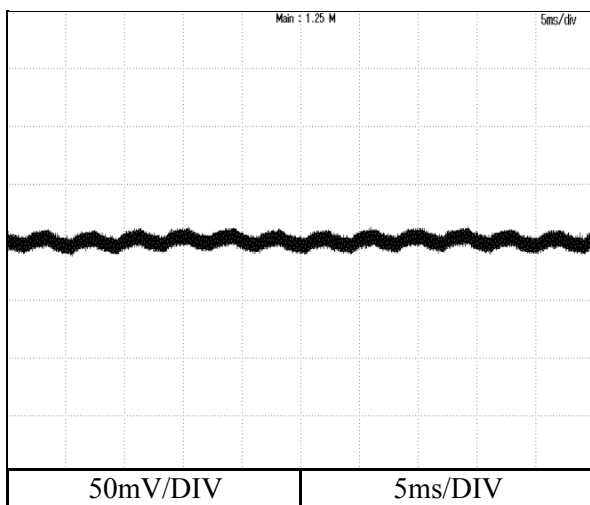
Iout : 100%



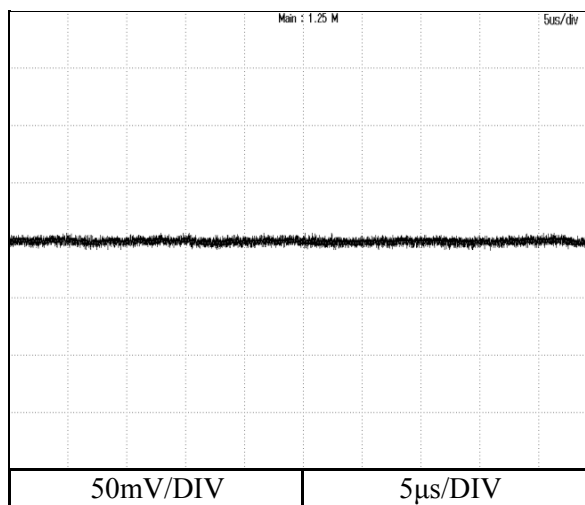
24V

(CUS30M-24)

Iout : 100%



Iout : 100%



2.11 出力リップル、ノイズ波形
Output ripple and noise waveform

CUS30M

Conditions

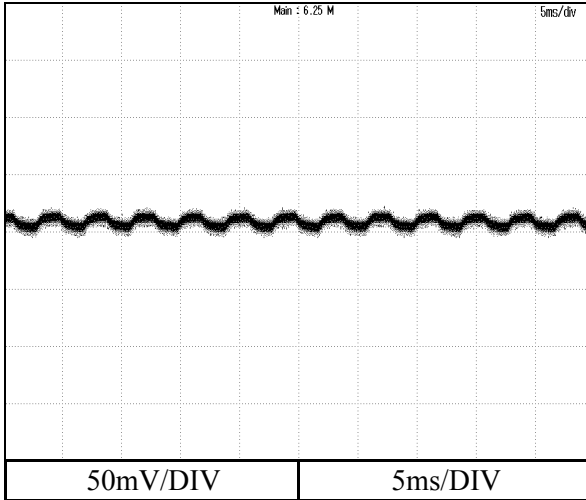
Vin : 230 VAC

Ta : 25 °C

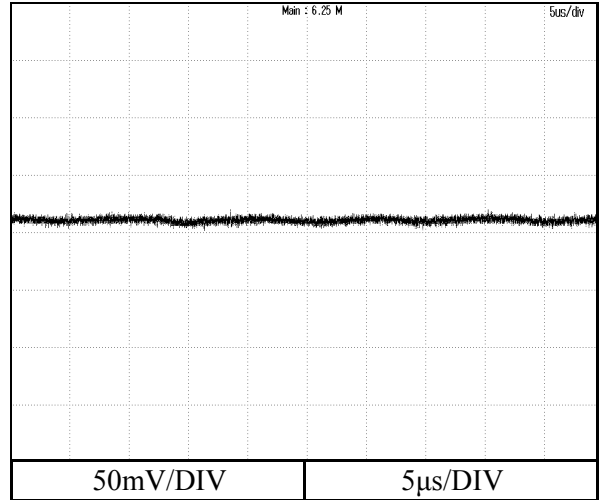
48V

(CUS30M-48)

Iout : 100%



Iout : 100%



2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

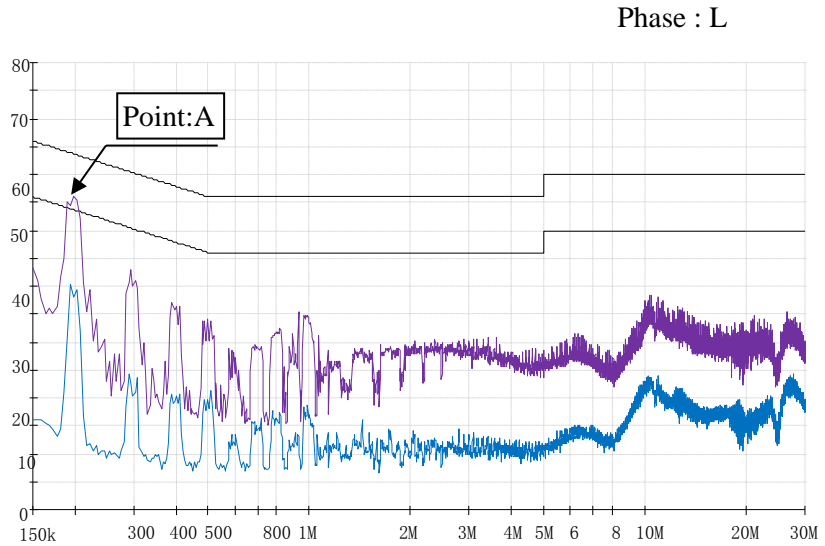
雑音端子電圧

Conducted Emission (CLASS I)

12V

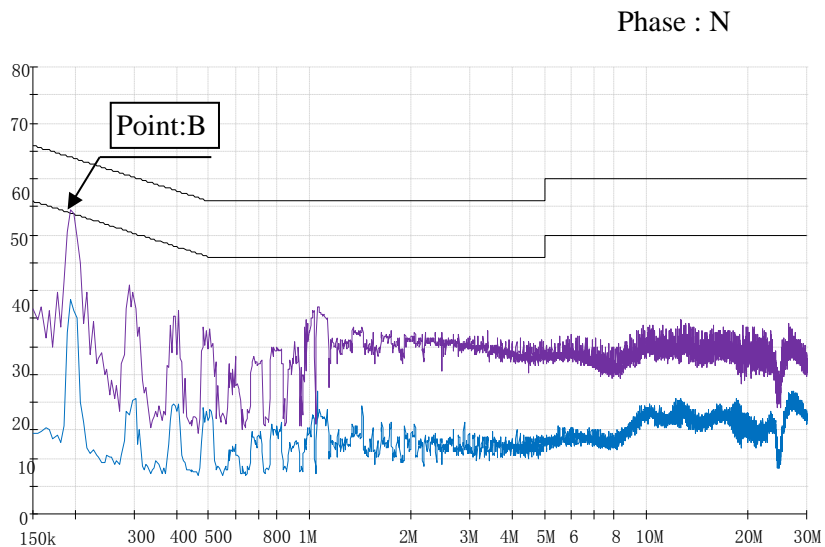
(CUS30M-12)

Point A (0.195MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	53.8
AV	53.6	38.2



EN55032 Class B QP Limit
←
←
EN55032 Class B AV Limit

Point B (0.190MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	64.0	51.3
AV	53.8	35.5



EN55032 Class B QP Limit
←
←
EN55032 Class B AV Limit

EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ
Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

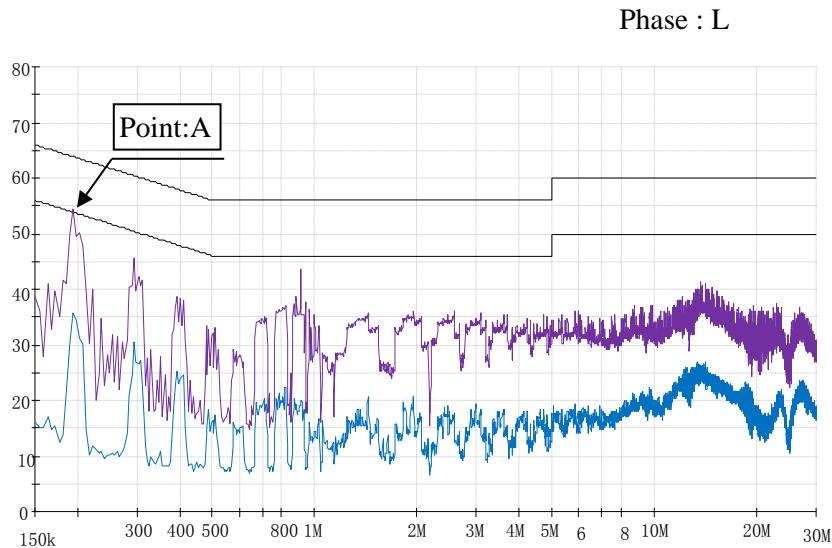
雑音端子電圧

Conducted Emission (CLASS I)

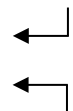
12V

(CUS30M-12)

Point A (0.195MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	51.8
AV	53.4	33.7

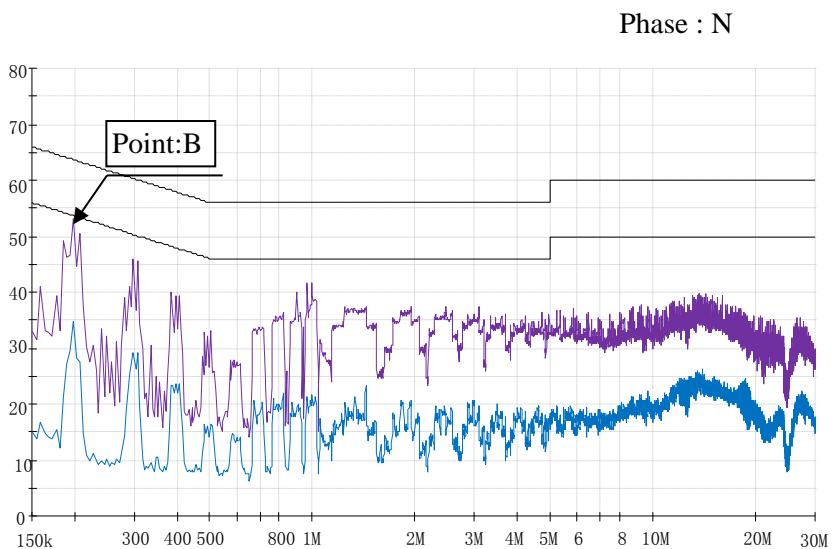


EN55032
Class B
QP Limit

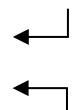


EN55032
Class B
AV Limit

Point B (0.20MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.6	51.5
AV	53.4	32.1



EN55032
Class B
QP Limit



EN55032
Class B
AV Limit

EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ
Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

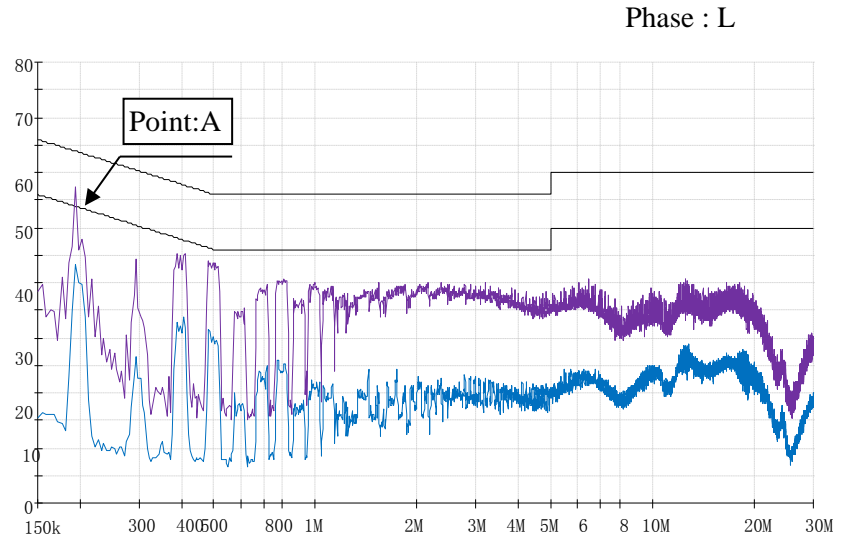
雑音端子電圧

Conducted Emission (CLASS II)

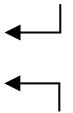
12V

(CUS30M-12)

Point A (0.195MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	54.9
AV	53.8	42.1

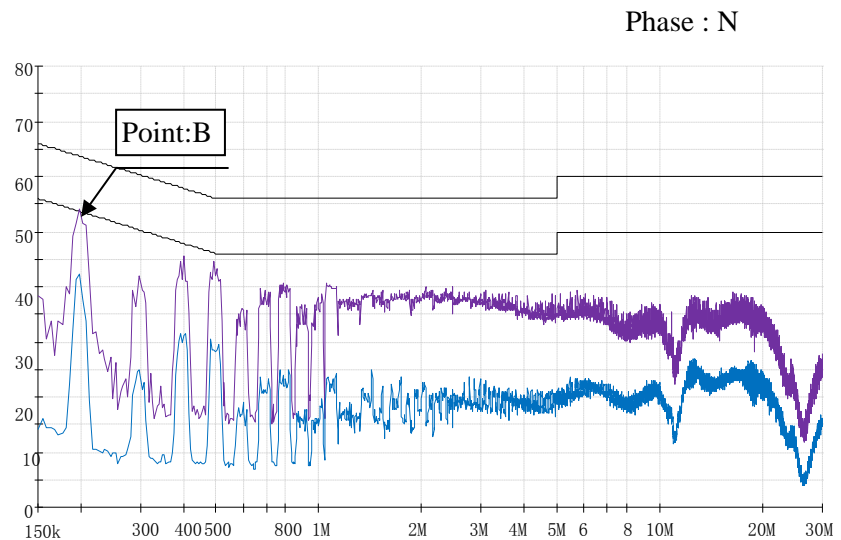


EN55032
Class B
QP Limit

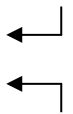


EN55032
Class B
AV Limit

Point B (0.204MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.4	51.7
AV	53.8	41.1



EN55032
Class B
QP Limit



EN55032
Class B
AV Limit

EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ

Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

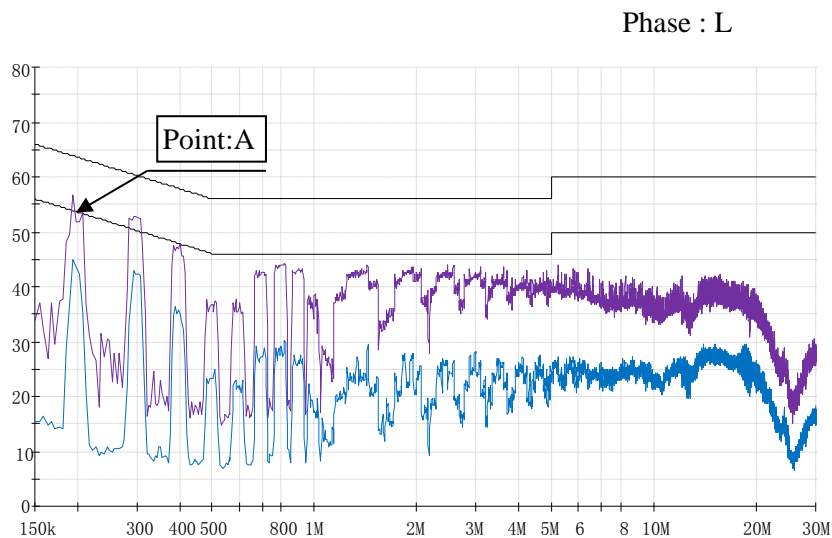
雑音端子電圧

Conducted Emission (CLASS II)

12V

(CUS30M-12)

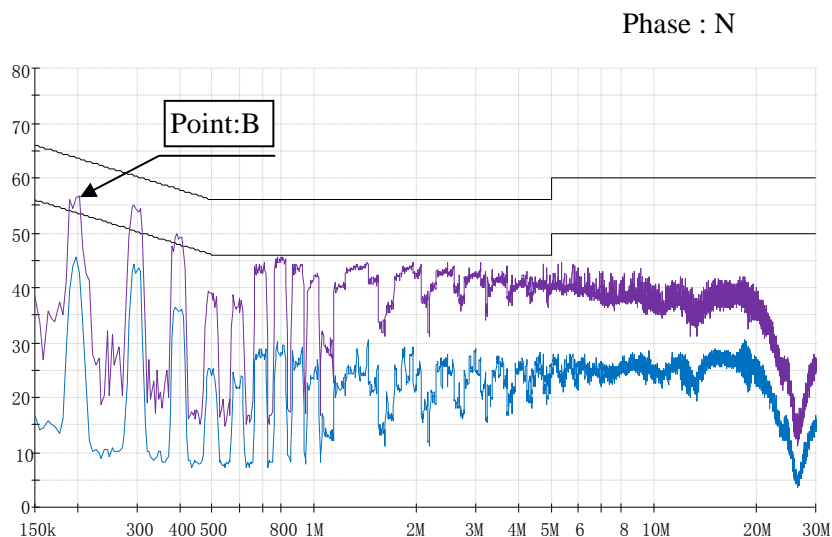
Point A (0.195MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	53.8
AV	53.4	42.6



EN55032
Class B
QP Limit

EN55032
Class B
AV Limit

Point B (0.204MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.4	54.2
AV	53.8	44.8



EN55032
Class B
QP Limit

EN55032
Class B
AV Limit

EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ
Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

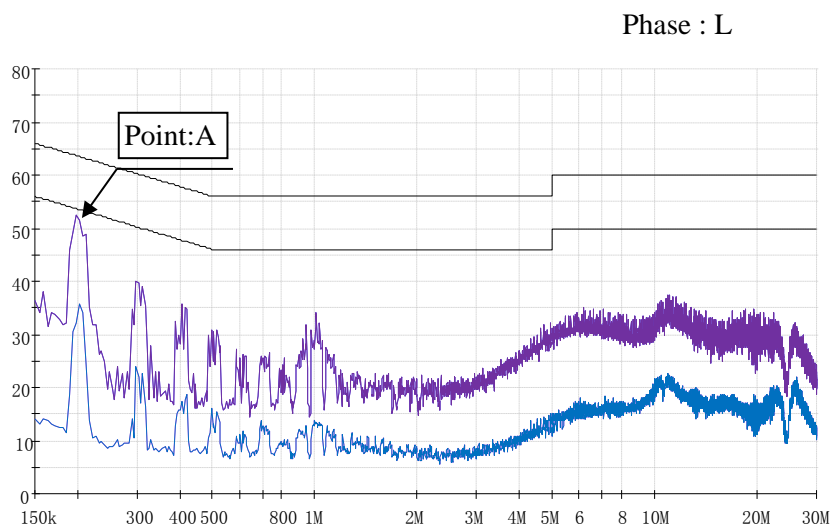
雑音端子電圧

Conducted Emission (CLASS I)

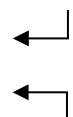
24V

(CUS30M-24)

Point A (0.21MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	54.1
AV	53.8	34.7



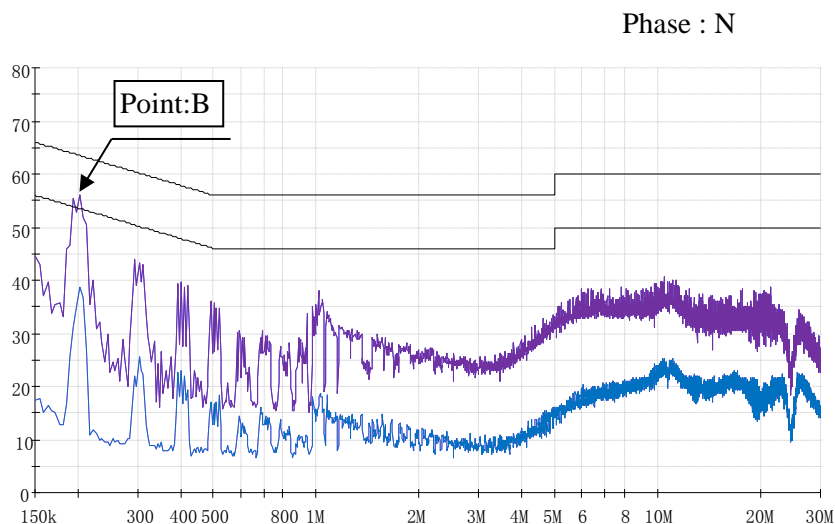
EN55032
Class B
QP Limit



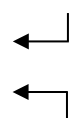
EN55032
Class B
AV Limit



Point B (0.20MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	53.2
AV	53.8	36.8



EN55032
Class B
QP Limit



EN55032
Class B
AV Limit



EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ

Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

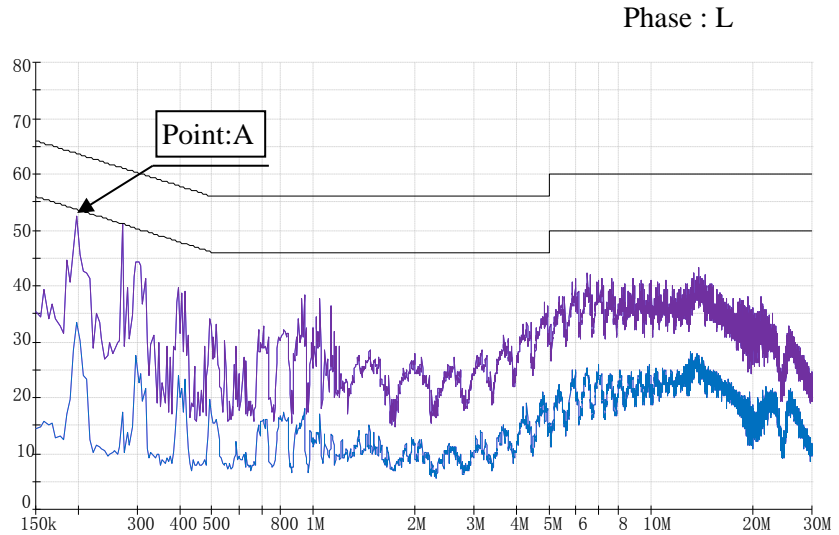
雑音端子電圧

Conducted Emission (CLASS I)

24V

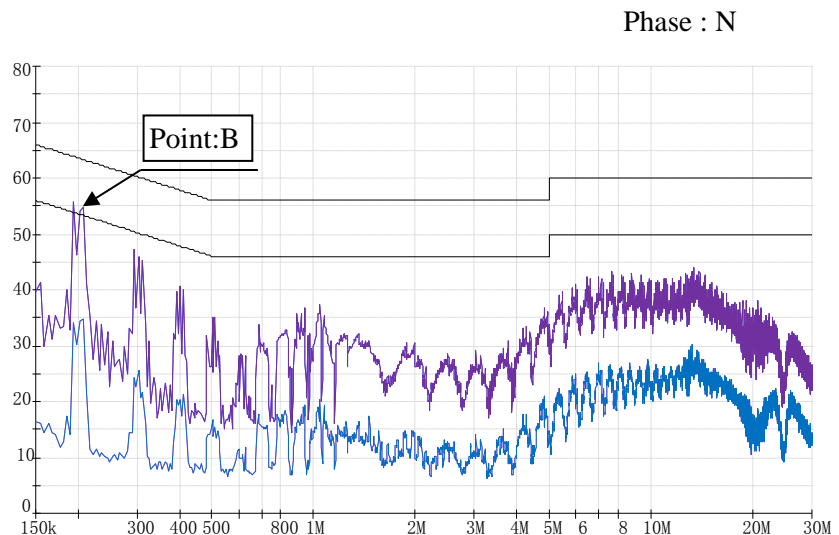
(CUS30M-24)

Point A (0.19MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	53.1
AV	53.8	31.0



EN55032
Class B
QP Limit
←
←
EN55032
Class B
AV Limit

Point B (0.19MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	53.0
AV	53.8	32.2



EN55032
Class B
QP Limit
←
←
EN55032
Class B
AV Limit

EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ
Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

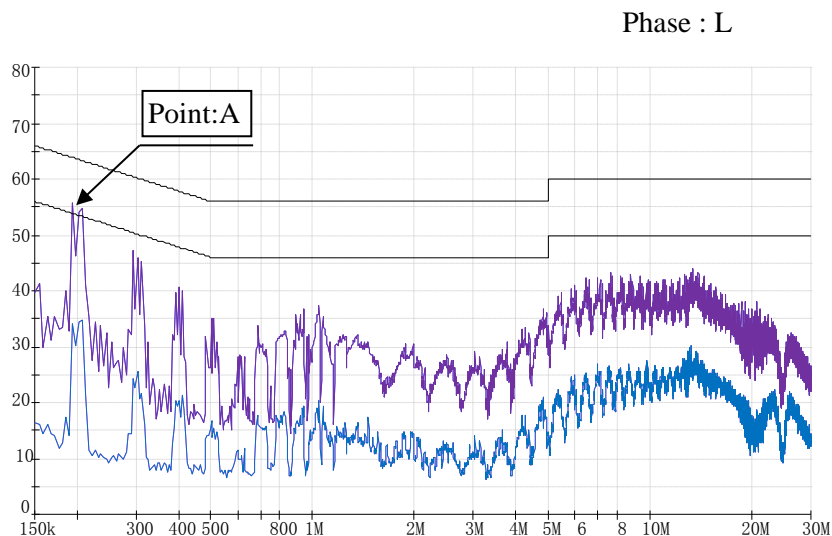
雑音端子電圧

Conducted Emission (CLASS II)

24V

(CUS30M-24)

Point A (1.88MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	55.0
AV	53.8	44.1

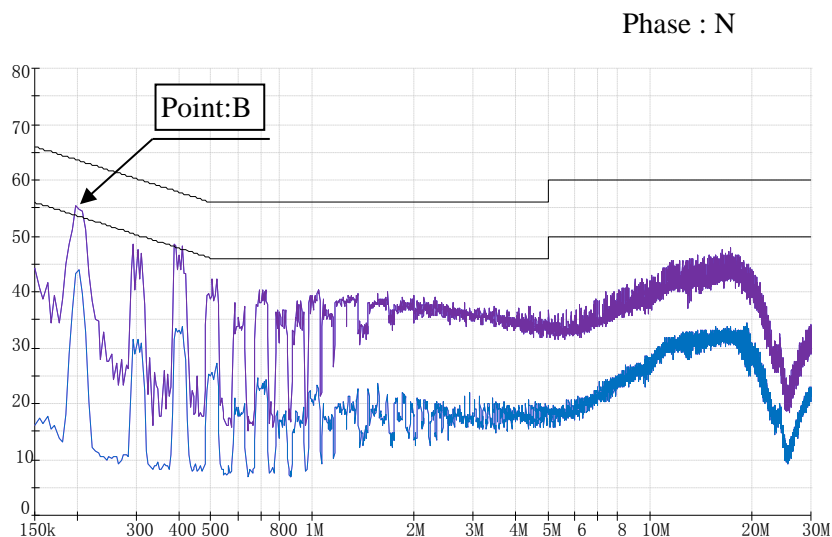


EN55032
Class B
QP Limit



EN55032
Class B
AV Limit

Point B (3.18MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	55.9
AV	53.8	42.6



EN55032
Class B
QP Limit



EN55032
Class B
AV Limit

EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ

Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

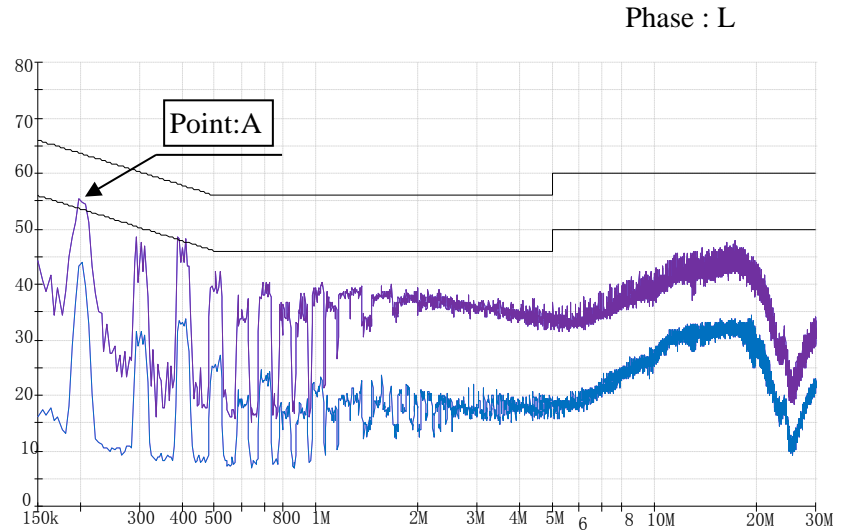
雑音端子電圧

Conducted Emission (CLASS II)

24V

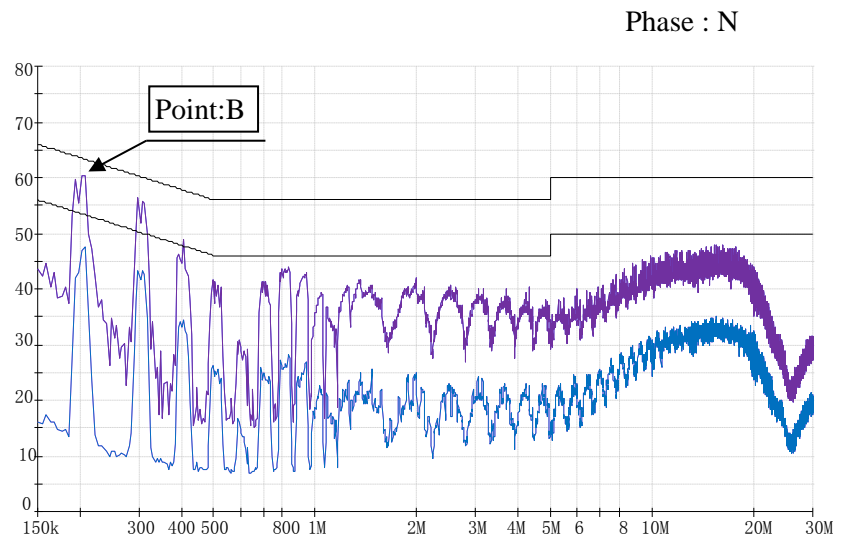
(CUS30M-24)

Point A (0.20MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	56.8
AV	53.8	44.0



EN55032
Class B
QP Limit
←
←
EN55032
Class B
AV Limit

Point B (0.20MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	57.4
AV	53.8	47.3



EN55032
Class B
QP Limit
←
←
EN55032
Class B
AV Limit

EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ
Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

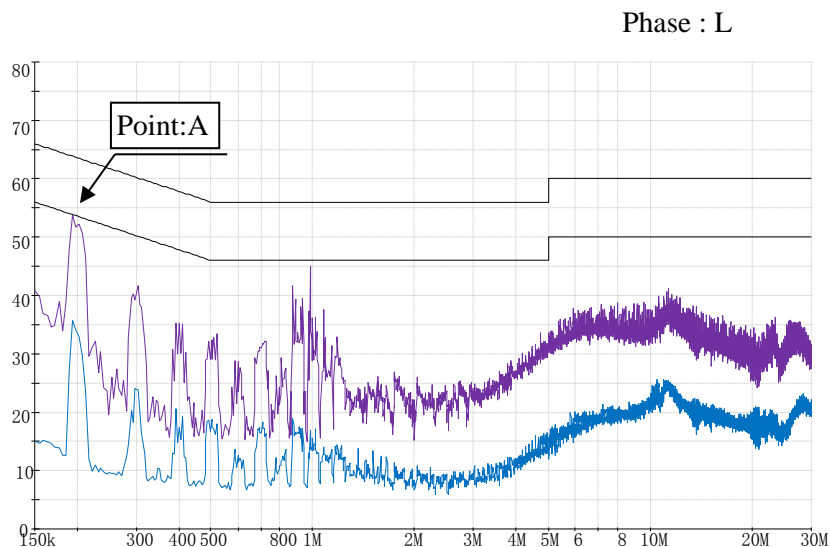
雑音端子電圧

Conducted Emission (CLASS I)

48V

(CUS30M-48)

Point A (0.195MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	52.0
AV	53.6	35.0

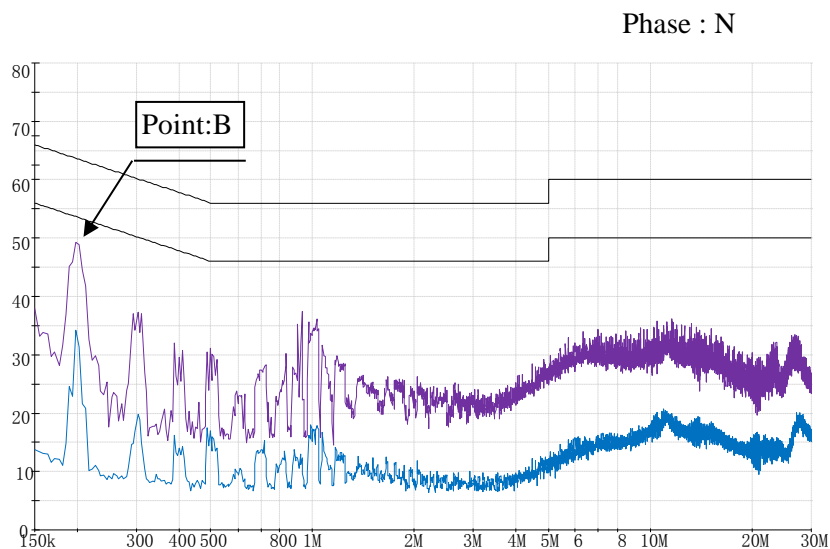


EN55032
Class B
QP Limit



EN55032
Class B
AV Limit

Point B (0.195MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	48.6
AV	53.8	30.9



EN55032
Class B
QP Limit



EN55032
Class B
AV Limit

EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ

Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

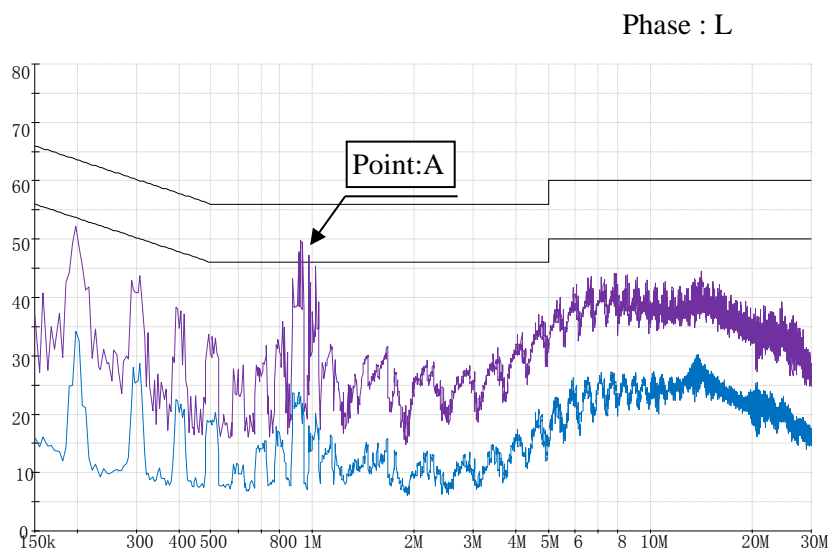
雑音端子電圧

Conducted Emission (CLASS I)

48V

(CUS30M-48)

Point A (0.929MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	56.0	39.6
AV	46.0	30.0

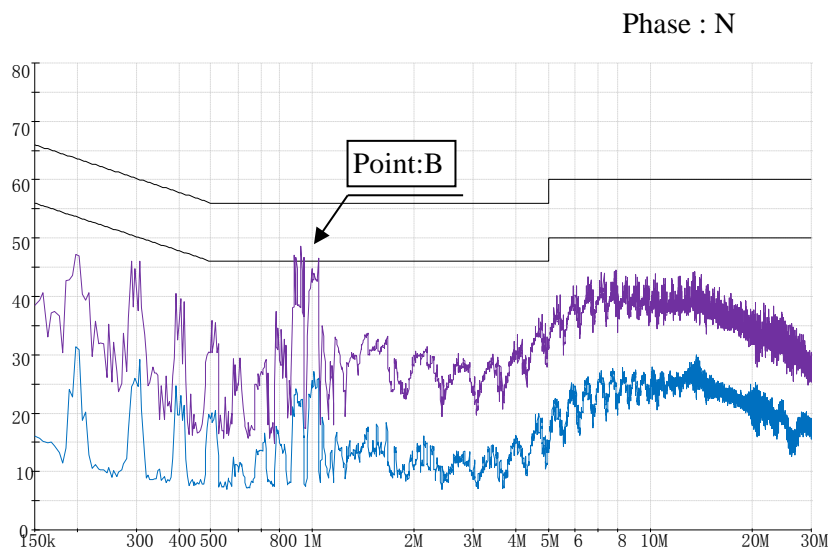


EN55032
Class B
QP Limit



EN55032
Class B
AV Limit

Point B (0.925MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	56.0	39.3
AV	46.0	29.1



EN55032
Class B
QP Limit



EN55032
Class B
AV Limit

EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ

Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

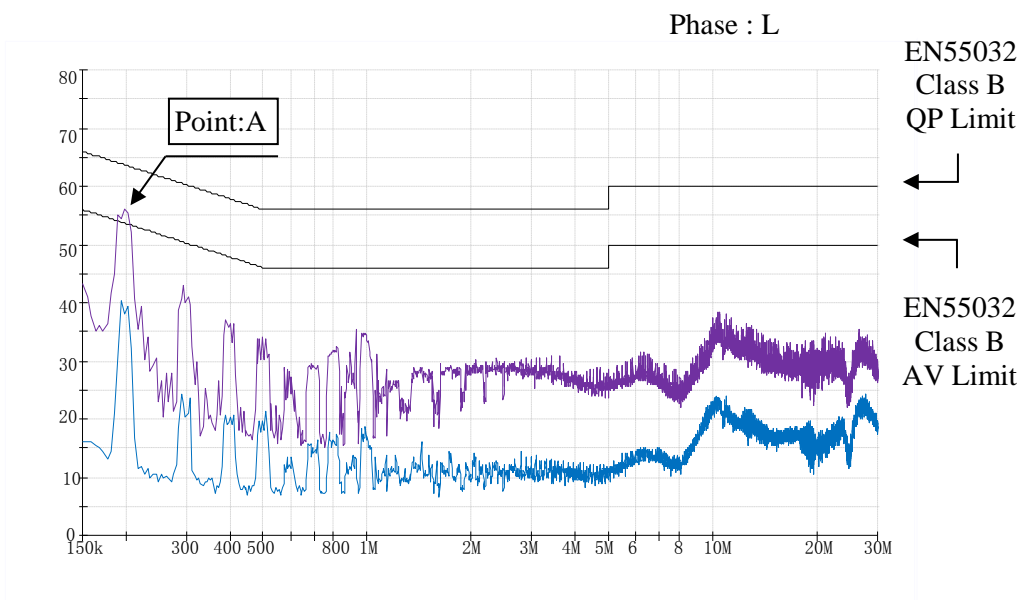
雑音端子電圧

Conducted Emission (CLASS II)

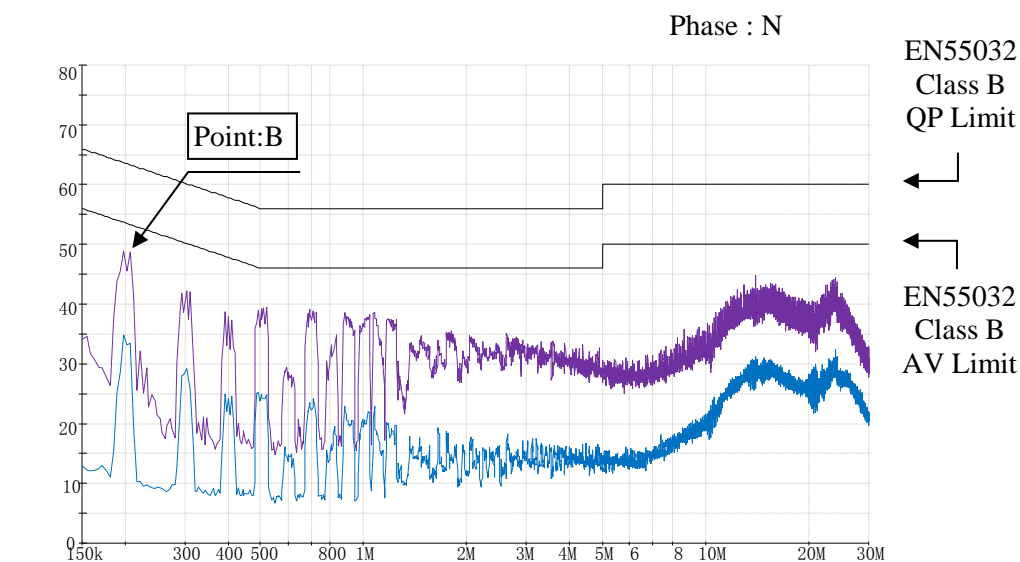
48V

(CUS30M-48)

Point A (0.195MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.8	53.9
AV	53.8	39.8



Point B (0.200MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	63.6	49.2
AV	53.6	39.3



EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ

Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

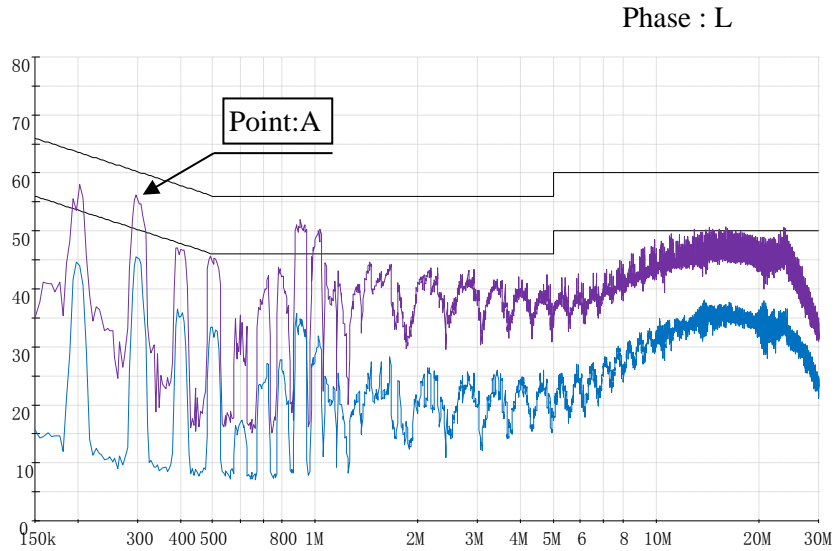
雑音端子電圧

Conducted Emission (CLASS II)

48V

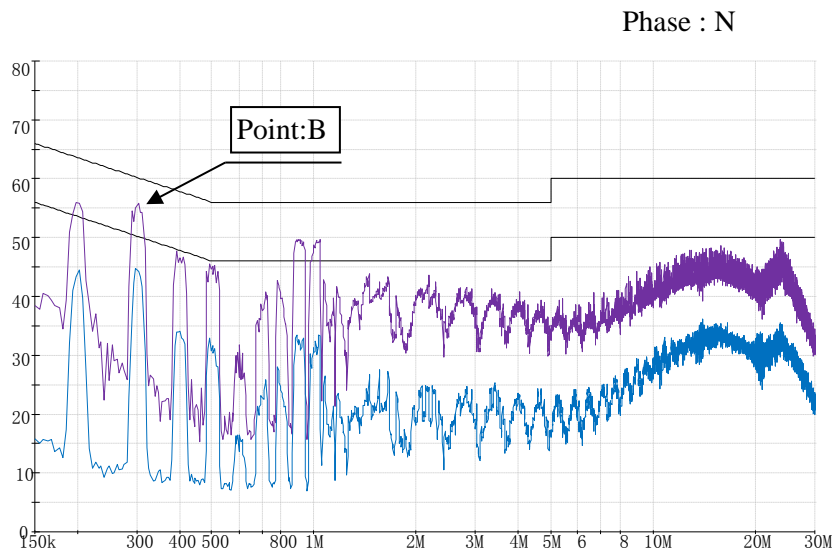
(CUS30M-48)

Point A (0.303MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	60.2	53.9
AV	50.2	44.9



EN55032
Class B
QP Limit
←
←
EN55032
Class B
AV Limit

Point B (0.299MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	60.3	52.9
AV	50.3	43.8



EN55032
Class B
QP Limit
←
←
EN55032
Class B
AV Limit

EN55011-B,VCCI-B,FCC-Bの限界値はEN55032 class Bの限界値と同じ
Limit of EN55011-B,VCCI-B,FCC-B are same as its EN55032 class B.

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

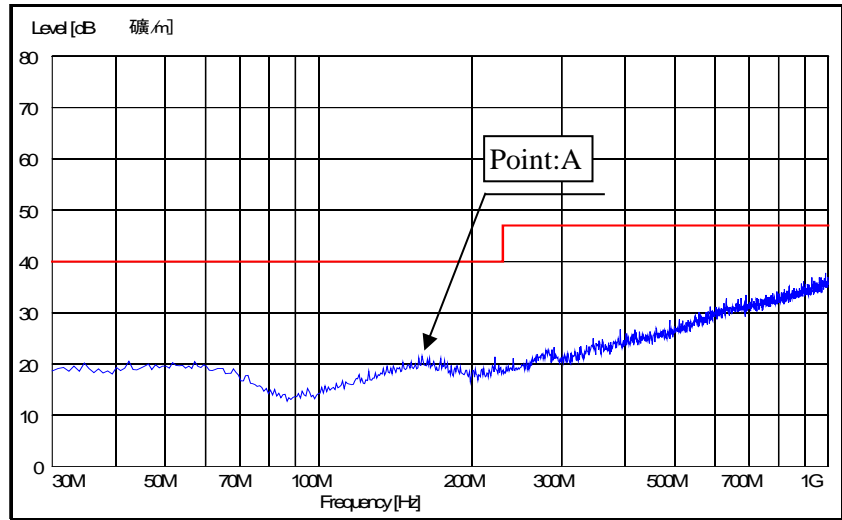
雑音電界強度

Radiated Emission (CLASS I)

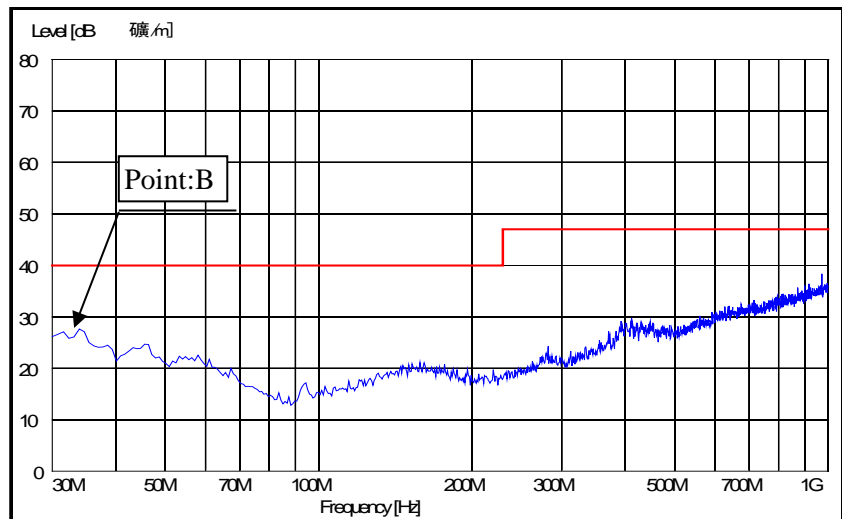
12V

(CUS30M-12)

Point A (183.2MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	20.2



Point B (34.7MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	28.1



2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

雑音電界強度

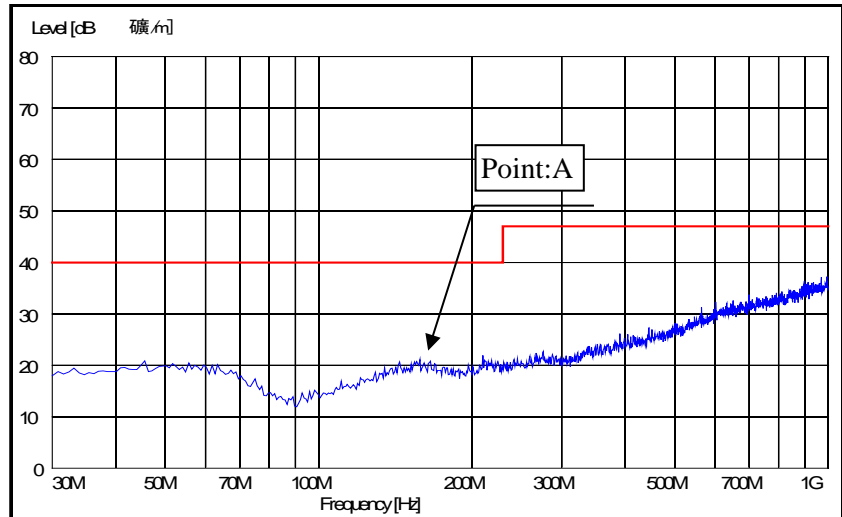
Radiated Emission (CLASS I)

12V

(CUS30M-12)

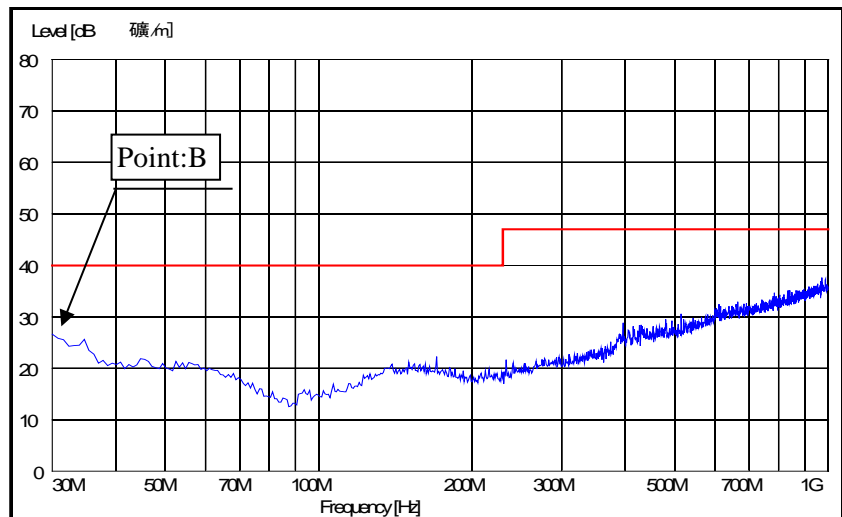
Point A (182.4MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	20.1

HORIZONTAL



Point B (30.6MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	26.8

VERTICAL



2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

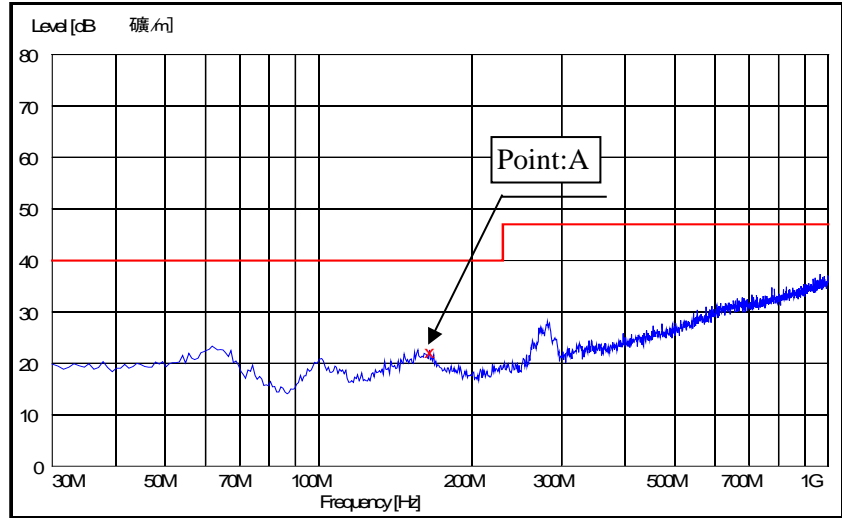
雑音電界強度

Radiated Emission (CLASS II)

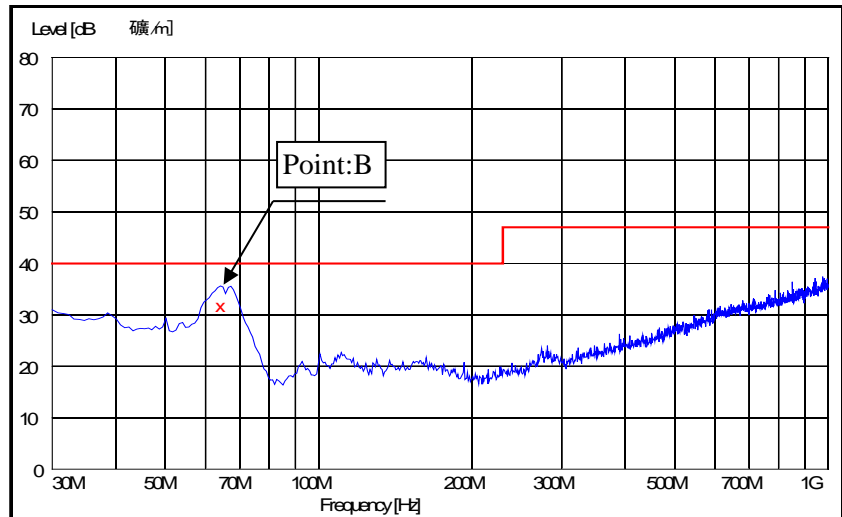
12V

(CUS30M-12)

Point A (183.3MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	22.4



Point B (64.1MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	32.0



2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

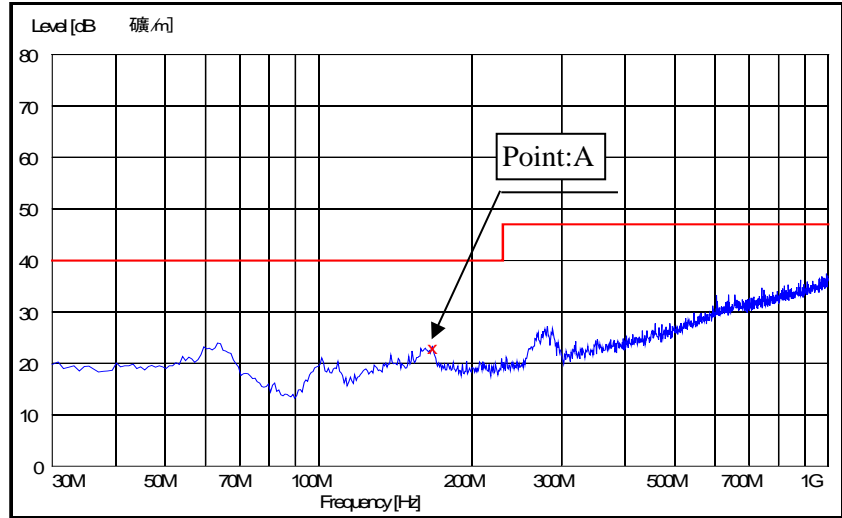
雑音電界強度

Radiated Emission (CLASS II)

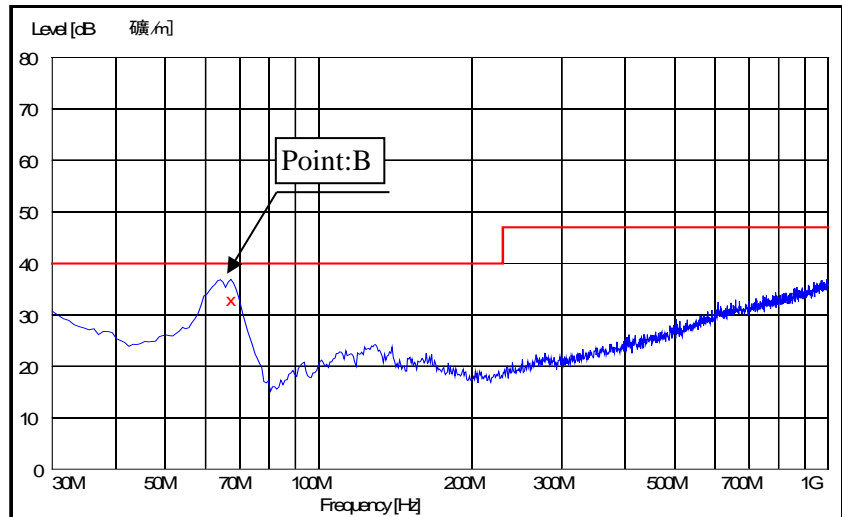
12V

(CUS30M-12)

Point A (185.6MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	22.9



Point B (67.4MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	33.2



2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

雑音電界強度

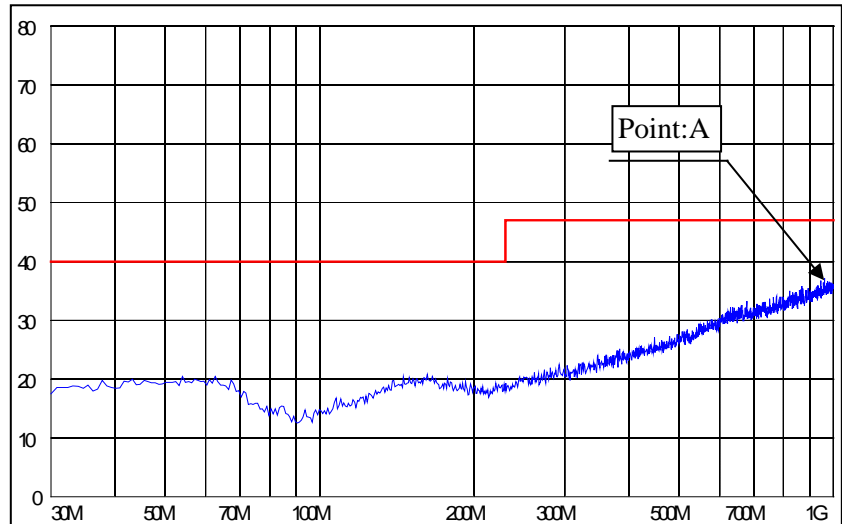
Radiated Emission (CLASS I)

24V

(CUS30M-24)

Point A (1000MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	46.0	33.0

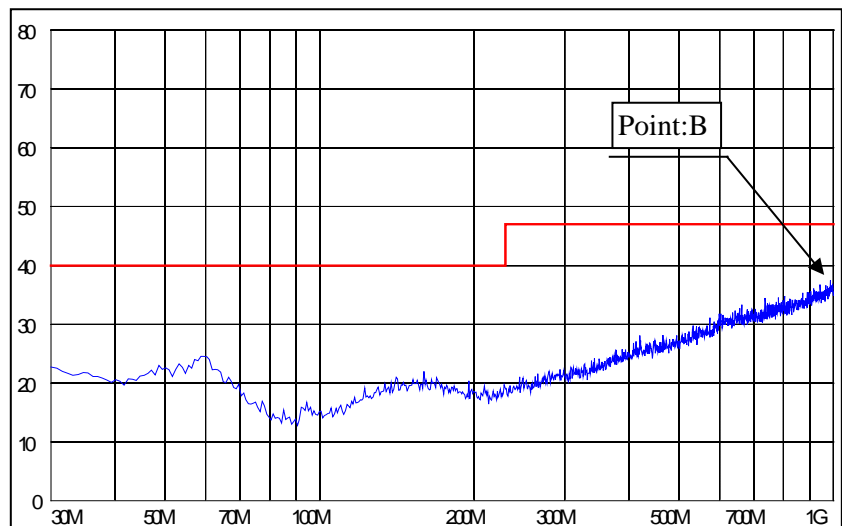
HORIZONTAL



EN55032
Class B
QP Limit

Point B (1000MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	46.0	33.0

VERTICAL



EN55032
Class B
QP Limit

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

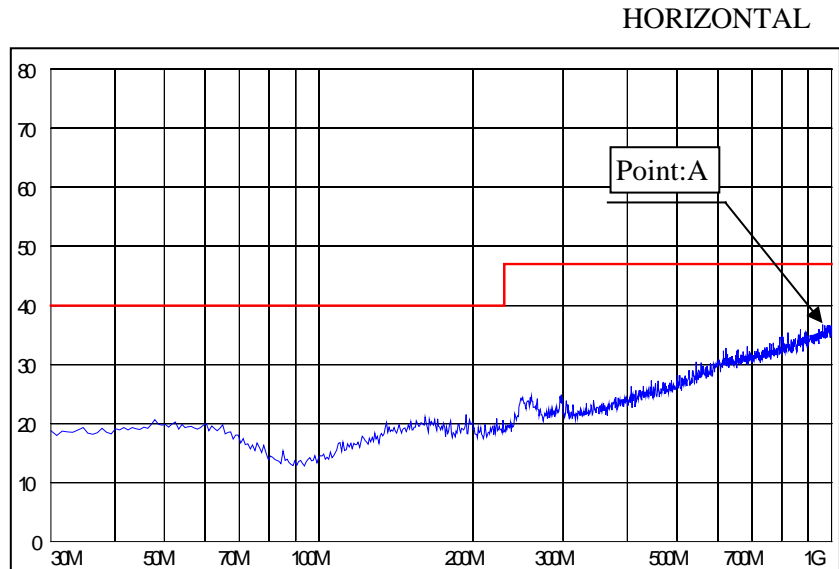
雑音電界強度

Radiated Emission (CLASS I)

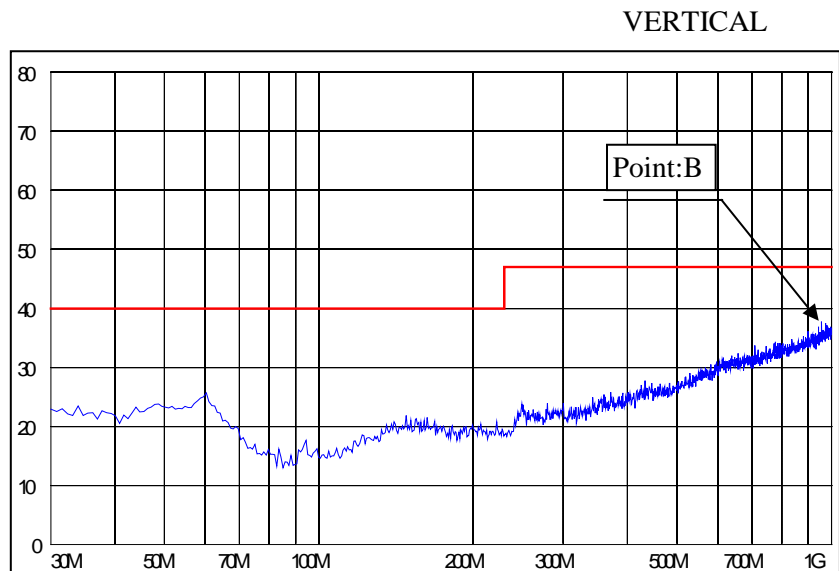
24V

(CUS30M-24)

Point A (1000MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	46.0	33.0



Point B (1000MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	46.0	33.0



2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

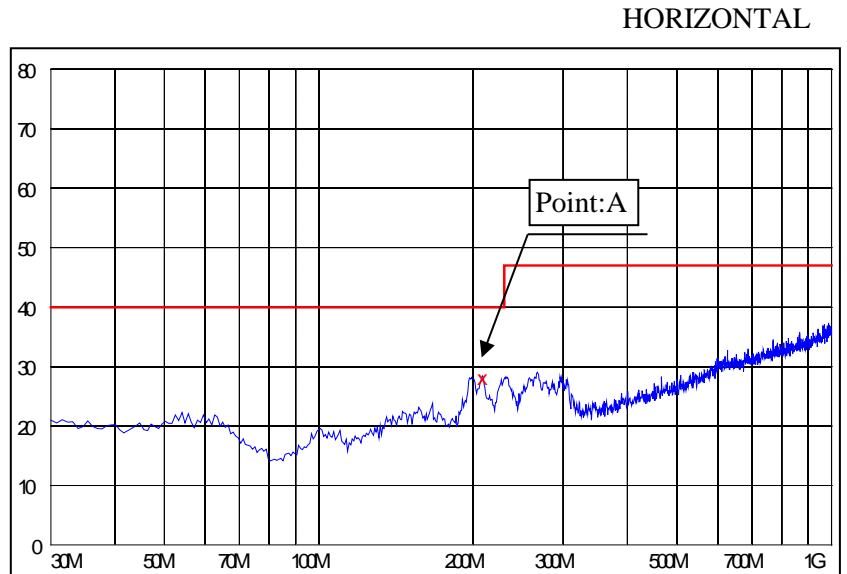
雑音電界強度

Radiated Emission (CLASS II)

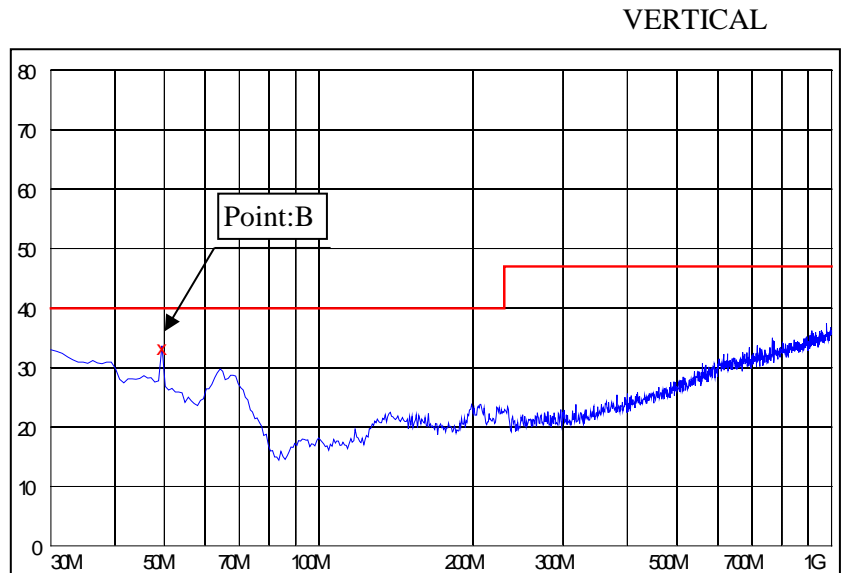
24V

(CUS30M-24)

Point A (200MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	30.0



Point B (50MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	34.0



2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

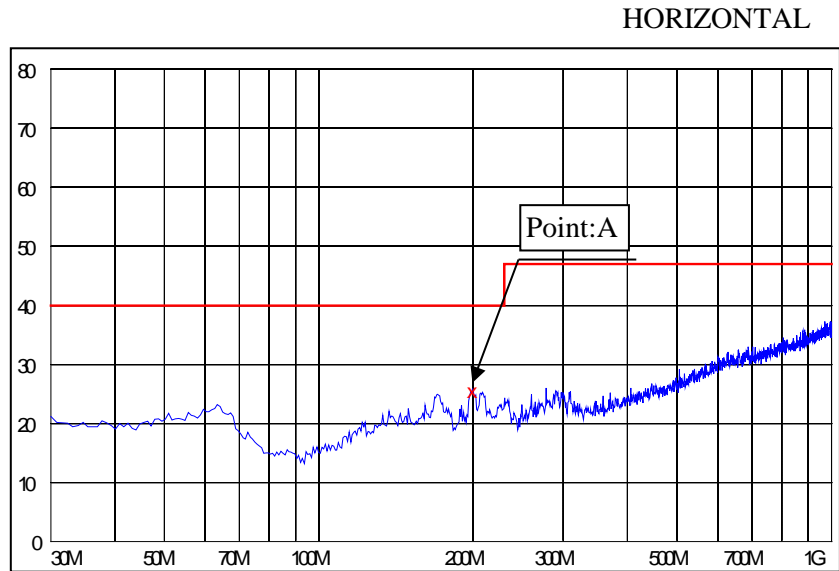
雑音電界強度

Radiated Emission (CLASS II)

24V

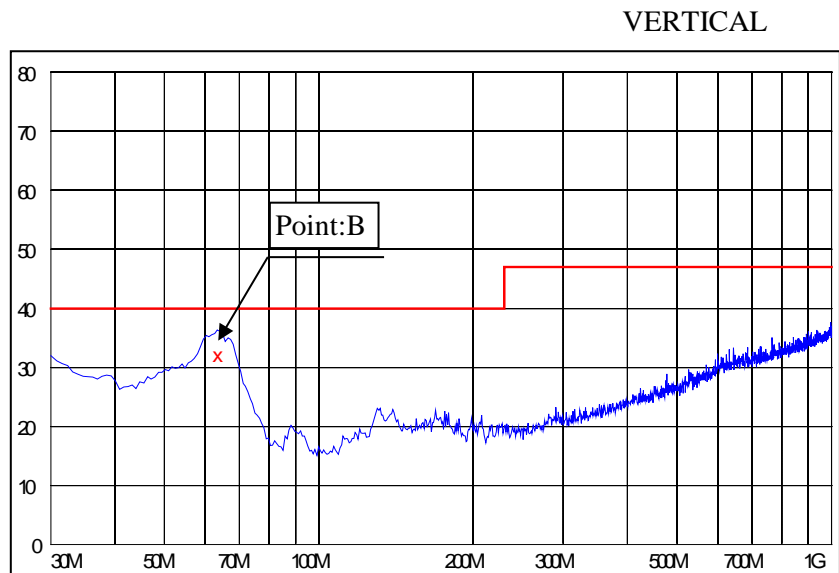
(CUS30M-24)

Point A (230MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	27.0



EN55032
Class B
QP Limit

Point B (60MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	32.3



EN55032
Class B
QP Limit

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

雑音電界強度

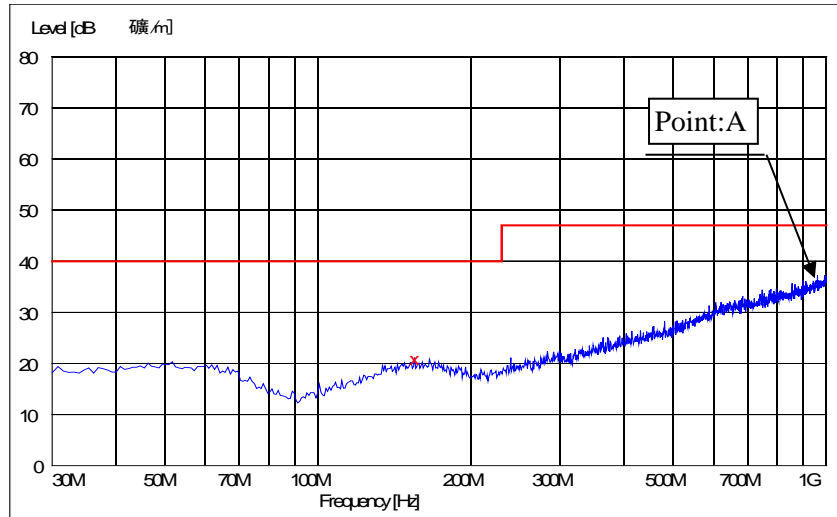
Radiated Emission (CLASS I)

48V

(CUS30M-48)

Point A (1000MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	47.0	35.5

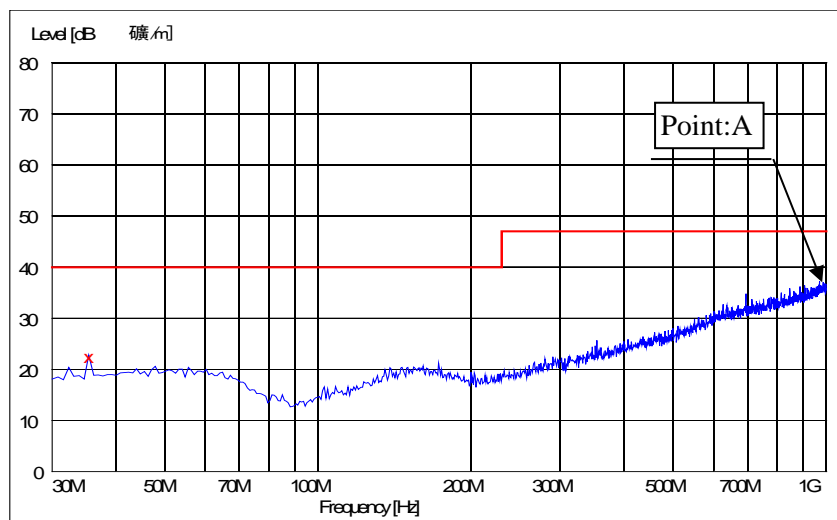
HORIZONTAL



EN55032
Class B
QP Limit

Point B (1000MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	47.0	35.0

VERTICAL



EN55032
Class B
QP Limit

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

雑音電界強度

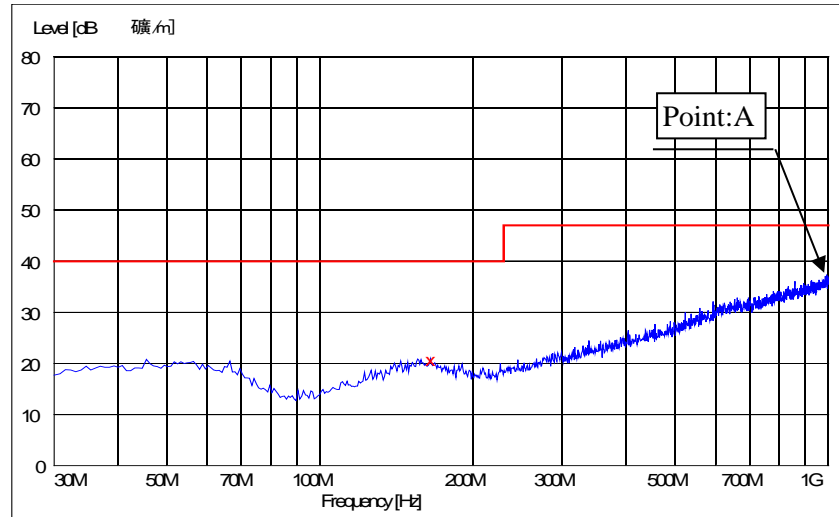
Radiated Emission (CLASS I)

48V

(CUS30M-48)

Point A (1000MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	47.0	36.0

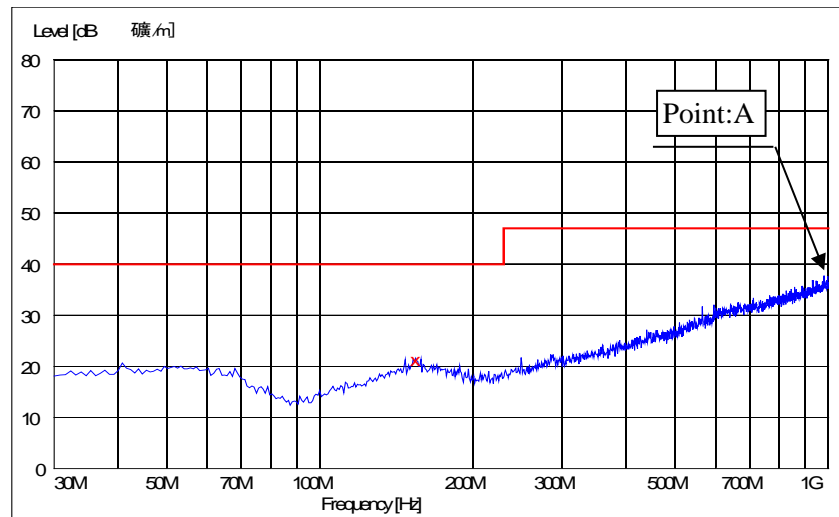
HORIZONTAL



EN55032
Class B
QP Limit

Point B (1000MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	47.0	36.0

VERTICAL



EN55032
Class B
QP Limit

2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 115 VAC
Iout : 100 %
Ta : 25 °C

雑音電界強度

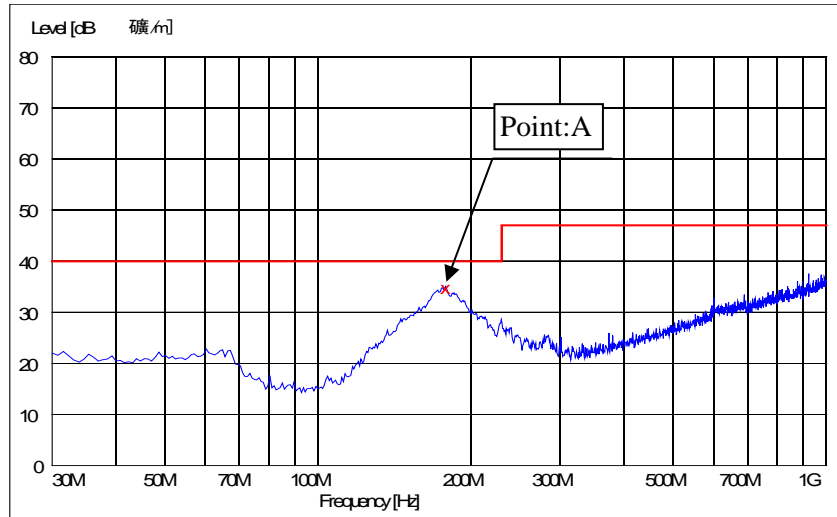
Radiated Emission (CLASS II)

48V

(CUS30M-48)

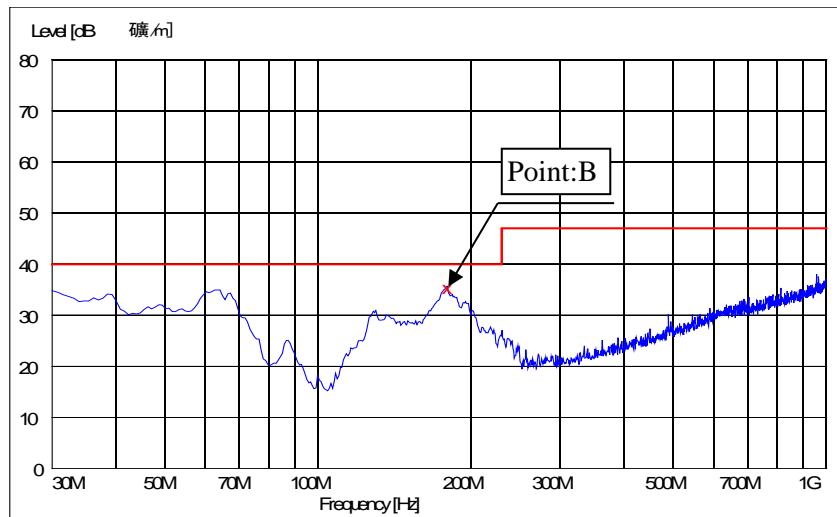
Point A (175MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	35.0

HORIZONTAL



Point B (175MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	35.4

VERTICAL



2.12 EMI 特性

Electro-Magnetic Interference characteristics

CUS30M

Conditions Vin : 230 VAC
Iout : 100 %
Ta : 25 °C

雑音電界強度

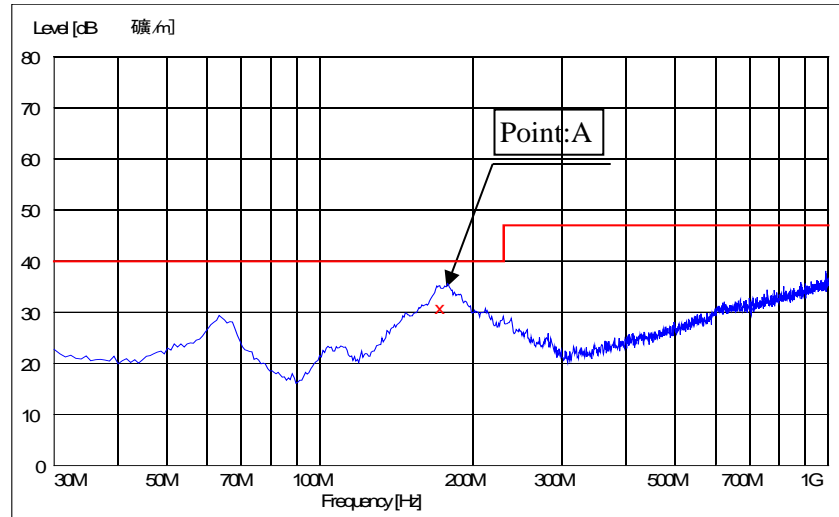
Radiated Emission (CLASS II)

48V

(CUS30M-48)

Point A (172MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	31.2

HORIZONTAL



Point B (63MHz)		
Ref. Data	Limit (dBuV)	Measure (dBuV)
QP	40.0	36.9

VERTICAL

